

# STIC Search Report

# STIC Database Translation Number 1

TO: John Chu

Location: REM 9D51

**Art Unit : 1752 February 28, 2006** 

Case Serial Number: 10/849197

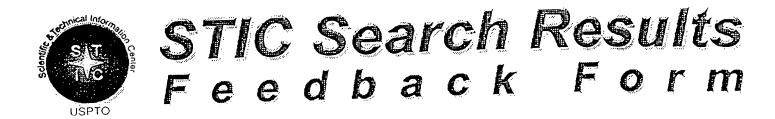
From: Usha Shrestha Location: EIC 1700 REMSEN 4B28

Phone: 571/272-3519

usha.shrestha@uspto.gov

| Search Notes |   |  |
|--------------|---|--|
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Comments:

Questions about the scope or the results of the search? Contact the EIC searcher or contact:

Kathleen Fuller, EIC 1700 Team Leader 571/272-2505 REMSEN 4B28

| Voluntary Results Feedback Form   |
|---|
| Fuemala: 1713   |
|   |
| > Relevant prior art found, search results used as follows:   |
| 102 rejection   |
| 103 rejection   |
| Cited as being of interest.   |
| Helped examiner better understand the invention.  |
| Helped examiner better understand the state of the art in their technology.   |
| Types of relevant prior art found:  |
| Foreign Patent(s)   |
| <ul> <li>Non-Patent Literature</li> <li>(journal articles, conference proceedings, new product announcements etc.)</li> </ul>   |
| <ul> <li>Results verified the lack of relevant prior art (helped determine patentability).</li> <li>Results were not useful in determining patentability or understanding the invention.</li> </ul> |

#### Banks, Kendra

From:

JOHN CHU [john.chu@uspto.gov]

Sent:

Wednesday, February 22, 2006 8:28 PM

To:

STIC-EIC1700

Subject:

Database Search Request, Serial Number: 10849197

Requester:

JOHN CHU (P/1752)

Art Unit:

**GROUP ART UNIT 1752** 

Employee Number:

68314

Office Location:

**REM 09D51** 

Phone Number:

(571)272-1329

Mailbox Number:

SCIENTIFIC REFERENCE BR Sci ? rech Inf · Cnt.

FEB 2 3 RECO

10849197 Class / Subclass(es):

Case serial number:

430/270.1

Pat. & T.M. Office

Earliest Priority Filing Date:

5/21/03

Format preferred for results:

Paper

Search Topic Information:

Please search the compound of formula (1) alone and in a photoresist composition.

Thank you very much,

John

Special Instructions and Other Comments:



### United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Vignia 22313-1450 www.uspto.gov



**CONFIRMATION NO. 7290** 

| Bib Data Sheet  |            | · ·                                     | <u></u>    |                  |     |                |             |        |                                      |
|---|------------|---|------------|------------------|-----|----------------|-------------|--------|--------------------------------------|
| SERIAL NUMBE<br>10/849,197  | R          | FILING DATE<br>05/20/2004<br>ULE        | c          | CLASS<br>430     | GRO | UP ART<br>1752 | UNIT        | D      | ATTORNEY<br>OCKET NO.<br>71-1098PUS1 |
|   |            | JLE                                     |            |                  |     |                | i           |        |                                      |
| APPLICANTS  |            |   |            |                  |     |                |             |        |                                      |
| Takeru Wata   | anabe, Ni  | iigata-ken, JAPAN                       | l;         |                  |     |                |             |        |                                      |
|   |            | ata-ken, JAPAN;<br>ata-ken, JAPAN;      |            |                  |     |                |             |        |                                      |
| " CONTINUING D  | DATA ****  | ******                                  | · ym       |                  |     |                |             |        |                                      |
| ** FOREIGN APPL<br>JAPAN 2003   |            | NS ************************************ | ***<br>)!~ |                  |     |                |             | •      |                                      |
| IF REQUIRED, FC<br>** 09/24/2004  | DREIGN F   | FILING LICENSE                          | GRANTE     | ED               | T   |                |             |        |                                      |
| Foreign Priority claimed<br>35 USC 119 (a-d) conditi                          |            | yes no no Met afte                      | er         | STATE OR         | SHE | ETS            | TOT         | AL     | INDEPENDENT                          |
| met<br>Verified and<br>Acknowledged   |            | 1                                       |            | COUNTRY<br>JAPAN | 1   | WING<br>0      | CLAII<br>13 |        | CLAIMS<br>8                          |
| ADDRESS<br>02292<br>BIRCH STEWART<br>PO BOX 747<br>FALLS CHURCH<br>22040-0747 |            | CH & BIRCH                              |            |                  | ·   |                |             |        |                                      |
| TITLE<br>Basic compound, r  | resist con | nposition and patte                     | erning pr  | ocess            |     |                |             |        |                                      |
|   |            |   |            |                  |     | □ Ali          | Fees        |        | •                                    |
| FILING FEE F  | EES: Aut   | thority has been gi                     | iven in P  | aper             |     |                | 6 Fees (    | Filing | 1)                                   |
| RECEIVED N<br>1200  | lo<br>lo   | to charge/cr                            | edit DEP   | OSIT ACCOU       | NT  | 1.1 time )     | 7 Fees (    | Proce  | essing Ext. of                       |
| 1200  |            |   |            |                  |     | □ 1.1          | 8 Fees (    | Issue  | )                                    |

#### **ABSTRACT**

Resist compositions comprising basic compounds having

a benzimidazole skeleton and a polar functional group have an excellent resolution and an excellent focus margin and are useful in microfabrication using electron beams or deep-UV light.

Application No. 10/849,197 Amendment dated December 20, 2005 Reply to Office Action of September 26, 2005 Page 4 of 18

#### AMENDED SET OF CLAIMS

1. (Original) A resist composition comprising at least one basic compound having a benzimidazole skeleton and a polar functional group, represented by the general formula (1):

$$\begin{array}{c}
R^1 \\
N \\
N \\
\end{array}$$
(1)

wherein R<sup>1</sup> is a hydrogen atom, a straight, branched or cyclic alkyl group of 1 to 10 carbon atoms, an aryl group of 6 to 10 carbon atoms, or an aralkyl group of 7 to 10 carbon atoms; and R<sup>2</sup> is a polar functional group-bearing straight, branched or cyclic alkyl group of 1 to 20 carbon atoms wherein said alkyl group contains as the polar functional group at least one group selected from among ester, acetal and cyano groups, and optionally at least one group selected from among hydroxyl, carbonyl, ether, sulfide and carbonate groups.

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2. (Original) A resist composition comprising at least one basic compound having a benzimidazole skeleton and a polar functional group, represented by the general formulae (2) to (7):

wherein R<sup>1</sup> is a hydrogen atom, a straight, branched or cyclic alkyl group of 1 to 10 carbon atoms, an aryl group of 6 to 10 carbon atoms, or an aralkyl group of 7 to 10 carbon atoms;

R<sup>3</sup>, R<sup>5</sup>, R<sup>9</sup>, R<sup>12</sup> and R<sup>14</sup> are each independently a straight, branched or cyclic alkylene group of 1 to 10 carbon atoms;

R<sup>4</sup> is a hydrogen atom or an alkyl group of 1 to 15 carbon atoms which may contain at least one group selected from among hydroxyl, carbonyl, ester, ether, sulfide, carbonate, cyano and acetal groups;

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R<sup>6</sup> is an alkyl group of 1 to 15 carbon atoms which may contain at least one group selected from among hydroxyl, carbonyl, ester, ether, sulfide, carbonate, cyano and acetal groups;

R<sup>7</sup> is a trivalent, straight, branched or cyclic hydrocarbon group of 2 to 10 carbon atoms;

R<sup>8</sup> is each independently an acyl group of 1 to 10 carbon atoms which may contain at least one ester or ether group, or two R<sup>8</sup> may bond together to form a cyclic carbonate or cyclic acetal;

R<sup>10</sup> is a hydrogen atom or a straight, branched or cyclic alkyl group of 1 to 10 carbon atoms;

 $R^{11}$  is a straight, branched or cyclic alkyl group of 1 to 10 carbon atoms which may contain at least one group selected from among ether, sulfide and acetal groups, or  $R^{10}$  and  $R^{11}$  may bond together to form a ring;

R<sup>13</sup> is a straight, branched or cyclic alkyl group of 1 to 10 carbon atoms, or two R<sup>13</sup> may bond together to form a ring.

- 3. (Original) A positive-working resist composition comprising:
  - (A) the basic compound of claim 1;
  - (B) an organic solvent;
  - (C) a base resin having an acid labile group-protected acidic functional group which is alkali-insoluble or substantially alkali-insoluble, but becomes alkali-soluble when the acid labile group is eliminated; and
  - (D) a photoacid generator.

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- 4. (Original) The positive resist composition of claim 3 which further comprises (E) a dissolution inhibitor.
  - 5. (Original) A negative-working resist composition comprising:
    - (A) the basic compound of claim 1;
    - (B) an organic solvent;
    - (C') a base resin which is alkali-soluble, but becomes substantially alkaliinsoluble when crosslinked with a crosslinking agent;
    - (D) a photoacid generator; and
    - (F) a crosslinking agent which induces crosslinkage under the action of an acid.
  - 6. (Withdrawn) A patterning process comprising the steps of:
    - (1) applying the positive resist composition of claim 3 onto a substrate;
    - (2) heat treating the applied resist, then exposing the heat-treated resist through a photomask to high-energy radiation having a wavelength of at most 300 nm or an electron beam; and
    - (3) heat treating the exposed resist, then developing the resist with a liquid developer.
  - 7. (Withdrawn) A patterning process comprising the steps of:
    - (1) applying the negative resist composition of claim 5 onto a substrate;

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- (2) heat treating the applied resist, then exposing the heat-treated resist through a photomask to high-energy radiation having a wavelength of at most 300 nm or an electron beam; and
- (3) heat treating the exposed resist, then developing the resist with a liquid developer.
- 8. (Withdrawn) A basic compound represented by the general formula (2):

$$\begin{array}{c}
R^{1} & O \\
N & R^{3} & R^{4}
\end{array}$$
(2)

wherein R<sup>1</sup> is a hydrogen atom, a straight, branched or cyclic alkyl group of 1 to 10 carbon atoms, an aryl group of 6 to 10 carbon atoms, or an aralkyl group of 7 to 10 carbon atoms;

R<sup>3</sup> is a straight, branched or cyclic alkylene group of 1 to 10 carbon atoms; and

R<sup>4</sup> is a hydrogen atom or an alkyl group of 1 to 15 carbon atoms which may contain at
least one group selected from among hydroxyl, carbonyl, ester, ether, sulfide, carbonate, cyano
and acetal groups.

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9. (Withdrawn) A basic compound represented by the general formula (3):

$$\begin{array}{c}
R^1 \\
N \\
N \\
O
\end{array}$$

$$\begin{array}{c}
R^5 \\
O \\
R^6
\end{array}$$

$$\begin{array}{c}
O \\
R^6
\end{array}$$

wherein R<sup>1</sup> is a hydrogen atom, a straight, branched or cyclic alkyl group of 1 to 10 carbon atoms, an aryl group of 6 to 10 carbon atoms, or an aralkyl group of 7 to 10 carbon atoms;

R<sup>5</sup> is a straight, branched or cyclic alkylene group of 1 to 10 carbon atoms; and R<sup>6</sup> is an alkyl group of 1 to 15 carbon atoms which may contain at least one group selected from among hydroxyl, carbonyl, ester, ether, sulfide, carbonate, cyano and acetal groups.

10. (Withdrawn) A basic compound represented by the general formula (4):

$$\begin{array}{c}
R^{1} \\
N \\
N \\
N^{R^{7}} (OR^{8})_{2}
\end{array}$$
(4)

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wherein R<sup>1</sup> is a hydrogen atom, a straight, branched or cyclic alkyl group of 1 to 10 carbon atoms, an aryl group of 6 to 10 carbon atoms, or an aralkyl group of 7 to 10 carbon atoms;

R<sup>7</sup> is a trivalent, straight, branched or cyclic hydrocarbon group of 2 to 10 carbon atoms; and

R<sup>8</sup> is each independently an acyl group of 1 to 10 carbon atoms which may contain at least one ester or ether group, or two R<sup>8</sup> may bond together to form a cyclic carbonate or cyclic acetal.

# 11. (Withdrawn) A basic compound represented by the general formula (5):

$$\begin{array}{c}
R^{1} \\
N \\
N \\
N
\end{array}$$

$$\begin{array}{c}
R^{9} \\
O \\
O
\end{array}$$

$$\begin{array}{c}
R^{11} \\
O \\
O
\end{array}$$

$$\begin{array}{c}
R^{11} \\
O \\
O
\end{array}$$

wherein R<sup>1</sup> is a hydrogen atom, a straight, branched or cyclic alkyl group of 1 to 10 carbon atoms, an aryl group of 6 to 10 carbon atoms, or an aralkyl group of 7 to 10 carbon atoms;

R<sup>9</sup> is a straight, branched or cyclic alkylene group of 1 to 10 carbon atoms;

R<sup>10</sup> is a hydrogen atom or a straight, branched or cyclic alkyl group of 1 to 10 carbon atoms;

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R<sup>11</sup> is a straight, branched or cyclic alkyl group of 1 to 10 carbon atoms which may contain at least one group selected from among ether, sulfide and acetal groups, or R<sup>10</sup> and R<sup>11</sup> may bond together to form a ring.

12. (Withdrawn) A basic compound represented by the general formula (6):

$$\begin{array}{c}
R^{1} \\
N \\
N \\
N \\
OR^{12} \\
OR^{13}
\end{array}$$
(6)

wherein R<sup>1</sup> is a hydrogen atom, a straight, branched or cyclic alkyl group of 1 to 10 carbon atoms, an aryl group of 6 to 10 carbon atoms, or an aralkyl group of 7 to 10 carbon atoms;

R<sup>12</sup> is a straight, branched or cyclic alkylene group of 1 to 10 carbon atoms; and R<sup>13</sup> is a straight, branched or cyclic alkyl group of 1 to 10 carbon atoms, or two R<sup>13</sup> may bond together to form a ring.

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# 13. (Withdrawn) A basic compound represented by the general formula (7):

$$\begin{array}{c}
R^{1} \\
N \\
N \\
\end{array}$$

$$\begin{array}{c}
R^{14} \\
CN \\
\end{array}$$

$$(7)$$

wherein R<sup>1</sup> is a hydrogen atom, a straight, branched or cyclic alkyl group of 1 to 10 carbon atoms, an aryl group of 6 to 10 carbon atoms, or an aralkyl group of 7 to 10 carbon atoms; and

R<sup>14</sup> is a straight, branched or cyclic alkylene group of 1 to 10 carbon atoms.

## 14. (Currently Amended) A compound of the formula:

Amine 2

15. (Withdrawn) A resist composition comprising the compound of claim 14.

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16. (New) The resist composition of claim 1 wherein the basic compound is at least one selected from the group consisting of compounds represented by the following general formulae:

wherein R1 is a hydrogen atom, methyl group or phenyl group;

R<sup>3</sup>, R<sup>9</sup>, and R<sup>12</sup> are each independently a straight, branched or cyclic alkylene group of 1 to

10 carbon atoms;

R<sup>4</sup> is a hydrogen atom or an alkyl group of 1 to 15 carbon atoms which may contain at least one group selected from among hydroxyl, carbonyl, ester, ether, sulfide, carbonate, cyano and acetal groups;

R<sup>7</sup> is a trivalent, straight, branched or cyclic hydrocarbon group of 2 to 10 carbon atoms;

R<sup>8</sup> is each independently an acyl group of 1 to 10 carbon atoms which may contain at least one ester or ether group, or two R<sup>8</sup> may bond together to form a cyclic carbonate or cyclic acetal;

R<sup>10</sup> is a hydrogen atom or a straight, branched or cyclic alkyl group of 1 to 10 carbon atoms;

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 $R^{11}$  is a straight, branched or cyclic alkyl group of 1 to 10 carbon atoms which may contain at least one group selected from among ether, sulfide and acetal groups, or  $R^{10}$  and  $R^{11}$  may bond together to form a ring; and

R<sup>13</sup> is a straight, branched or cyclic alkyl group of 1 to 10 carbon atoms, or two R<sup>13</sup> may bond together to form a ring.

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=> d his
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               _____
                STR
L1
L2
         442695 SEA FILE=REGISTRY SSS FUL L1
               ACT CHU186/A
L3
                STR
L4
                STR
         442695) SEA FILE=REGISTRY SSS FUL L3
L5
   (
1.6
           2290 SEA FILE=REGISTRY SUB=L5 SSS FUL L4
               ACT CHU197/A
               _____
L7
                STR
L8
                STR
L9
         442695) SEA FILE=REGISTRY SSS FUL L7
   (
L10
           8549 SEA FILE=REGISTRY SUB=L9 SSS FUL L8
     FILE 'HCAPLUS' ENTERED AT 09:46:55 ON 28 FEB 2006
L11
            1 S US20040234884/PN
L12
             1 S US20050008968/PN
L13
           924 S L6
L14
          1426 S L10
            35 S L13 AND ?RESIST?
L15
            52 S L14 AND ?RESIST?
L16
                SEL L16 HIT RN 1-52
L17
            21 S L16 AND PHOTOG?/SC,SX
            10 S L15 AND PHOTOG?/SC,SX
L18
            25 S L15 NOT L18
L19
            23 S L13 AND PHOTOG?/SC,SX
L20
L21
            23 S L18 OR L20
             1 S L21 AND L11
L22
L23
            48 S L14 AND PHOTOG?/SC,SX
            48 S L17 OR L23
L24
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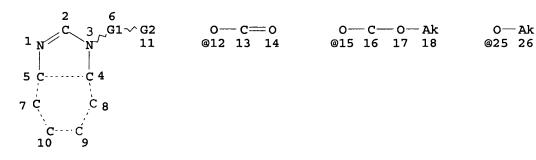
1 S L24 AND L12

L25

VAR G1=AK/CB NODE ATTRIBUTES: DEFAULT MLEVEL IS ATOM DEFAULT ECLEVEL IS LIMITED **GRAPH ATTRIBUTES:** 

RING(S) ARE ISOLATED OR EMBEDDED NUMBER OF NODES IS 6

STEREO ATTRIBUTES: NONE



Ak-0-C-0-Ak 0=C-0-Ak 24 23 @20 21 22 27 @28 29 30

VAR G1=AK/CB VAR G2=CN/12/15/25/20/28 NODE ATTRIBUTES: DEFAULT MLEVEL IS ATOM DEFAULT ECLEVEL IS LIMITED

GRAPH ATTRIBUTES:

RING(S) ARE ISOLATED OR EMBEDDED NUMBER OF NODES IS 29

STEREO ATTRIBUTES: NONE

L9 ( 442695) SEA FILE=REGISTRY SSS FUL L7

L10 8549 SEA FILE=REGISTRY SUB=L9 SSS FUL L8

L14 1426 SEA FILE=HCAPLUS ABB=ON PLU=ON L10

L16 52 SEA FILE=HCAPLUS ABB=ON PLU=ON L14 AND ?RESIST?

L17 21 SEA FILE=HCAPLUS ABB=ON PLU=ON L16 AND PHOTOG?/SC,SX

L23 48 SEA FILE=HCAPLUS ABB=ON PLU=ON L14 AND PHOTOG?/SC,SX

L24 48 SEA FILE=HCAPLUS ABB=ON PLU=ON L17 OR L23

=> fil hcap

FILE 'HCAPLUS' ENTERED AT 09:56:43 ON 28 FEB 2006

=> d 124 1-48 ibib abs hitstr hitind

L24 ANSWER 1 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

2005:1314040 HCAPLUS

DOCUMENT NUMBER:

144:47761

TITLE:

Luminescent compounds having a functionalized

linker arm used in the bioconjugation and

labelling of biomolecules

INVENTOR(S):

Caputo, Giuseppe; Gobetto, Roberto; Viscardi,

Guido

PATENT ASSIGNEE(S):

Italy

SOURCE:

PCT Int. Appl., 40 pp.

CODEN: PIXXD2

DOCUMENT TYPE:

Patent

LANGUAGE:

English

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| PATI     | ENT 1      | NO.  |      |     | KIN        | D : | DATE |      | •   | APPL  | ICAT  | ION I | NO. |     | D   | ATE        |
|----------|------------|------|------|-----|------------|-----|------|------|-----|-------|-------|-------|-----|-----|-----|------------|
|          |            |      |      |     |            | -   |      |      |     |       |       |       |     |     |     |            |
| WO 2     | 2005       | 1192 | 54   |     | <b>A</b> 1 |     | 2005 | 1215 | 1   | WO 2  | 005-  | IB51  | 782 |     |     |            |
|          |            |      |      |     |            |     |      |      |     |       |       |       |     |     |     | 005<br>501 |
|          | <b>W</b> : | ΑE,  | AG,  | AL, | AM,        | AT, | AU,  | AZ,  | BA, | BB,   | ВG,   | BR,   | BW, | BY, | BZ, |            |
|          |            | CA,  | CH,  | CN, | CO,        | CR, | CU,  | CZ,  | DE, | DK,   | DM,   | DZ,   | EC, | EE, | EG, |            |
|          |            | ES,  | FI,  | GB, | GD,        | GΕ, | GH,  | GM,  | HR, | HU,   | ID,   | IL,   | IN, | IS, | JP, |            |
|          |            | KΕ,  | KG,  | KM, | KΡ,        | KR, | KZ,  | LC,  | LK, | LR,   | LS,   | LT,   | LU, | LV, | MA, |            |
|          |            | MD,  | MG,  | MK, | MN,        | MW, | MX,  | ΜZ,  | NA, | NG,   | NI,   | NO,   | ΝZ, | OM, | PG, |            |
|          |            | PH,  | PL,  | PT, | RO,        | RU, | SC,  | SD,  | SE, | SG,   | SK,   | SL,   | SM, | SY, | ТJ, |            |
|          |            | TM,  | TN,  | TR, | TT,        | TZ, | UA,  | UG,  | US, | UΖ,   | VC,   | VN,   | YU, | ZA, | ZM, | ZW         |
|          | RW:        | BW,  | GH,  | GM, | KΕ,        | LS, | MW,  | ΜZ,  | NA, | SD,   | SL,   | SZ,   | TZ, | ŪĠ, | ZM, |            |
|          |            | ZW,  | AM,  | ΑZ, | BY,        | KG, | KZ,  | MD,  | RU, | ТJ,   | TM,   | AT,   | BE, | BG, | CH, |            |
|          |            | CY,  | CZ,  | DE, | DK,        | EE, | ES,  | FI,  | FR, | GB,   | GR,   | HU,   | ΙE, | ıs, | IT, |            |
|          |            | LT,  | LU,  | MC, | NL,        | PL, | PT,  | RO,  | SE, | SI,   | SK,   | TR,   | BF, | ВJ, | CF, |            |
|          |            | CG,  | CI,  | CM, | GA,        | GN, | GQ,  | GW,  | ML, | MR,   | NE,   | SN,   | TD, | TG  |     |            |
| PRIORITY | APP        | LN.  | INFO | . : |            |     |      |      |     | IT 20 | 004-' | TO37: | 2   | 7   | A   |            |
|          |            |      |      |     |            |     |      |      |     |       |       |       |     |     | 20  | 004        |
|          |            |      |      |     |            |     |      |      |     |       |       |       |     |     | 06  | 501        |

AB The present invention relates to luminescent compds. having a functionalized linker arm, their synthesis and use in bioconjugation and labeling of biomols., such as for example nucleosides, nucleotides, nucleic acids (DNA, RNA or PNA) and proteins, as well as their use in the execution of in vitro and in vivo analytic and diagnostic assays.

IT 871031-12-8P

(luminescent compds. having a functionalized linker arm and electrochemiluminescent properties used in bioconjugation and labeling of biomols.)

RN 871031-12-8 HCAPLUS

1H-Benzimidazole-1-hexanoic acid, 2-(4-methyl-2-pyridinyl)-, CN phenylmethyl ester (9CI) (CA INDEX NAME)

IC ICM G01N033-53

ICS C07F015-00

9-16 (Biochemical Methods) CC

Section cross-reference(s): 29, 41

IT 15746-57-3P 64819-73-4P 64819-74-5P 78277-26-6P 871031-13-9P 871031-14-0P 871031-15-1P 871031-12-8P 871031-16-2P

(luminescent compds. having a functionalized linker arm and electrochemiluminescent properties used in bioconjugation and labeling of biomols.)

REFERENCE COUNT:

10

THERE ARE 10 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE

IN THE RE FORMAT

L24 ANSWER 2 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

2005:1155389 HCAPLUS

DOCUMENT NUMBER:

143:413518

TITLE:

Nitrogen-containing organic compound,

chemically amplified resist

composition and patterning process

INVENTOR(S):

Watanabe, Takeru; Hasegawa, Koji; Takemura,

Katsuya; Noda, Kazumi

PATENT ASSIGNEE(S):

Shin-Etsu Chemical Co., Ltd., Japan

SOURCE:

U.S. Pat. Appl. Publ., 23 pp.

CODEN: USXXCO

DOCUMENT TYPE:

Patent

LANGUAGE:

English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

| PATENT NO.             | KIND | DATE     | APPLICATION NO.  | DATE |
|------------------------|------|----------|------------------|------|
|                        |      |          |                  |      |
| US 2005238993          | A1   | 20051027 | US 2005-110927   |      |
|                        |      |          |                  | 2005 |
| JP 2005306812          | A2   | 20051104 | JP 2004-128478   | 0421 |
|                        |      |          |                  | 2004 |
|                        |      |          |                  | 0423 |
| PRIORITY APPLN. INFO.: |      |          | JP 2004-128478 A |      |
|                        |      |          |                  | 2004 |
|                        |      |          |                  | 0423 |

- AB Chemical amplified **photoresist** compns. comprising nitrogen-containing organic compds. having a 7-oxanorbornane-2-carboxylic ester structure have an excellent resolution and provide a precise pattern profile and are useful in microfabrication using electron beams or deep-UV light.
- IT 867257-56-5P

(nitrogen-containing organic compound for chemical amplified resist composition)

- RN 867257-56-5 HCAPLUS
- CN 7-Oxabicyclo[2.2.1]heptane-2-carboxylic acid, 2-(1H-benzimidazol-1-yl)ethyl ester (9CI) (CA INDEX NAME)

IC ICM G03C001-492

INCL 430270100

CC 74-5 (Radiation Chemistry, Photochemistry, and **Photographic** and Other Reprographic Processes)

ST nitrogen org compd chem amplified photoresist compn

```
patterning process
IT
     Photolithography
       Photoresists
        (nitrogen-containing organic compound for chemical amplified resist
        composition and patterning process)
                   867257-47-4P
                                   867257-49-6P 867257-51-0P
TT
     867257-46-3P
     867257-52-1P
                   867257-54-3P
        (nitrogen-containing organic compound for chemical amplified resist
        composition)
                                867257-48-5P
     111-95-5P 867257-45-2P
                                               867257-50-9P
IT
                   867257-55-4P 867257-56-5P 867257-57-6P
     867257-53-2P
     867257-59-8P
        (nitrogen-containing organic compound for chemical amplified resist
        composition)
ΙT
     102-71-6, Triethanolamine, reactions 102-79-4,
     Butyldiethanolamine 105-59-9, Methyldiethanolamine
                                                            109-85-3,
     2-Methoxyethylamine 120-07-0, Phenyldiethanolamine 122-20-3,
     Triisopropanolamine 122-96-3, 1,4-(Bis(2-hydroxyethyl)piperazine
     622-40-2, 2-Morpholinoethanol 1615-14-1, 1H-Imidazole-1-ethanol 3040-44-6, 2-Piperidinoethanol 3445-11-2, 2-(2-0xo-1-
     pyrrolidinyl)ethanol 6340-03-0, 1H-Benzimidazole-1-ethanol
     17209-72-2 21987-32-6 64897-90-1 867257-43-0
        (proparation of nitrogen-containing organic compound for chemical amplified
        resist composition)
IT
     79402-97-4P
        (proparation of nitrogen-containing organic compound for chemical amplified
        resist composition)
IT
     867257-44-1P
        (proparation of nitrogen-containing organic compound for chemical amplified
        resist composition)
L24 ANSWER 3 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN
ACCESSION NUMBER:
                       2005:429276 HCAPLUS
DOCUMENT NUMBER:
                        142:490393
TITLE:
                        Nitrogen-containing organic compound,
                        resist composition and patterning
                        process
INVENTOR(S):
                        Watanabe, Takeru; Kinsho, Takeshi; Hasegawa,
                        Koji; Takemura, Katsuya; Noda, Kazumi;
                        Kobayashi, Katsuhiro
PATENT ASSIGNEE(S):
                        Shin-Etsu Chemical Co., Ltd., Japan
SOURCE:
                        U.S. Pat. Appl. Publ., 31 pp.
                        CODEN: USXXCO
DOCUMENT TYPE:
                        Patent
LANGUAGE:
                        English
FAMILY ACC. NUM. COUNT:
PATENT INFORMATION:
     PATENT NO.
                        KIND DATE
                                           APPLICATION NO.
                                                                   DATE
                        ----
                                           -----
                               -----
     US 2005106500
                        A1
                                20050519
                                           US 2004-984933
                                                                   2004
                                                                   1110
```

JP 2004-324619

JP 2003-384505

2004 1109

2003 1114

20050623

JP 2005165295

PRIORITY APPLN. INFO.:

A2

- AB Chemical amplified **resist** compns. comprising nitrogen-containing organic compds. having an aromatic carboxylic acid ester structure have an excellent resolution and provide a precise pattern profile and are useful in microfabrication using electron beams or deep-UV light.
- IT 22495-17-6P, 2-(1H-Benzimidazol-1-yl)ethyl benzoate 851706-05-3P

(nitrogen-containing organic compound, resist composition and patterning process)

- RN 22495-17-6 HCAPLUS
- CN 1H-Benzimidazole-1-ethanol, benzoate (ester) (9CI) (CA INDEX NAME)

$$\begin{array}{c|c}
 & O \\
 & O \\
 & CH_2-CH_2-O-C-Ph
\end{array}$$

- RN 851706-05-3 HCAPLUS
- CN Benzoic acid, 4-methoxy-, 2-(2-phenyl-1H-benzimidazol-1-yl)ethyl ester (9CI) (CA INDEX NAME)

- IC ICM G03C001-492
- INCL 430270100
- CC 74-5 (Radiation Chemistry, Photochemistry, and

Photographic and Other Reprographic Processes)

- ST nitrogen org photoresist compn process
- IT Photolithography

#### Photoresists

(nitrogen-containing organic compound, resist composition and patterning process)

- 98-88-4, Benzoyl chloride IT. 51-17-2, Benzimidazole 100-07-2. 4-Methoxybenzoyl chloride 102-71-6, Triethanolamine, reactions 527-69-5, 2-Furoyl chloride 622-40-2, 2-Morpholinoethanol 879-18-5, 1-Naphthoyl chloride 1615-14-1, 2-(Imidazol-1yl)ethanol 2243-83-6, 2-Naphthoyl chloride 2955-88-6, 2-(1-Pyrrolidinyl)ethanol 5452-06-2, 2-Chloroethyl 4-methoxybenzoate 6425-32-7, 3-Morpholinopropane-1,2-diol 14002-51-8, 4-Phenylbenzoyl chloride 17209-72-2 17213-57-9, 3,5-Dimethoxybenzoyl chloride 33941-15-0, 1-Aza-18-crown-6 79402-97-4 98998-43-7
  - (nitrogen-containing organic compound, resist composition and patterning process)
- IT 22495-17-6P, 2-(1H-Benzimidazol-1-yl)ethyl benzoate 192817-77-9P, Ethyl 47750-79-8P 79690-87-2P 2-(1-pyrrolidinyl)benzoate 497057-34-8P 851705-95-8P 851706-01-9P 851705-97-0P 851705-99-2P 851706-00-8P 851706-04-2P 851706-05-3P 851706-02-0P 851706-03-1P 851706-06-4P 851706-07-5P

(nitrogen-containing organic compound, resist composition and patterning process)

L24 ANSWER 4 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 2005:394655 HCAPLUS

DOCUMENT NUMBER: 142:454315

TITLE: Nitrogen-containing organic compound,

resist composition and patterning

process

INVENTOR(S): Watanabe, Takeru; Kinsho, Takeshi; Takemura,

Katsuya; Seki, Akihiro

PATENT ASSIGNEE(S): Shin-Etsu Chemical Co., Ltd., Japan

SOURCE: U.S. Pat. Appl. Publ., 23 pp.

CODEN: USXXCO

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

| PATENT NO.             | KIND | DATE     | APPLICATION NO.  | DATE |
|------------------------|------|----------|------------------|------|
|                        |      |          |                  |      |
| US 2005095533          | A1   | 20050505 | US 2004-974759   |      |
| •                      |      |          |                  | 2004 |
|                        |      |          |                  | 1028 |
| JP 2005132749          | A2   | 20050526 | JP 2003-368421   |      |
|                        |      |          |                  | 2003 |
|                        |      |          |                  | 1029 |
| PRIORITY APPLN. INFO.: |      |          | JP 2003-368421 A |      |
|                        |      |          |                  | 2003 |
|                        |      |          |                  | 1029 |

OTHER SOURCE(S): MARPAT 142:454315

- AB Resist compns. comprises nitrogen-containing organic compds. having a benzimidazole structure and a specific ether chain moiety have an excellent resolution, form precisely configured patterns with minimized roughness of sidewalls and are useful in microfabrication using electron beams or deep-UV light.
- IT 118468-98-7P 639477-67-1P 671201-35-7P

(nitrogen-containing organic compound for **resist** composition and patterning process)

- RN 118468-98-7 HCAPLUS
- CN 1H-Benzimidazole, 1-(2-methoxyethyl)- (9CI) (CA INDEX NAME)

RN 639477-67-1 HCAPLUS

CN 1H-Benzimidazole, 1-[2-[2-(2-methoxyethoxy)ethoxy]ethyl]- (9CI) (CA INDEX NAME)

RN 671201-35-7 HCAPLUS

CN 1H-Benzimidazole, 1-[2-(2-methoxyethoxy)ethyl]- (9CI) (CA INDEX NAME)

IT 143656-17-1P 160665-97-4P 444995-61-3P 488086-49-3P 488719-18-2P 488795-64-8P 497241-32-4P 637324-61-9P 637324-85-7P 851211-18-2P 851211-19-3P 851211-20-6P 851211-22-8P 851211-23-9P 851211-24-0P 851211-25-1P 851211-26-2P 851211-27-3P

851211-28-4P
 (nitrogen-containing organic compound for resist composition and
 patterning process)

RN 143656-17-1 HCAPLUS

CN 1H-Benzimidazole, 1-(2-ethoxyethyl)- (9CI) (CA INDEX NAME)

RN 160665-97-4 HCAPLUS

CN 1H-Benzimidazole, 1-(2-ethoxyethyl)-2-methyl- (9CI) (CA INDEX NAME)

RN 444995-61-3 HCAPLUS

CN 1H-Benzimidazole, 1-(2-methoxyethyl)-2-methyl- (9CI) (CA INDEX NAME)

RN 488086-49-3 HCAPLUS

CN 1H-Benzimidazole, 2-ethyl-1-(2-methoxyethyl)- (9CI) (CA INDEX NAME)

RN 488719-18-2 HCAPLUS

CN 1H-Benzimidazole, 1-(2-methoxyethyl)-2-phenyl- (9CI) (CA INDEX NAME)

RN 488795-64-8 HCAPLUS

CN 1H-Benzimidazole, 1-(2-ethoxyethyl)-2-ethyl- (9CI) (CA INDEX NAME)

$$\underbrace{ \begin{array}{c} \text{N} \\ \text{N} \\ \text{CH}_2\text{--}\text{CH}_2\text{--}\text{OEt} \end{array} }^{\text{N}}$$

RN 497241-32-4 HCAPLUS

CN 1H-Benzimidazole, 1-(2-ethoxyethyl)-2-phenyl- (9CI) (CA INDEX NAME)

RN 637324-61-9 HCAPLUS

CN 1H-Benzimidazole, 2-ethyl-1-[2-(2-methoxyethoxy)ethyl]- (9CI) (CA INDEX NAME)

$$\begin{array}{c} \text{Et} \\ \\ \text{CH}_2\text{--}\text{CH}_2\text{--}\text{O}\text{--}\text{CH}_2\text{--}\text{CH}_2\text{--}\text{OMe} \end{array}$$

RN 637324-85-7 HCAPLUS

CN 1H-Benzimidazole, 1-[2-(2-methoxyethoxy)ethyl]-2-methyl- (9CI) (CA INDEX NAME)

$$\begin{array}{c|c} & \text{Me} \\ \hline & \text{N} \\ \hline & \text{CH}_2\text{--}\text{CH}_2\text{--}\text{O}\text{--}\text{CH}_2\text{--}\text{CH}_2\text{--}\text{OMe} \end{array}$$

RN 851211-18-2 HCAPLUS

CN 1H-Benzimidazole, 1-(2-propoxyethyl)- (9CI) (CA INDEX NAME)

RN 851211-19-3 HCAPLUS

CN 1H-Benzimidazole, 1-[2-(1-methylethoxy)ethyl]- (9CI) (CA INDEX NAME)

RN 851211-20-6 HCAPLUS

CN 1H-Benzimidazole, 1-[2-(1,1-dimethylethoxy)ethyl]- (9CI) (CA INDEX NAME)

$$\begin{array}{c|c} & & \\ & & \\ \hline & & \\ &$$

RN 851211-22-8 HCAPLUS

CN 1H-Benzimidazole, 1-[2-(2-methoxyethoxy)ethyl]-2-phenyl- (9CI) (CA INDEX NAME)

RN 851211-23-9 HCAPLUS

CN 1H-Benzimidazole, 1-[2-(2-ethoxyethoxy)ethyl]- (9CI) (CA INDEX NAME)

RN 851211-24-0 HCAPLUS

CN 1H-Benzimidazole, 1-[2-(2-ethoxyethoxy)ethyl]-2-methyl- (9CI) (CA INDEX NAME)

$$\begin{array}{c|c} & \text{Me} \\ \hline & \text{N} \\ & \text{CH}_2\text{--}\text{CH}_2\text{--}\text{O--}\text{CH}_2\text{--}\text{OEt} \end{array}$$

RN 851211-25-1 HCAPLUS

CN 1H-Benzimidazole, 1-[2-[2-(2-methoxyethoxy)ethoxy]ethyl]-2-methyl-(9CI) (CA INDEX NAME)

$$\begin{picture}(20,10) \put(0,0){\line(1,0){100}} \put(0,0){\line(1,0){10$$

RN 851211-26-2 HCAPLUS

CN 1H-Benzimidazole, 1-(3,6,9,12-tetraoxatridec-1-yl)- (9CI) (CA INDEX NAME)

RN 851211-27-3 HCAPLUS

CN 1H-Benzimidazole, 2-methyl-1-(3,6,9,12-tetraoxatridec-1-yl)- (9CI) (CA INDEX NAME)

RN 851211-28-4 HCAPLUS

CN 1H-Benzimidazole, 2-methyl-1-(3,6,9,12,15-pentaoxahexadec-1-yl)-(9CI) (CA INDEX NAME)

PAGE 1-A

PAGE 1-B

- CH<sub>2</sub>- OMe

IC ICM G03C001-73

INCL 430270100

CC 74-5 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

Section cross-reference(s): 38

ST nitrogen org compd photoresist compn patterning process

IT Photolithography

Photoresists

(nitrogen-containing organic compound for **resist** composition and patterning process)

IT 118468-98-7P 639477-67-1P 671201-35-7P

(nitrogen-containing organic compound for resist composition and

patterning process) 143656-17-1P 160665-97-4P 444995-61-3P IT 488086-49-3P 488719-18-2P 488795-64-8P 497241-32-4P 637324-61-9P 637324-85-7P 851211-18-2P 851211-19-3P 851211-20-6P 851211-21-7P 851211-22-8P 851211-23-9P 851211-24-0P 851211-25-1P 851211-26-2P 851211-27-3P 851211-28-4P 851211-29-5P (nitrogen-containing organic compound for resist composition and patterning process) 51-17-2, Benzimidazole 615-15-6, 2-MethylBenzimidazole IT 627-42-9, 2-Chloroethyl methyl ether 628-34-2, 2-Chloroethyl ethyl ether 716-79-0, 2-PhenylBenzimidazole 1848-84-6, 2-EthylBenzimidazole 13830-12-1, 2-Chloroethyl isopropyl ether 17229-11-7 41771-35-1, 2-Chloroethyl 2-ethoxyethyl ether 42149-74-6, 2-Chloroethyl propyl ether 52808-36-3, 2-Chloroethyl 2-methoxyethyl ether 52995-76-3 53067-04-2 57722-04-0 120259-67-8 (preparation of nitrogen-containing organic compound for resist composition and patterning process) L24 ANSWER 5 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN ACCESSION NUMBER: 2005:315916 HCAPLUS DOCUMENT NUMBER: 142:382185 Chemically amplified positive-working TITLE: resists sensitive for far-IR, x ray, and electron beam Nagai, Tomoki; Miyaji, Shoji; Hara, Hiromichi; INVENTOR (S): Murata, Makoto PATENT ASSIGNEE(S): JSR Ltd., Japan Jpn. Kokai Tokkyo Koho, 22 pp. SOURCE: CODEN: JKXXAF DOCUMENT TYPE: Patent LANGUAGE: Japanese FAMILY ACC. NUM. COUNT: PATENT INFORMATION:

| PATENT NO.             | KIND | DATE     | APPLICATION NO. | DATE |
|------------------------|------|----------|-----------------|------|
| <br>JP 2005099076      | A2   | 20050414 | JP 2003-329356  |      |
| UP 2003099076          | AZ   | 20030414 | OF 2003-329336  | 2003 |
| PRIORITY APPLN. INFO.: |      |          | JP 2003-329356  | 0922 |
|                        |      |          |                 | 2003 |
|                        |      |          |                 | 0922 |

OTHER SOURCE(S):

MARPAT 142:382185

GI

Q1 = 
$$CH-CH_2$$
 Q2 =  $CH_2$   $R_3$   $CH_2$   $R_3$   $CH_2$   $R_3$   $CH_2$   $R_3$   $CH_2$   $R_3$   $R_3$ 

- AB The resists contain (A) alkali-insol. polymers having repeating unit of Q1 (R1 = monovalent organic group, n = 1-3, m = 0-2) and Q2 [R2 = H, Me; R3 = C1-4 hydrocarbyl] becoming alkali soluble upon dissociation of C(R3)3 groups, and (B) N-sulfonyloxyimides and di-Ph iodonium salts as photoacid generators. Preferably, the resists further contain acid-diffusion inhibitors. The resists show high sensitivity for far IR, x ray, and electron beams.
- RN 193810-83-2 HCAPLUS
- CN 1H-Benzimidazole-1-carboxylic acid, 2-phenyl-, 1,1-dimethylethyl ester (9CI) (CA INDEX NAME)

- IC ICM G03F007-039
  - ICS G03F007-004; H01L021-027
- CC 74-5 (Radiation Chemistry, Photochemistry, and **Photographic** and Other Reprographic Processes)
  Section cross-reference(s): 38
- ST pos resist photoacid generator sulfonyloxyimide diphenyliodonium; far IR pos resist photoacid generator multiple; x ray pos resist photoacid generator multiple; electron beam pos resist photoacid generator multiple
- IT Positive photoresists

(UV, chemical amplified; chemical amplified pos.-working resist sensitive for far-IR, x ray, and electron beam)

IT Electron beam resists

X-ray resists

(pos.-working, chemical amplified; chemical amplified pos.-working resist sensitive for far-IR, x ray, and electron beam)

IT 716-79-0, 2-Phenylbenzimidazole 193810-83-2,

N-tert-Butoxycarbonyl-2-phenyl benzimidazole

(acid-diffusion inhibitor; in chemical amplified pos.-working resist sensitive for far-IR, x ray, and electron beam)

IT 288622-96-8P, p-tert-Butoxystyrene-p-hydroxystyrene-styrene copolymer 406198-55-8DP, p-Acetoxystyrene-p-tert-butoxystyrene-N,N-dimethylacrylamide-styrene copolymer, hydrolyzed 406198-64-9DP, p-Acetoxystyrene-p-tert-butoxystyrene-styrene copolymer, hydrolyzed 849671-40-5P, p-tert-Butoxystyrene-N,N-dimethylacrylamide-p-hydroxystyrene-styrene copolymer (in chemical amplified pos.-working resist sensitive for far-IR, x ray, and electron beam)

IT 66003-76-7, Diphenyliodonium trifluoromethanesulfonate
133710-62-0 194999-82-1 214534-44-8, Diphenyliodonium
10-camphorsulfonate 307531-76-6
(photoacid generator; in chemical amplified pos.-working
resist sensitive for far-IR, x ray, and electron beam)

L24 ANSWER 6 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

2004:1125476 HCAPLUS

DOCUMENT NUMBER:

142:65319

TITLE:

Acid generators and positively or negatively

working radiation-sensitive resin compositions containing the same

INVENTOR(S):

Ibata, Satoshi; Nagai, Tomoki; O, Isamu

PATENT ASSIGNEE(S):

JSR Ltd., Japan

SOURCE:

Jpn. Kokai Tokkyo Koho, 63 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

| PATENT NO.             | KIND | DATE     | APPLICATION NO. | DATE |
|------------------------|------|----------|-----------------|------|
|                        |      |          |                 |      |
| JP 2004359590          | A2   | 20041224 | JP 2003-158808  |      |
|                        |      |          |                 | 2003 |
|                        |      |          |                 | 0604 |
| PRIORITY APPLN. INFO.: |      |          | JP 2003-158808  |      |
|                        |      |          |                 | 2003 |
|                        |      |          |                 | 0604 |

OTHER SOURCE(S):

MARPAT 142:65319

GI

AB The acid generators comprise compds. having the structure of SO2(CF2)nSO2 (n = 2-10 integer), preferably, disulfonic acid onium salts SO3-(CF2)nSO3- 2M+ (n = 2-10 integer; M+ = monovalent onium cation). Preferably, M+ comprises sulfonium cations R1R2R3S+ or iodonium cations R4R5I+ (R1-R5 = C1-10 alkyl, C6-18 aryl; ≥1 of R1-R3 may be bonded together and form ring with S; R4 and R5 may be bonded together and form ring with I). Acid

generators comprising N, N'-di(sulfonyloximides) I (n = 2-10 integer; R6, R7 = H, monovalent organic group; R6 and R7 bonding to the same imide ring may be bonded together and form ring; Y1 = single bond, double bond, divalent organic group) are also claimed. The pos. working radiation-sensitive resin compns. contain (A) radiation-sensitive acid generators involving any of the above-mentioned acid generators and (B) resins which are insol. or slightly soluble in alkalis, bear acid-dissociable groups, and become soluble in alkalis upon dissociation of the acid-dissociable groups. neg.-working radiation-sensitive resin compns. contain (A) radiation-sensitive acid generators involving any of the above-mentioned acid generators, (C) alkali-soluble resins, and (D) compds. capable of crosslinking the alkali-soluble resins in the presence of acids. The acids generated from the acid generators have sufficiently high acidity and b.p., the diffusion length of the acids in resist films is appropriately short, mask pattern dependency is small, and focus depth is excellent. 193810-83-2, N-tert-Butoxycarbonyl-2-phenylbenzimidazole (diffusion controlling agent; disulfonic acid generators for pos. or neg. working radiation-sensitive resist

IT compns.)

RN 193810-83-2 HCAPLUS

CN 1H-Benzimidazole-1-carboxylic acid, 2-phenyl-, 1,1-dimethylethyl ester (9CI) (CA INDEX NAME)

IC ICM C07C309-06

> C07C381-12; C07D207-46; C07D209-52; C07D221-14; C07D491-18; G03F007-004; G03F007-038; G03F007-039; H01L021-027

CC 74-5 (Radiation Chemistry, Photochemistry, and

Photographic and Other Reprographic Processes)

disulfonic acid generator deep UV resist; pos photoresist disulfonic acid generator; neg photoresist disulfonic acid generator

IT Negative photoresists

Positive photoresists

(deep UV; disulfonic acid generators for pos. or neg. working radiation-sensitive resist compns.)

IT Sulfonic acids, preparation

> (di-; disulfonic acid generators for pos. or neg. working radiation-sensitive resist compns.)

IT Onium compounds

> (disulfonic acid; disulfonic acid generators for pos. or neg. working radiation-sensitive resist compns.)

IT Resists

ST

(neg.-working radiation-sensitive; disulfonic acid generators for pos. or neg. working radiation-sensitive resist compns.)

IT Resists

(pos.-working radiation-sensitive; disulfonic acid generators for pos. or neg. working radiation-sensitive resist

compns.) 17464-88-9

IT (crosslinking agent; disulfonic acid generators for pos. or neg. working radiation-sensitive resist compns.)

IT 102-71-6, Triethanolamine, uses 716-79-0, 2-Phenylbenzimidazole 1116-76-3, Tri-n-octylamine 1739-84-0, 1,2-Dimethylimidazole 193810-83-2, N-tert-Butoxycarbonyl-2-phenylbenzimidazole (diffusion controlling agent; disulfonic acid generators for pos. or neg. working radiation-sensitive resist compns.)

133710-62-0 138529-81-4, Bis(cyclohexylsulfonyl)diazomethane TΤ 144317-44-2, Triphenylsulfonium nonafluoro-n-butanesulfonate 209482-18-8

> (disulfonic acid generators for pos. or neg. working radiation-sensitive resist compns.)

809274-47-3P 809274-48-4P 809274-49-5P IT 809274-50-8P (disulfonic acid generators for pos. or neg. working radiation-sensitive resist compns.)

IT 109-92-2DP, Ethyl vinyl ether, reaction products with 4-tert-butoxystyrene-4-hydroxystyrene copolymer 95418-60-3DP, 4-tert-Butoxystyrene homopolymer, partially hydrolyzed 123589-22-0DP, 4-tert-Butoxystyrene-4-hydroxystyrene copolymer, reaction products with Et vinyl ether 123589-22-0P, 4-tert-Butoxystyrene-4-hydroxystyrene copolymer 200808-68-0P, tert-Butyl acrylate-4-hydroxystyrene-styrene copolymer 221549-67-3DP, 4-Acetoxystyrene-tert-butyl acrylate-styrene copolymer, hydrolyzed 288622-96-8P, 4-tert-Butoxystyrene-4hydroxystyrene-styrene copolymer 340964-24-1P 340964-38-7P 406198-64-9DP, 4-Acetoxystyrene-4-tert-butoxystyrene-styrene copolymer, hydrolyzed 428516-13-6P 479628-09-6P 670248-60-9P 690258-42-5P 726175-42-4P

> (disulfonic acid generators for pos. or neg. working radiation-sensitive resist compns.)

IT 24979-74-6, 4-Hydroxystyrene-styrene copolymer (disulfonic acid generators for pos. or neg. working radiation-sensitive resist compns.)

L24 ANSWER 7 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

2004:1058692 HCAPLUS

DOCUMENT NUMBER:

142:45905

TITLE:

Basic compounds, resist materials,

and pattern formation

INVENTOR(S):

Watanabe, Takeshi; Kaneo, Takeshi; Hasegawa,

Applicant

Koji

PATENT ASSIGNEE(S):

Shin-Etsu Chemical Industry Co., Ltd., Japan

SOURCE:

Jpn. Kokai Tokkyo Koho, 57 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

Japanese

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| PATENT NO.    | KIND | DATE     | APPLICATION NO. | DATE         |
|---------------|------|----------|-----------------|--------------|
| JP 2004347738 | A2   | 20041209 | JP 2003-142853  | 2003         |
| US 2005008968 | A1   | 20050113 | US 2004-849197  | 0521<br>2004 |

PRIORITY APPLN. INFO.:

JP 2003-142853

0520

2003 0521

OTHER SOURCE(S):

MARPAT 142:45905

GI

Ι

AB The resist materials contain ≥1

benzimidazole-based basic compds. having polar functional groups I (R1 = H, C1-10 normal, branched, or cyclic alkyl, C6-10 aryl, C7-10 aralkyl; R2 = C1-20 normal, branched, or cyclic alkyl having ≥1 polar functional groups selected from ester, acetal, and cyano; R2 may contain OH, carbonyl, ether, sulfide, and/or carbonate). Patterns are formed by (1) applying the materials on substrates, (2) heating, (3) exposing to ≤300-nm high energy beam or electron beam via photomasks, (4) heating, and (5) developing. Six kinds of Markush structures of benzimidazole-based basic compds. are also claimed. The resist materials show high resolution and large focus margin.

IT 46400-55-9P 58553-97-2P, 1H-Benzimidazole-1butanenitrile 102025-46-7P 502651-76-5P 804550-88-7P 804550-89-8P 804550-90-1P

804550-88-7P 804550-89-8P 804550-90-1P 804550-91-2P 804550-93-4P

(benzimidazole-based basic compds. for resists with high resolution and large focus margin)

RN 46400-55-9 HCAPLUS

CN 1H-Benzimidazole-1-ethanol, acetate (ester) (9CI) (CA INDEX NAME)

RN 58553-97-2 HCAPLUS

CN 1H-Benzimidazole-1-butanenitrile (9CI) (CA INDEX NAME)

RN 102025-46-7 HCAPLUS

CN 1H-Benzimidazole-1-ethanol, 2-phenyl-, acetate (ester) (9CI) (CA INDEX NAME)

RN 502651-76-5 HCAPLUS

CN 1H-Benzimidazole-1-butanoic acid, ethyl ester (9CI) (CA INDEX NAME)

RN 804550-88-7 HCAPLUS

CN 1H-Benzimidazole-1-propanol, acetate (ester) (9CI) (CA INDEX NAME)

RN 804550-89-8 HCAPLUS

CN Acetic acid, methoxy-, 2-(1H-benzimidazol-1-yl)ethyl ester (9CI) (CA INDEX NAME)

RN 804550-90-1 HCAPLUS

CN 1H-Benzimidazole-1-propanoic acid, 2-phenyl-, methyl ester (9CI) (CA INDEX NAME)

RN 804550-91-2 HCAPLUS

CN 1H-Benzimidazole, 1-[2-[(2-methoxyethoxy)methoxy]ethyl]- (9CI) (CA INDEX NAME)

RN 804550-93-4 HCAPLUS

CN 1H-Benzimidazole, 1-[2-(1-ethoxyethoxy)ethyl]- (9CI) (CA INDEX NAME)

IC ICM G03F007-004

ICS C07D235-12; C07D235-16; C07D405-06; C09K003-00; G03F007-038; G03F007-039; H01L021-027

CC 74-5 (Radiation Chemistry, Photochemistry, and **Photographic** and Other Reprographic Processes) Section cross-reference(s): 28

ST benzimidazole basic compd resist pattern formation; focus margin benzimidazole basic compd resist

IT Negative photoresists

Positive photoresists

(benzimidazole-based basic compds. for **resists** with high resolution and large focus margin)

IT 6293-66-9, Diphenyliodonium tosylate 138529-81-4, Bis(cyclohexanesulfonyl)diazomethane 144317-44-2, Triphenylsulfonium perfluorobutanesulfonate 161453-44-7 266308-64-9

(acid generators; benzimidazole-based basic compds. for resists with high resolution and large focus margin)

IT 46400-55-9P 58553-97-2P, 1H-Benzimidazole-1-butanenitrile 102025-46-7P 172678-64-7P 502651-76-5P 804550-88-7P 804550-89-8P 804550-90-1P 804550-91-2P 804550-93-4P

804550-95-6P (benzimidazole-based basic compds. for **resists** with

high resolution and large focus margin)

IT 24979-74-6, 4-Hydroxystyrene-styrene copolymer 123589-22-0,

```
4-tert-Butoxystyrene-4-hydroxystyrene copolymer 129674-22-2
     158593-28-3 221900-55-6 279243-86-6 326925-68-2
     336620-37-2 443796-30-3 645393-08-4
                                            651043-12-8
     798570-42-0
                 804550-98-9 804551-00-6
        (benzimidazole-based basic compds. for resists with
       high resolution and large focus margin)
IT
     6340-03-0P, 1H-Benzimidazole-1-ethanol
        (intermediates in base preparation; benzimidazole-based basic
        compds. for resists with high resolution and large focus
       margin)
     51-17-2, Benzimidazole 75-21-8, Ethylene oxide, reactions
IT
     96-33-3, Methyl acrylate 108-24-7, Acetic anhydride 592-33-6,
     3-Bromopropyl acetate 716-79-0, 2-Phenylbenzimidazole
     2969-81-5, Ethyl 4-bromobutanoate 5332-06-9,
     4-Bromobutyronitrile 6290-49-9, Methyl methoxyacetate
     18742-02-4, 2-(2-Bromoethyl)-1,3-dioxolane 36236-76-7,
     4-Bromomethyl-2,2-dimethyl-1,3-dioxolane 78487-70-4
     804550-96-7
        (reactants in base preparation; benzimidazole-based basic compds.
        for resists with high resolution and large focus margin)
L24 ANSWER 8 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN
                        2004:392711 HCAPLUS
ACCESSION NUMBER:
DOCUMENT NUMBER:
                        140:414937
TITLE:
                        Radiation-sensitive resin composition
                        containing specific resin
                        Nishimura, Yukio; Ishii, Hiroyuki; Nishimura,
INVENTOR(S):
                        Isao; Kobayashi, Eiichi
PATENT ASSIGNEE(S):
                        JSR Corporation, Japan
SOURCE:
                        PCT Int. Appl., 126 pp.
                        CODEN: PIXXD2
DOCUMENT TYPE:
                        Patent
LANGUAGE:
                        Japanese
FAMILY ACC. NUM. COUNT:
PATENT INFORMATION:
    PATENT NO.
                       KIND DATE
                                          APPLICATION NO.
                                                                 DATE
                        ----
                               -----
                                          WO 2003-JP13560
    WO 2004040376
                        A1 20040513
                                                                  2003
                                                                  1023
    WO 2004040376
                        B1
                              20040708
        W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, BZ, CA,
            CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, ES, FI,
            GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, KE, KG, KR,
            KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW,
            MX, MZ, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD,
            SE, SG, SK, SL, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US,
            UZ, VC, VN, YU, ZA, ZM, ZW
        RW: GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZM, ZW, AM,
            AZ, BY, KG, KZ, MD, RU, TJ, TM, AT, BE, BG, CH, CY, CZ,
            DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IT, LU, MC, NL,
            PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN,
            GQ, GW, ML, MR, NE, SN, TD, TG
    JP 2005043852
                         A2
                               20050217
                                          JP 2003-359842
                                                                  2003
                                                                  1020
                       A1
    AU 2003280571
                               20040525 AU 2003-280571
                                                                  2003
```

| EP 1557718             | A1 20050727     | EP 2003-769916                          | 1023         |
|------------------------|-----------------|---|--------------|
|                        |                 |   | 2003         |
| D. AM DE CU            | DE DY HO ED     | GD GD TM TT 111                         | 1023         |
|                        |                 | GB, GR, IT, LI, LU, RO, MK, CY, AL, TR, |              |
| EE, HU, SK             | 51, HI, HV, FI, | RO, MR, CI, ALI, IR,                    | BG, CZ,      |
| PRIORITY APPLN. INFO.: |                 | JP 2002-315021                          | A            |
|                        |                 |   | 2002         |
|                        |                 |   | 1029         |
|                        |                 |   | _            |
|                        |                 | JP 2003-192477                          | Α 2002       |
|                        |                 |   | 2003<br>0704 |
|                        |                 |   | 0704         |
|                        |                 | WO 2003-JP13560                         | W            |
|                        |                 |   | 2003         |
|                        |                 |   | 1023         |

GI

$$\begin{array}{c|c}
R^{1?} \\
\hline
CH_2 - C \\
\hline
O \\
\hline
N \\
X^1 - X^1 \\
X^2 - N^2
\end{array}$$
OH

I

The invention relates to a radiation-sensitive resin composition which is useful as a chemical amplified resist in micro-fabrication with various radiations including far UV rays such as KrF excimer laser radiation and ArF excimer laser radiation. The composition comprises [A] a resin comprising repeating units represented by the general formulaI(R1a = H, Me, C1-4 hydroxyalkyl, C1-4 perfluoroalkyl; X1-2 = H, F, C1-4 alkyl, C1-4 fluorinated alkyl, l = integer 0-5; n = integer 0-2), [B] a radiation-sensitive acid generator (such as 1-(4-n-butoxynaphthyl)tetrahydrothiophenium nonafluoro-n -butanesulfonate), and, if necessary, [C] an acid diffusion

controller (such as phenylbenzimidazole).

- 193810-83-2, N-tert-Butoxycarbonyl-2-phenylbenzimidazole IT (radiation-sensitive resin composition)
- RN 193810-83-2 HCAPLUS
- 1H-Benzimidazole-1-carboxylic acid, 2-phenyl-, 1,1-dimethylethyl CN ester (9CI) (CA INDEX NAME)

- IC ICM G03F007-039
- CC74-5 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes) Section cross-reference(s): 35
- Light-sensitive materials TТ

## Photoresists

(radiation-sensitive resin composition)

- 109384-19-2, N-(tert-Butoxycarbonyl)-4-hydroxypiperidine TT 193810-83-2, N-tert-Butoxycarbonyl-2-phenylbenzimidazole (radiation-sensitive resin composition)
- REFERENCE COUNT: THERE ARE 12 CITED REFERENCES AVAILABLE 12 FOR THIS RECORD. ALL CITATIONS AVAILABLE

IN THE RE FORMAT

L24 ANSWER 9 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

2004:203439 HCAPLUS

DOCUMENT NUMBER:

140:261399

TITLE:

Low silicon-outgassing resist for

bilayer lithography

INVENTOR (S):

Khojasteh, Mahmoud M.; Kwong, Ranee W.; Chen, Kuang-Jung; Varanasi, Pushkara Rao; Allen,

Robert D.; Brock, Phillip; Houle, Frances;

Sooriyakumaran, Ratnam

PATENT ASSIGNEE(S):

International Business Machines Corp., USA

SOURCE: U.S. Pat. Appl. Publ., 7 pp.

CODEN: USXXCO

DOCUMENT TYPE:

Patent English

LANGUAGE:

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| PATENT NO.            | KIND       | DATE     | APPLICATION NO. | DATE |
|-----------------------|------------|----------|-----------------|------|
|                       |            |          |                 |      |
|                       |            |          |                 |      |
| US 2004048187         | A1         | 20040311 | US 2002-241937  |      |
|                       |            |          |                 | 2002 |
| And the second of the |            |          |                 | 0911 |
| US-677041-9           | B2         | 20040803 |                 |      |
| WO 2004068243         | <b>A</b> 1 | 20040812 | WO 2003-US28770 |      |
|                       |            |          |                 | 2003 |
|                       |            |          |                 | 0911 |

AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, ES, FI,

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GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG,
             KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK,
             MN, MW, MX, MZ, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU,
             SC, SD, SE, SG, SK, SL, SY, TJ, TM, TN, TR, TT, TZ, UA,
             UG, UZ, VC, VN, YU, ZA, ZM, ZW
         RW: GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZM, ZW, AM,
             AZ, BY, KG, KZ, MD, RU, TJ, TM, AT, BE, BG, CH, CY, CZ,
             DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IT, LU, MC, NL,
             PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN,
             GQ, GW, ML, MR, NE, SN, TD, TG
                                20050629
    EP 1546813
                          A1
                                            EP 2003-815294
                                                                    2003
                                                                    0911
         R: AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE,
             MC, PT, IE, SI, LT, LV, FI, RO, MK, CY, AL, TR, BG, CZ,
             EE, HU, SK
PRIORITY APPLN. INFO.:
                                            US 2002-241937
                                                                    2002
                                                                    0911
                                            WO 2003-US28770
                                                                    2003
                                                                    0911
```

AB The silicon-containing resist compns. which have low silicon outgassing and high resolution lithog. performance, especially in bilayer or multilayer lithog. applications using 193 nm or shorter wavelength imaging radiation are enabled by the presence of an imaging polymer having silicon-containing, non-acid-labile pendant groups. The resist compns. of the invention are preferably further characterized by the substantial absence of silicon-containing acid-labile moieties.

IT 193810-83-2

(low silicon-outgassing resist for bilayer lithog.)

RN 193810-83-2 HCAPLUS

CN 1H-Benzimidazole-1-carboxylic acid, 2-phenyl-, 1,1-dimethylethyl ester (9CI) (CA INDEX NAME)

IC ICM G03F007-038

ICS G03F007-38

INCL 430270100; 430313000; 430330000; 430905000

CC 74-5 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

low silicon outgassing resist bilayer lithog

photoresist compn

IT Photoresists

ST

(low silicon-outgassing resist for bilayer lithog.)

IT 669067-94-1P 669067-95-2P

(low silicon-outgassing resist for bilayer lithog.)

IT 193810-83-2 218151-20-3 240435-11-4 307531-76-6

(low silicon-outgassing resist for bilayer lithog.)

REFERENCE COUNT:

THERE ARE 13 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE

IN THE RE FORMAT

L24 ANSWER 10 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

13

ACCESSION NUMBER:

2003:692240 HCAPLUS

DOCUMENT NUMBER:

139:308867

TITLE:

Synthesis and UV/vis spectra of J-aggregating 5,5',6,6'-tetrachlorobenzimidacarbocyanine dyes for artificial light-harvesting systems

and for asymmetrical generation of

supramolecular helices

AUTHOR (S):

Pawlik, Andreas; Ouart, Andre; Kirstein, Stefan; Abraham, Hans-Werner; Daehne,

Siegfried

CORPORATE SOURCE:

Max-Planck-Institute of Colloids and Interfaces, Golm/Potsdam, 14476, Germany

SOURCE:

European Journal of Organic Chemistry (2003),

(16), 3065-3080

CODEN: EJOCFK; ISSN: 1434-193X Wiley-VCH Verlag GmbH & Co. KGaA

DOCUMENT TYPE:

PUBLISHER:

Journal English

OTHER SOURCE(S):

CASREACT 139:308867

A new class of dyes, in which the self-assembling property of surfactants is combined with the capability for light energy propagation over long distances in dye J-aggregates, is described. This has been achieved by the syntheses of achiral 5,5',6,6'-tetrachlorobenzimidacarbocyanine dyes possessing systematically varied hydrophobic and hydrophilic substituents at their nitrogen atoms. These substituents are introduced into a 5,6-dichlorobenzimidazole precursor by substitution, either firstly by nucleophilic reaction with  $\omega$ -bromoalkylnitriles and secondly by quaternization with alkyl bromides or firstly by nucleophilic reaction with alkyl bromides and secondly by quaternization with  $\omega$ -bromoalkylnitriles or ω-bromoalkyl esters and subsequent saponification The UV/visible spectra of 20 differently substituted dyes containing the same chromophore have been investigated. The spectra of the dye monomers in DMSO are nearly identical, with no signs of optically activity, whereas in aqueous alkaline solns. quite different spectra are obtained for the dyes, indicating the formation of different aggregates depending on the nitrogen substituents. One of these types of J-aggregate is optically inactive and displays a single red-shifted (with respect to the dye monomers) absorption band, resembling the behavior of J-aggregates of common cyanine dyes. In the cases of strongly amphiphilic 5,5',6,6'benzimidacarbocyanines with 1,1'-dialkyl substituents longer than hexyl and 3,3'-bis(2-carboxyethyl), 3,3'-bis(3-carboxypropyl), or 3,3'-bis(3-sulfopropyl) substituents, a new type of J-aggregate is formed, and is distinguished by a doubly or even triply split J-absorption band that displays optical activity. A third type of aggregate showing different spectral behavior occurs when the dyes contain very short 3,3'-bis(carboxymethyl) substituents or strongly hydrophobic fluorinated octyl groups, or when all four nitrogen atoms are identically substituted by hydrophilic 3-carboxypropyl groups. The various types of dye aggregates have been characterized through UV/visible spectroscopic parameters such as the positions and widths of the absorption and

fluorescence bands, the Stokes' shifts, the coupling consts., and the strength of the J-band splitting. The results provide new prospects for the development of new artificial light-harvesting systems as well as for the understanding of the evolution of asymmetry in the biosphere.

IT 611233-49-9P

(intermediate; preparation and UV/vis spectra of J-aggregating cyanine dyes)

RN 611233-49-9 HCAPLUS

CN 1H-Benzimidazole-1-butanenitrile, 5,6-dichloro-2-methyl- (9CI) (CA INDEX NAME)

CC 41-11 (Dyes, Organic Pigments, Fluorescent Brighteners, and Photographic Sensitizers)

Section cross-reference(s): 28, 73

IT 163403-28-9P 6858-62-4P 163403-24-5P 171354-91-9P 251095-00-8P 611233-49-9P 611233-53-5P 611233-54-6P 611233-56-8P 611233-55-7P 611233-57-9P 611233-58-0P 611233-59-1P 611233-62-6P 611233-60-4P 611233-61-5P 611233-64-8P 611233-63-7P

(intermediate; preparation and UV/vis spectra of J-aggregating cyanine dyes)

REFERENCE COUNT:

52 THERE ARE 52 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L24 ANSWER 11 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

2003:510302 HCAPLUS

DOCUMENT NUMBER:

139:76306

TITLE:

Heat-developable photographic material giving

high-contrast image

INVENTOR(S):

Usakawa, Yasushi; Hanyu, Takeshi; Yasukawa,

Hiroyuki

PATENT ASSIGNEE(S):

Konica Co., Japan

SOURCE:

Jpn. Kokai Tokkyo Koho, 27 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

Japanese

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| PATENT NO.             | KIND | DATE     | APPLICATION NO. | DATE         |
|------------------------|------|----------|-----------------|--------------|
| <br>ЈР 2003186140      | A2   | 20030703 | JP 2001-381446  |              |
|                        |      |          |                 | 2001<br>1214 |
| PRIORITY APPLN. INFO.: |      |          | JP 2001-381446  |              |
|                        |      |          |                 | 2001         |
|                        |      |          |                 | 1214         |

OTHER SOURCE(S):

MARPAT 139:76306

The material has a photosensitive layer containing a photosensitive Ag halide on a support, wherein at least one of a photosensitive layer or a light-insensitive layer contains an organic Ag salt, a reducing agent, and CXW:CHA and/or CYA:CHR (X = substituted alkyl, substituted alkenyl, alkynyl, aryl, heterocyclic, halo, acyl, thioacyl, oxalyl, oxyoxalyl, -S-oxalyl, oxamoyl, oxycarbonyl, -S-carbonyl, carbamoyl, thiocarbamoyl, sulfonyl, sulfinyl, oxysulfonyl, -S-sulfonyl, sulfamoyl, oxysulfinyl, -S-sulfinyl, sulfinamoyl, phosphoryl, nitro, imino, N-carbonylimino, N-sulfonylimino, ammonium, sulfonium, phosphonium, pyrylium, immonium; W = H, alkyl, aryl, oxy, thio, amino, nonarom. heterocyclic, silyl; A = N-containing aromatic heterocyclic group linking through N in the ring; Y = H, substituent; R = halo, oxy, thio, amino, heterocyclic, silyl). Preferably, (a) the photosensitive Ag halide is doped with transition metal complexes and/or (b) the photog. material contains hydrazines. The material shows high sensitivity and low fogging even stored at high temperature and humidity.

IT 552301-65-2 552301-67-4

(heat-developable photog. material using N-containing heterocyclic double bond compds. for high-contrast image)

RN 552301-65-2 HCAPLUS

CN 3-Buten-2-one, 3-(1H-benzimidazol-1-yl)-4-ethoxy-1,1-difluoro-(9CI) (CA INDEX NAME)

RN 552301-67-4 HCAPLUS

CN Benzonitrile, 4-[2-(5-chloro-1H-benzimidazol-1-yl)-1-oxo-3-(triphenylmethoxy)-2-propenyl]- (9CI) (CA INDEX NAME)

IC ICM G03C001-498

CC 74-2 (Radiation Chemistry, Photochemistry, and **Photographic** and Other Reprographic Processes)

IT 85598-48-7 552301-51-6 552301-52-7 552301-53-8 552301-54-9 552301-55-0 552301-56-1 552301-57-2 552301-58-3

552301-59-4 552301-60-7 552301-61-8 552301-62-9 552301-64-1 **552301-65-2** 552301-66-3 552301-63-0 552301-67-4 552301-68-5 552301-69-6 552301-70-9 552301-71-0 552301-72-1 552301-73-2 552301-74-3 552301-76-5 552301-77-6 552301-75-4

(heat-developable photog. material using N-containing heterocyclic double bond compds. for high-contrast image)

L24 ANSWER 12 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

2003:111378 HCAPLUS

DOCUMENT NUMBER:

138:161077

TITLE:

Radiation-sensitive chemically amplified resist resin composition containing specific nitrogen-containing compound as

acid-diffusion-control agent

INVENTOR(S):

Nagai, Tomoki; Kobayashi, Eiichi; Shimokawa,

Tsutomu

PATENT ASSIGNEE(S):

JSR Ltd., Japan

SOURCE:

Jpn. Kokai Tokkyo Koho, 25 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

Japanese

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| PATENT NO.             | KIND | DATE     | APPLICATION NO. | DATE |
|------------------------|------|----------|-----------------|------|
|                        |      |          |                 |      |
|                        |      |          |                 |      |
| JP 2003043677          | A2   | 20030213 | JP 2001-234136  |      |
|                        |      |          |                 | 2001 |
|                        |      |          |                 | 0801 |
| PRIORITY APPLN. INFO.: |      |          | JP 2001-234136  |      |
|                        |      |          |                 | 2001 |
|                        |      |          |                 | 0801 |

## OTHER SOURCE(S): MARPAT 138:161077

AB The title composition contains a radiation-sensitive acid-generator and an acid-sensitive alkali solubilizable resin or both alkali solubilizable resin/alkali-solubility-controlling agent for the resin, wherein sulfur compound (R1) (R2)N-S(O)2-R3(R1-3 = H, C1-20 hydrocarbon). The composition provides the **resists** of high resolution, high durability, and good storageability.

IT 428859-16-9P

(radiation-sensitive chemical amplified resist resin composition containing specific nitrogen-containing compound)

RN 428859-16-9 HCAPLUS

CN 1H-Benzimidazole, 1-(methoxymethyl)-2-phenyl- (9CI) (CA INDEX NAME)

IC ICM G03F007-004

ICS G03F007-038; G03F007-039; H01L021-027

```
CC
     74-5 (Radiation Chemistry, Photochemistry, and
     Photographic and Other Reprographic Processes)
ST
     radiation sensitive amplified resist resin compn
IT
     Resists
        (radiation-sensitive, chemical amplified; radiation-sensitive
        chemical amplified resist resin composition containing specific
        nitrogen-containing compound)
     101-83-7, Dicyclohexylamine 63458-90-2, 1H-Imidazole, 1-methyl-,
IT
     mono(4-methylbenzenesulfonate)
        (acid-diffusion-control agent; radiation-sensitive chemical
        amplified resist resin composition containing specific
        nitrogen-containing compound)
IT
     107-30-2, Methoxymethyl chloride 122-39-4, Diphenylamine,
     reactions 288-32-4, Imidazole, reactions 716-79-0,
     2-Phenylbenzimidazole 4106-18-7, 1H-Benzotriazole,1-
     (phenylsulfonyl) - 13578-48-8, 1H-1,2,4-Triazole, 1-(phenylsulfonyl) - 18162-48-6
        (radiation-sensitive chemical amplified resist resin
        composition containing specific nitrogen-containing compound)
     4703-19-9P 15728-50-4P 39830-56-3P 46248-01-5P
TT
     95418-60-3DP, p-tert-Butoxystyrene homopolymer, hydrolized
     123589-22-0DP, ethoxyethyl ether 200808-68-0P 330576-44-8P
     406198-64-9P 428859-16-9P 479628-09-6P 494868-77-8P
        (radiation-sensitive chemical amplified resist resin
        composition containing specific nitrogen-containing compound)
L24 ANSWER 13 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN
ACCESSION NUMBER:
                       2002:807548 HCAPLUS
DOCUMENT NUMBER:
                        137:331078
TITLE:
                        Radiation-sensitive resin composition
                         containing polycyclic compound for chemical
                         amplification resist
                         Yamamoto, Masashi; Ishida, Hidemitsu; Ishii,
INVENTOR(S):
                         Hiroyuki; Kajita, Toru
PATENT ASSIGNEE(S):
                         JSR Ltd., Japan
                         Jpn. Kokai Tokkyo Koho, 61 pp.
SOURCE:
                         CODEN: JKXXAF
DOCUMENT TYPE:
                         Patent
LANGUAGE:
                         Japanese
FAMILY ACC. NUM. COUNT:
PATENT INFORMATION:
                                          APPLICATION NO.
                                                                   DATE
    PATENT NO.
                       KIND
                               DATE
                                           JP 2001-113462
     JP 2002311590
                        A2
                               20021023
                                                                   2001
                                                                   0412
PRIORITY APPLN. INFO.:
                                           JP 2001-113462
                                                                   2001
                                                                   0412
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GΙ

<sup>\*</sup> STRUCTURE DIAGRAM TOO LARGE FOR DISPLAY - AVAILABLE VIA OFFLINE PRINT

- The radiation-sensitive resin composition comprises (1) a hardly alkaline soluble resin or a alkaline insol. resin, which, becoming alkaline soluble by reaction with an acid, has repeating units selected from I, II, III (R1,3,5 = H, Me; R2,4,6 = H, C1-4alkyl; X = methylene, O, S; a = integer 1-5) and a repeating unit [CR7(COOCR83)CH2] (R7 = H, Me; R8 = C4-20 monovalent aliphatic hydrocarbon, etc.), (2) an photoacid, and (3) a polycyclic compound having the mol. weight ≤1,000. The radiation-sensitive resin composition provided a fine pattern when it is used as a far-UV photoresist.
- IT 193810-83-2, N-tert-Butoxycarbonyl-2-phenylbenzimidazole (acid diffusion suppressing agent; far-UV chemical amplification-type photoresist resin composition from)
  RN 193810-83-2 HCAPLUS
- CN 1H-Benzimidazole-1-carboxylic acid, 2-phenyl-, 1,1-dimethylethyl ester (9CI) (CA INDEX NAME)

- IC ICM G03F007-039
  - ICS C08F220-18; G03F007-004; H01L021-027
- CC 74-5 (Radiation Chemistry, Photochemistry, and **Photographic** and Other Reprographic Processes) Section cross-reference(s): 35, 38
- ST chem amplification resist resin compn polycyclic compd; far UV photoresist compn
- IT Photoresists
  - (far-UV chemical amplification-type **photoresist** resin composition containing polycyclic compound)
- IT 1148-79-4, 2,2':6',2''-Terpyridine 193810-83-2,
  - N-tert-Butoxycarbonyl-2-phenylbenzimidazole 330576-56-2,
    - N-t-Butoxycarbonyldicyclohexylamine
      - (acid diffusion suppressing agent; far-UV chemical amplification-type **photoresist** resin composition from)
- IT 195000-69-2P 340964-38-7P 340964-44-5P 473699-88-6P
  - 473699-89-7P
    (far-UV chemical amplification-type **photoresist** resin composition from)

- IT 96-48-0,  $\gamma$ -Butyrolactone 108-94-1, Cyclohexanone, uses 110-43-0, 2-Heptanone 84540-57-8, Propylene glycol monomethyl ether acetate

(solvent; far-UV chemical amplification-type photoresist
resin composition from)

L24 ANSWER 14 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 2002:553153 HCAPLUS

DOCUMENT NUMBER: 137:116956

TITLE:

Radiation-sensitive resin composition

INVENTOR(S):

Nishimura, Yukio; Yamamoto, Masafumi; Kataoka,

Atsuko; Kajita, Toru

PATENT ASSIGNEE(S): SOURCE: JSR Corporation, Japan Eur. Pat. Appl., 30 pp.

CODEN: EPXXDW

DOCUMENT TYPE: LANGUAGE: Patent English

FAMILY ACC. NUM. COUNT:

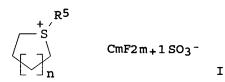
PATENT INFORMATION:

| PA'      | TENT 1 | NO.      |      |     | KIN       | )   | DATE |      | APPI    | LICAT: | ION 1 | . OI |     | DATE |
|----------|--------|----------|------|-----|-----------|-----|------|------|---------|--------|-------|------|-----|------|
|          |        |          |      |     |           | -   |      |      |         |        |       |      |     |      |
| EP       | 12254  | -<br>180 |      |     | A2        |     | 2002 | 0724 | EP 2    | 2002-3 | 1244  |      |     |      |
|          |        |          |      |     |           |     |      |      |         |        |       |      |     | 2002 |
|          |        |          |      |     |           |     |      |      |         |        |       |      |     | 0117 |
| EP       | 12254  | 180      |      |     | <b>A3</b> |     | 2003 | 0326 |         |        |       |      |     |      |
|          | R:     | AT,      | BE,  | CH, | DE,       | DK, | ES,  | FR,  | GB, GR, | , IT,  | LI,   | LU,  | ΝL, | SE,  |
|          |        | MC,      | PT,  | ΙE, | SI,       | LT, | LV,  | FI,  | RO, MK  | , CY,  | AL,   | TR   |     |      |
| US       | 20023  | 1321     | 81   |     | A1        |     | 2002 | 0919 | US 2    | 2002-4 | 16080 | )    |     |      |
|          |        |          |      |     |           |     |      |      |         |        |       |      |     | 2002 |
|          |        |          |      |     |           |     |      |      |         |        |       |      |     | 0116 |
| US       | 68382  | 225      |      |     | B2        |     | 2005 | 0104 |         |        |       |      |     |      |
| JP       | 20031  | L730     | 26   |     | A2        |     | 2003 | 0620 | JP 2    | 2002-9 | 9054  |      |     |      |
|          |        |          |      |     |           |     |      |      |         |        |       |      |     | 2002 |
|          |        |          |      |     |           |     |      |      |         |        |       |      |     | 0117 |
| PRIORITY | Y APPI | N.       | INFO | . : |           |     |      |      | JP 2    | 2001-1 | 10005 | 5    | 7   | A    |
|          |        |          |      |     |           |     |      |      |         |        |       |      |     | 2001 |
|          |        |          |      |     |           |     |      |      |         |        |       |      |     | 0118 |
|          |        |          |      |     |           |     |      |      |         |        |       |      |     |      |
|          |        |          |      |     |           |     |      |      | JP 2    | 2001-3 | 30382 | 20   | 1   | A    |
|          |        |          |      |     |           |     |      |      |         |        |       |      | _   | 2001 |
|          |        |          |      |     |           |     |      |      |         | •      |       |      |     | 0928 |
|          |        |          |      |     |           |     |      |      |         |        |       |      |     |      |

OTHER SOURCE(S):

MARPAT 137:116956

GI



The present invention relates to a radiation sensitive resin composition suitable as a chemical amplified resist useful for microfabrication utilizing various types of radiation, which exhibits high transparency, excellent resolution, dry etching resistance, and sensitivity, produces good pattern shapes, and well adheres to substrates. The radiation sensitive resin composition comprises (1) acid-dissociable group-containing resin insol. in alkali but becoming soluble in alkali when the acid-dissociable group dissocs., and containing recurring unit with specific structures; (2) a photoacid generator of formula I (R5 = aromatic hydrocarbon group; m = 1-8; n = 0-5).

IT 193810-83-2

(acid diffusion controller; radiation-sensitive resin composition

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for photoresist containing)
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RN 193810-83-2 HCAPLUS

1H-Benzimidazole-1-carboxylic acid, 2-phenyl-, 1,1-dimethylethyl CN ester (9CI) (CA INDEX NAME)

ICM G03F007-039 IC

ICS G03F007-004

CC 74-5 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes) Section cross-reference(s): 35, 38

ST photoresist resin compn acid generator

IT Photoresists

(radiation-sensitive resin composition for)

IT 1116-76-3, Tri-n-octylamine 4847-93-2 7560-83-0, Methyldicyclohexylamine 193810-83-2 330576-56-2, N-t-Butoxycarbonyldicyclohexylamine

> (acid diffusion controller; radiation-sensitive resin composition for **photoresist** containing)

ΤT 66003-78-9, Triphenylsulfonium trifluoromethanesulfonate 144317-44-2, Triphenylsulfonium nonafluoro-n-butanesulfonate 209482-18-8 330576-58-4 194999-85-4 380886-84-0 406198-76-3

> (acid generator; radiation-sensitive resin composition for photoresist containing)

IT 157692-53-0, tert-Butyl deoxycholate 169228-97-1, Di-tert-butyl 1,3-adamantanedicarboxylate 231296-44-9, t-Butoxycarbonylmethyl deoxycholate

(additive; radiation-sensitive resin composition for photoresist containing)

340964-24-1 340964-44-5 IT 426262-70-6 443346-74-5 443346-76-7 443346-77-8

(resin; radiation-sensitive resin composition for photoresist containing)

TT 108-94-1, Cyclohexanone, uses 110-43-0, 2-Heptanone 763-69-9. Ethyl 3-ethoxypropionate 84540-57-8, Propylene glycol monomethyl ether acetate

(solvent; radiation-sensitive resin composition for photoresist containing)

L24 ANSWER 15 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 2002:253088 HCAPLUS DOCUMENT NUMBER:

136:286596

TITLE:

Radiation sensitive resin composition

INVENTOR(S): Miyaji, Masaaki; Nagai, Tomoki; Yada, Yuji; Numata, Jun; Nishimura, Yukio; Yamamoto, Masafumi; Ishii, Hiroyuki; Kajita, Toru;

Shimokawa, Tsutomu

PATENT ASSIGNEE(S):

JSR Corporation, Japan Eur. Pat. Appl., 71 pp.

SOURCE:

CODEN: EPXXDW

DOCUMENT TYPE:

Patent

LANGUAGE:

English

FAMILY ACC. NUM. COUNT:

T: 1

PATENT INFORMATION:

| PATENT NO.                  | KIND       | DATE     | APPLICATION NO.       | DATE   |
|-----------------------------|------------|----------|-----------------------|--------|
|                             |            |          |                       |        |
| EP 1193558                  | A2         | 20020403 | EP 2001-122213        |        |
|                             |            |          |                       | 2001   |
| EP 1193558                  | <b>A</b> 3 | 20020814 |                       | 0917   |
|                             |            |          | GB, GR, IT, LI, LU, N | L, SE, |
| MC, PT, IE,                 |            |          |                       | _,,    |
| JP 2002202604               | A2         | 20020719 | JP 2000-401302        |        |
|                             |            |          |                       | 2000   |
| TD 2002162746               | 30         | 20020607 | TD 2001 20025         | 1228   |
| JP 2002162746               | AZ         | 20020607 | JP 2001-280035        | 2001   |
|                             |            |          |                       | 0914   |
| US 2002058201               | A1         | 20020516 | US 2001-953941        |        |
|                             |            |          |                       | 2001   |
|                             |            |          |                       | 0918   |
| US 6933094<br>US 2005214680 |            | 20050823 | US 2005-116269        |        |
| 05 2003214680               | ΑŢ         | 20050929 | 05 2005-116269        | 2005   |
|                             |            |          |                       | 0428   |
| PRIORITY APPLN. INFO.:      |            |          | JP 2000-282689        | A      |
|                             |            |          |                       | 2000   |
|                             |            |          |                       | 0918   |
|                             |            |          | JP 2000-401302        | A      |
|                             |            |          | BF 2000-401302        | 2000   |
|                             |            |          |                       | 1228   |
|                             |            |          |                       |        |
|                             |            |          | US 2001-953941        | A1     |
|                             |            |          |                       | 2001   |
|                             |            |          |                       | 0918   |

GI

AB A chemical amplified radiation sensitive resin composition comprises a specific copolymer and a photoacid generator, wherein the copolymer contains the recurring unit I and/or II and CH2CR1(C:O)NR3R4 (R1 = H, Me; R2 = C4-10 tertiary alkyl; R3,4 = H, C1-12 alkyl, C6-15 aromatic, C1-12 alkoxyl, or R3 and R4 may form, in combination and together with the nitrogen atom with which the R3 and R4 groups bond, a C3-14 cyclic structure, provided that R3 and

R4 are not a hydrogen atom at the same time). The composition effectively responds to various radiations, exhibits excellent resolution and pattern configuration and minimal iso-dense bias, and can form fine patterns at a high precision and in a stable manner. 193810-83-2

(acid diffusion control agent; radiation sensitive resin composition for **photoresist** containing)

RN 193810-83-2 HCAPLUS

IT

CN 1H-Benzimidazole-1-carboxylic acid, 2-phenyl-, 1,1-dimethylethyl ester (9CI) (CA INDEX NAME)

IC ICM G03F007-038

ICS G03F007-039; G03F007-004

CC 74-5 (Radiation Chemistry, Photochemistry, and **Photographic** and Other Reprographic Processes) Section cross-reference(s): 35, 38

ST chem amplified photoresist polymer

IT Photoresists

(chemical amplified; radiation sensitive resin composition for)

IT 102-60-3 102-71-6, Triethanolamine, uses 1008-89-5,
2-Phenylpyridine 1116-76-3, Tri-n-octylamine 193810-83-2
330576-56-2, N-t-Butoxycarbonyldicyclohexylamine 406198-67-2
(acid diffusion control agent; radiation sensitive resin composition for photoresist containing)

IT 66003-78-9, Triphenylsulfoniumtrifluoromethanesulfonate 84563-54-2, Bis(4-tert-butylphenyl)iodonium trifluoromethanesulfonate 133710-62-0 138529-81-4, Bis(cyclohexylsulfonyl)diazomethane 185195-30-6D, Bis(4-tert-butylphenyl)iodonium 10-camphorsulfonate, reaction product with Et vinyl ether 194999-85-4 205514-94-9, N-(10-Camphorsulfonyloxy)succinimide 406198-76-3 406198-77-4 (acid generator; radiation sensitive resin composition for photoresist containing)

IT 542-92-7, Cyclopentadiene, reactions 2680-03-7, N,N-Dimethylacrylamide

(preparation of radiation sensitive resin composition for photoresist)

IT 25171-46-4P

(preparation of radiation sensitive resin composition for photoresist)

IT 109-92-2DP, Ethyl vinyl ether, reaction product with
poly(hydroxystyrene) 928-55-2DP, Ethyl-1-propenyl ether,
reaction product with poly(hydroxystyrene) 2182-55-0DP,
Cyclohexyl vinyl ether, reaction product with poly(hydroxystyrene)
24979-70-2DP, Poly(p-hydroxystyrene), reaction product with Et
vinyl ether and Et propenyl ether 24979-70-2DP,
Poly(p-hydroxystyrene), reaction product with di-Bu carbonate
34619-03-9DP, Di-tert-butyl carbonate, reaction product with
poly(hydroxystyrene) 95418-60-3DP, Poly (p-tert-Butoxystyrene),
hydrolyzed, and/or reaction product with cyclohexyl vinyl ether

123589-22-0DP, p-tert-Butoxystyrene-p-hydroxystyrene copolymer, reaction product with Et vinyl ether 221524-18-1DP, reaction product with Et vinyl ether 221549-67-3DP, hydrolyzed 340964-44-5P 357167-14-7P 406198-55-8DP, hydrolyzed 406198-56-9DP, hydrolyzed 406198-57-0DP, hydrolyzed 406198-58-1DP, hydrolyzed 406198-60-5DP, hydrolyzed 406198-61-6DP, hydrolyzed 406198-62-7DP, hydrolyzed 406198-63-8DP, hydrolyzed 406198-64-9DP, hydrolyzed 406198-68-3P 406198-69-4P 406198-70-7P 406198-71-8P 406198-72-9P 406198-73-0P 406198-74-1P 406198-75-2P (resin; radiation sensitive resin composition for photoresist containing)

L24 ANSWER 16 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

2002:244559 HCAPLUS

DOCUMENT NUMBER:

136:286664

TITLE:

SOURCE:

Optical recording material containing azole

compound and recording method

INVENTOR (S):

Saito, Naoki

PATENT ASSIGNEE(S):

Fuji Photo Film Co., Ltd., Japan Jpn. Kokai Tokkyo Koho, 19 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

| PATENT NO.             | KIND | DATE     | APPLICATION NO. | DATE |
|------------------------|------|----------|-----------------|------|
|                        |      |          |                 |      |
|                        |      |          | •               |      |
| JP 2002096558          | A2   | 20020402 | JP 2000-285853  |      |
|                        |      |          |                 | 2000 |
| •                      |      |          |                 | 0920 |
| PRIORITY APPLN. INFO.: |      |          | JP 2000-285853  |      |
|                        |      |          |                 | 2000 |
|                        |      |          |                 | 0920 |

OTHER SOURCE(S): MARPAT 136:286664

The material comprises a support coated with a laser-recordable layer containing an azole compound A1L1mA2n [A1-2 = (substituted) azolyl; n = 1-5; L1 = (n + 1)-valent  $\pi$ -conjugated linkage; m = 0,1; when m = 0, n = 1; A1 and L1, A2 and L1, A1 and A2 may form a ring]. Information is recorded by irradiating laser with  $\leq 550$  nm on the material. The material is recorded and read by  $\leq 450$  nm laser beam and suited for high d. recording.

IT 405885-79-2

(optical recording material containing azole compound)

RN 405885-79-2 HCAPLUS

CN 1H-Benzimidazole, 2,2'-(1,4-phenylenedi-2,1-ethynediyl)bis[1-(2-ethoxyethyl)- (9CI) (CA INDEX NAME)

$$\begin{array}{c} \text{EtO-CH}_2\text{-CH}_2\\ \text{CH}_2\text{-CH}_2\text{-OEt}\\ \text{C} \end{array}$$

IC ICM B41M005-26

ICS G11B007-0045; G11B007-24; C09B023-00; C09B057-00

CC 74-12 (Radiation Chemistry, Photochemistry, and **Photographic** and Other Reprographic Processes)

IT 405885-67-8 405885-71-4 405885-75-8 405885-79-2

405885-83-8 405885-87-2 405885-91-8

(optical recording material containing azole compound)

L24 ANSWER 17 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

2001:918945 HCAPLUS

DOCUMENT NUMBER:

136:45683

TITLE:

Radiation-sensitive resin composition for

chemical amplified resist

INVENTOR(S):

Nishimura, Yukio; Yamahara, Noboru; Yamamoto, Masafumi; Kajita, Toru; Shimokawa, Tsutomu;

Ito, Hiroshi

PATENT ASSIGNEE(S):

JSR Corporation, Japan; International Business

Machines Corporation

SOURCE:

Eur. Pat. Appl., 63 pp.

CODEN: EPXXDW

DOCUMENT TYPE:

Patent

LANGUAGE:

English

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| PATENT NO.             | KIND      | DATE         | APPLICATION NO.      | DATE  |
|------------------------|-----------|--------------|----------------------|-------|
|                        |           |              |                      | -     |
| EP 1164434             | 7.2       | 20011219     | EP 2001-114503       |       |
| Pt 1104424             | AZ        | 20011219     | EF 2001-114505       | 2001  |
|                        |           |              |                      | 0615  |
| EP 1164434             | <b>A3</b> | 20041222     |                      |       |
|                        | •         |              | , GR, IT, LI, LU, NL | , SE, |
|                        | •         | , LV, FI, RO |                      |       |
| JP 2002072484          | A2        | 20020312     | JP 2001-108824       |       |
|                        |           |              |                      | 2001  |
| US 2002009668          | A1        | 20020124     | US 2001-879894       | 0406  |
| 05 2002009668          | AT        | 20020124     | 05 2001-8/9894       | 2001  |
|                        |           |              |                      | 0614  |
| US 6800414             | B2        | 20041005     |                      | -     |
| SG 100729              | A1        |              | SG 2001-3498         |       |
|                        |           |              |                      | 2001  |
|                        |           |              |                      | 0614  |
| CN 1332205             | Α         | 20020123     | CN 2001-124927       |       |
|                        |           |              |                      | 2001  |
|                        | _         |              |                      | 0615  |
| TW 536661              | В         | 20030611     | TW 2001-90114559     | 2001  |
|                        |           |              |                      | 0615  |
| US 2004241580          | A1        | 20041202     | US 2004-867892       | 0613  |
| 00 2004241300          | ***       | 20041202     | 05 2004 007032       | 2004  |
|                        |           |              |                      | 0616  |
| US 6964840             | B2        | 20051115     |                      |       |
| PRIORITY APPLN. INFO.: |           |              | JP 2000-182297       | A     |
|                        |           |              |                      | 2000  |
|                        |           |              |                      | 0616  |
|                        |           |              |                      |       |
|                        |           |              | JP 2001-108824       | A     |

2001 0406

US 2001-879894

2001

**A1** 

0614

OTHER SOURCE(S): MARPAT 136:45683

AB A radiation-sensitive resin composition comprising an acid-labile group-containing resin and a photoacid generator is disclosed. The resin has a structure of X1R2COR1 (R1 = H, monovalent acid-labile group, C1-6 alkyl which does not have an acid-labile group, C2-7 alkylcarbonyl which does not have an acid-labile group; X1 = C1-4 fluorinated alkyl; and R2 = H, C1-10 alkyl, C1-10 fluorinated alkyl). The resin composition exhibits high transmittance of radiation, high sensitivity, resolution, and pattern shape, and is useful as a chemical amplified **resist** in producing semiconductors at a high yield.

IT 193810-83-2, N-tert-Butoxycarbonyl-2-phenylbenzimidazole
 (acid diffusion control agent for radiation-sensitive
 resist composition)

RN 193810-83-2 HCAPLUS

CN 1H-Benzimidazole-1-carboxylic acid, 2-phenyl-, 1,1-dimethylethyl ester (9CI) (CA INDEX NAME)

IC ICM G03F007-004 ICS G03F007-039

CC 74-5 (Radiation Chemistry, Photochemistry, and **Photographic** and Other Reprographic Processes) Section cross-reference(s): 35, 38, 76

ST chem amplified radiation electron beam **photoresist** microfabrication

IT Photoresists

(acid-labile group-containing resin for radiation-sensitive resist composition)

IT Polyalkenamers

(acid-labile group-containing resin for radiation-sensitive resist composition)

IT Semiconductor device fabrication

(radiation-sensitive resist composition for)

IT 1116-76-3, Tri-n-octylamine 2052-49-5, Tetra-n-butylammoniumhydroxide 4847-93-2, 3-Piperidino-1,2-propanediol 193810-83-2, N-tert-Butoxycarbonyl-2-phenylbenzimidazole 330576-56-2, N-tert-Butoxycarbonyldicyclohexylamine (acid diffusion control agent for radiation-sensitive resist composition)

IT 144317-44-2, Triphenylsulfonium nonafluoro-n-butanesulfonate 194999-85-4 213740-80-8 307531-76-6 330576-58-4 380886-84-0

(acid generator for radiation-sensitive resist

```
composition)
                    370102-83-3P
                                   380886-62-4P
                                                  380886-63-5P
IT
     370099-14-2P
                                                  380886-70-4P
     380886-66-8P
                    380886-68-0P
                                   380886-69-1P
     380886-71-5P
                    380886-72-6DP, hydrogenated
                                                  380886-72-6P
                                   380886-74-8DP, hydrogenated
     380886-73-7DP, hydrogenated
     380886-74-8P
                    380886-75-9DP, hydrogenated
                                                  380886-76-0DP,
                                   380886-77-1DP, hydrogenated
     hydrogenated
                    380886-76-0P
                                                  380886-81-7P
     380886-78-2P
                    380886-79-3P
                                   380886-80-6P
     380886-82-8P
                    380886-83-9P
                                   380915-67-3P
        (acid-labile group-containing resin for radiation-sensitive
        resist composition)
IT
     157692-53-0, tert-Butyl deoxycholate 169228-97-1, Di-tert-butyl
                                   231296-44-9, t-
     1,3-adamantanedicarboxylate
     Butoxycarbonylmethyldeoxycholate 296242-01-8
        (alicyclic additive for radiation-sensitive resist
        composition)
     77-73-6, Dicyclopentadiene
IT
                                542-92-7, Cyclopentadiene, reactions
     646-97-9, 1,1-Bis(trifluoromethyl)-3-buten-1-ol
                                                       5292-43-3,
     tert-Butyl bromoacetate
        (preparation of acid-labile group-containing resin for
        radiation-sensitive resist composition)
IT
                    196314-63-3P 365533-00-2P
                                                  380886-59-9P
     196314-61-1P
     380886-60-2P
        (preparation of acid-labile group-containing resin for
        radiation-sensitive resist composition)
L24 ANSWER 18 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN
ACCESSION NUMBER:
                         2001:918944 HCAPLUS
DOCUMENT NUMBER:
                         136:45682
TITLE:
                         Radiation-sensitive resin composition
INVENTOR(S):
                         Kobayashi, Eiichi; Numata, Jun; Yamachika,
                         Mikio; Yamamoto, Masafumi
PATENT ASSIGNEE(S):
                         JSR Corporation, Japan
SOURCE:
                         Eur. Pat. Appl., 25 pp.
                         CODEN: EPXXDW
DOCUMENT TYPE:
                         Patent
LANGUAGE:
                         English
FAMILY ACC. NUM. COUNT:
PATENT INFORMATION:
     PATENT NO.
                         KIND
                                DATE
                                            APPLICATION NO.
                                                                   DATE
     EP 1164433
                         A1
                                20011219
                                            EP 2001-114245
                                                                   2001
                                                                   0612
            AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE,
             MC, PT, IE, SI, LT, LV, FI, RO
     JP 2002072477
                         A2
                                20020312
                                            JP 2000-177487
                                                                   2000
                                                                   0613
     US 2002012872
                         A1
                                20020131
                                            US 2001-878274
                                                                   2001
                                                                   0612
     US 6506537
                         B2
                                20030114
PRIORITY APPLN. INFO.:
                                            JP 2000-176171
                                                                   2000
```

JP 2000-177487

0612

Α

2000 0613

OTHER SOURCE(S): MARPAT 136:45682

A pos.-type radiation-sensitive resin composition is provided. The composition includes: (A) a low-mol. compound comprising a compound having at least one amino group having H bonded to N; at least one H in the amino group having been substituted with a t-butoxycarbonyl group; (B) a radiation-sensitive acid generator; and (C) a silicon-atom-containing resin comprising an alkali-insol. or alkali-slightly-soluble resin having been protected with an acid-cleavable group; the resin being capable of turning soluble in alkali upon cleavage of the acid-cleavable group. This radiation-sensitive resin composition is effectively responsive to radiations of various types, has superior sensitivity and resolution and also a superior long-term storage stability, and is useful as a pos.-type chemical amplified resist.

IT 193810-83-2, N-tert-Butoxycarbonyl-2-phenylbenzimidazole (acid diffusion control agent for radiation-sensitive resin composition)

RN 193810-83-2 HCAPLUS

1H-Benzimidazole-1-carboxylic acid, 2-phenyl-, 1,1-dimethylethyl CN ester (9CI) (CA INDEX NAME)

IC ICM G03F007-004 ICS G03F007-075

74-5 (Radiation Chemistry, Photochemistry, and CC Photographic and Other Reprographic Processes) Section cross-reference(s): 38, 76

ST radiation sensitive resin chem amplified resist

Photoresists TΤ

(radiation-sensitive resin composition for)

IT 151476-40-3, N-t-Butoxycarbonyl-1-adamantylamine 193810-83-2, N-tert-Butoxycarbonyl-2-phenylbenzimidazole 330576-56-2, N-t-Butoxycarbonyldicyclohexylamine 197144-31-3 353275-42-0

> (acid diffusion control agent for radiation-sensitive resin composition)

REFERENCE COUNT:

THERE ARE 4 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L24 ANSWER 19 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

2001:900258 HCAPLUS

DOCUMENT NUMBER:

136:29177

TITLE:

Radiation-sensitive resin composition for

chemical amplified pos. tone resist

INVENTOR (S):

Nishimura, Yukio; Douki, Katsuji; Kajita,

Toru; Shimokawa, Tsutomu

PATENT ASSIGNEE(S):

JSR Corporation, Japan

SOURCE:

Eur. Pat. Appl., 54 pp.

CODEN: EPXXDW

DOCUMENT TYPE:

Patent

LANGUAGE:

English

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| PATENT NO.                        | KIN | D DATE                     | APPLICATION NO.        | DATE              |
|-----------------------------------|-----|----------------------------|------------------------|-------------------|
| EP 1162506                        | A1  | 20011212                   | EP 2001-113944         |                   |
| 1102500                           | AI  | 20011212                   | EF 2001 113744         | 2001<br>0607      |
|                                   |     | DK, ES, FR,<br>LT, LV, FI, | GB, GR, IT, LI, LU, RO |                   |
| JP 2002062657                     | A2  | 20020228                   | JP 2001-95877          | 2001              |
|                                   |     |                            |                        | 2001<br>0329      |
| US 2002009667                     | A1  | 20020124                   | US 2001-874977         | 2001              |
|                                   |     |                            |                        | 0607              |
| US 6753124 PRIORITY APPLN. INFO.: | B2  | 20040622                   | JP 2000-173708         | A                 |
|                                   |     |                            |                        | 2000<br>0609      |
|                                   |     |                            | JP 2001-95877          | A<br>2001<br>0329 |

GI

Ι

- AB A radiation-sensitive resin composition used as a chemical amplified postone resist responsive to short wavelength active radiation such as KrF excimer laser and ArF excimer laser is disclosed. The resin composition comprises: (A) an acid-dissociable group-containing resin which is insol. or scarcely soluble in alkali and becomes alkali soluble when the acid-dissociable group dissocs., the resin comprising a lactone cyclic structure I (a = 1-3; b = 0-9; R1 = monovalent organic group); and (B) a photoacid generator. The composition has high transmittance of radiation, exhibits high sensitivity, resolution, and pattern shape, and can produce semiconductors at a high yield without producing resolution defects during microfabrication.

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RN 193810-83-2 HCAPLUS
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CN 1H-Benzimidazole-1-carboxylic acid, 2-phenyl-, 1,1-dimethylethyl ester (9CI) (CA INDEX NAME)

IC ICM G03F007-039

CC 74-5 (Radiation Chemistry, Photochemistry, and **Photographic** and Other Reprographic Processes) Section cross-reference(s): 35, 38, 76

ST chem amplified **photoresist** acid dissociable lactone cyclic

IT Positive photoresists

(radiation-sensitive resin composition for)

IT 1116-76-3, Tri-n-octylamine 3033-62-3, Bis(2-

dimethylaminoethyl)ether 193810-83-2,

N-tert-Butoxycarbonyl-2-phenylbenzimidazole 330576-56-2,

N-tert-Butoxycarbonyldicyclohexylamine

(acid diffusion control agent; radiation-sensitive resin composition for chemical amplified pos. tone **resist**)

IT 157692-53-0, tert-Butyl deoxycholate 169228-97-1, Di-tert-butyl 1,3-adamantanedicarboxylate 231296-44-9, t-Butoxycarbonylmethyl deoxycholate 296242-01-8, 2,5-Dimethyl-2,5-di(1-adamantylcarbonyloxy)hexane

(additives; radiation-sensitive resin composition for chemical amplified pos. tone **resist**)

IT 542-92-7, Cyclopentadiene, reactions 814-68-6, Acryloyl chloride 920-46-7, Methacryloyl chloride 34862-06-1, 4,5-Diacetoxypentanal 78984-88-0

(preparation of radiation-sensitive resin composition for chemical amplified pos. tone **resist**)

IT 10374-51-3P, 4-Hydroxymethyl- $\gamma$ -butyrolactone 156938-09-9P 259154-20-6P, 4,5-Diacetoxypentanoic acid 264193-11-5P

379257-66-6P 379257-68-8P 379257-69-9P 379257-70-2P

(preparation of radiation-sensitive resin composition for chemical amplified pos. tone **resist**)

IT 379257-71-3P 379257-72-4P 379257-73-5P 379257-75-7P

379257-76-8P 379257-77-9P 379257-78-0P 379257-79-1P

379257-81-5P 379257-82-6P 379257-83-7P

(radiation-sensitive resin composition for chemical amplified pos. tone resist)

IT 96-48-0,  $\gamma$ -Butyrolactone 108-94-1, Cyclohexanone, uses 110-43-0, 2-Heptanone 84540-57-8, Propylene glycol monomethyl

(solvent; radiation-sensitive resin composition for chemical amplified pos. tone resist)

REFERENCE COUNT:

ether acetate

THERE ARE 4 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L24 ANSWER 20 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN ACCESSION NUMBER: 2001:581559 HCAPLUS

DOCUMENT NUMBER:

135:160153

TITLE: INVENTOR(S): Radiation-sensitive resin composition Numata, Jun; Suzuki, Aki; Hara, Hiromichi; Natsume, Norihiro; Murata, Kiyoshi; Yamamoto,

Masafumi; Soyano, Akimasa; Kajita, Toru;

Shimokawa, Tsutomu

PATENT ASSIGNEE(S):

JSR Corp., Japan

SOURCE:

Eur. Pat. Appl., 77 pp.

CODEN: EPXXDW

DOCUMENT TYPE:

Patent

LANGUAGE:

English

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| PATENT NO.             | KIND | DATE     | APPLICATION NO.     | DATE         |
|------------------------|------|----------|---------------------|--------------|
|                        |      |          |                     |              |
| EP 1122605             | A2   | 20010808 | EP 2001-102326      |              |
|                        |      |          |                     | 2001<br>0201 |
| EP 1122605             | Α3   | 20010919 |                     | 0201         |
|                        |      |          | GB, GR, IT, LI, LU, | NL, SE,      |
| MC, PT, IE,            |      |          |                     | ,,           |
| JP 2001215689          |      |          |                     |              |
|                        |      |          |                     | 2000         |
|                        |      |          |                     | 0204         |
| JP 2002082438          | A2   | 20020322 | JP 2000-273962      |              |
|                        |      |          |                     | 2000<br>0908 |
| US 2001023050          | A1   | 20010920 | US 2001-774714      | 0908         |
| 05 2001025050          | N.   | 20010720 | 05 2001 //4/14      | 2001         |
|                        |      |          |                     | 0201         |
| US 6623907             | B2   | 20030923 |                     |              |
| SG 90230               | A1   | 20020723 | SG 2001-565         |              |
|                        |      |          |                     | 2001         |
|                        |      |          |                     | 0205         |
| PRIORITY APPLN. INFO.: |      |          | JP 2000-28456       | Α 2000       |
| ·                      |      |          |                     | 2000<br>0204 |
|                        |      |          |                     | 0204         |
|                        |      |          | JP 2000-273962      | Α            |
|                        |      |          |                     | 2000         |
|                        |      |          |                     | 0908         |
|                        |      |          |                     |              |

AB The invention relates to a pos. - or neg. -tone radiation sensitive resin composition suitable as a resist for ultra-microprocessing using UV, deep-UV, x-ray radiation and charged particle rays. A pos. tone radiation-sensitive resin composition containing (a) a low mol. weight compound having at least one amino group in which the nitrogen atom has at least one hydrogen atom bonded thereto and at least one of the hydrogen atoms is replaced by a tert-butoxycarbonyl group, (b) a photoacid generator and (c) a resin insol. or scarcely soluble in alkali which is protected by an acid-soluble group and becomes soluble in alkali when the acid-dissociating group dissocs. or an alkali-soluble resin and an alkali solubility control agent, is disclosed. Also disclosed is a neg.-tone radiation sensitive resin composition comprising a low mol. weight compound, a photoacid generator, and an alkali-soluble resin, and a compound capable of crosslinking with alkali-soluble resin in the presence of an acid. The composition is useful as a chemical amplified resist

which effectively responds to various radiations, exhibits superior sensitivity and resolution, forms fine patterns at a high precision and in a stable manner even if the patterns are isolated line patterns.

193810-83-2 TΤ

> (acid-diffusion control agent; pos.-tone radiation-sensitive resin composition containing acid-diffusion control agent of)

193810-83-2 HCAPLUS RN

1H-Benzimidazole-1-carboxylic acid, 2-phenyl-, 1,1-dimethylethyl CN ester (9CI) (CA INDEX NAME)

IC ICM G03F007-004

ICS G03F007-038; G03F007-039

CC 74-5 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

ST radiation resin neg pos tone resist

IT Resists

> (chemical amplified; pos.-tone radiation-sensitive resin composition containing alkali-soluble acid-dissociating group containing polymer)

IT Photoresists

> (pos.-tone radiation-sensitive resin composition containing alkali-soluble acid-dissociating group containing polymer)

151476-40-3 **193810-83-2** IT 59255-81-1 330576-56-2 353275-42-0

> (acid-diffusion control agent; pos.-tone radiation-sensitive resin composition containing acid-diffusion control agent of)

L24 ANSWER 21 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

2001:208019 HCAPLUS

DOCUMENT NUMBER:

INVENTOR (S):

134:245232

TITLE:

Radiation-sensitive resin composition as

chemically-amplified photoresist with superior dry etching resistance and resolution for deep UV lithography Douki, Katsuji; Murata, Kiyoshi; Ishii, Hiroyuki; Kajita, Toru; Shimokawa, Tsutomu

PATENT ASSIGNEE(S):

SOURCE:

JSR Corporation, Japan Eur. Pat. Appl., 52 pp.

CODEN: EPXXDW

DOCUMENT TYPE:

Patent English

LANGUAGE:

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| PATENT NO. | KIND | DATE     | APPLICATION NO. | DATE |
|------------|------|----------|-----------------|------|
| EP 1085379 | A1   | 20010321 | EP 2000-120000  | 2000 |

0914

| EP       | 1085 |      | BE.  | CH. | B1<br>DE. |    |      | 104<br>FR. | GB, G | R. I | Т.  | LT. | LU. | NL. | SE.          |
|----------|------|------|------|-----|-----------|----|------|------------|-------|------|-----|-----|-----|-----|--------------|
|          | 10.  |      |      |     |           |    |      |            | RO, C |      | -,  | ,   | _0, |     | ,            |
| JP       | 2001 | 1091 | 57   | ·   | A2        | 20 | 010  | 1420       | JP    | 199  | 9-2 | 912 | 91  |     |              |
|          |      |      |      |     |           |    |      |            |       |      |     |     |     |     | 1999         |
|          |      |      |      |     |           |    |      |            |       |      |     |     |     |     | 1013         |
| JP       | 2001 | 2091 | 81   |     | A2        | 20 | 0010 | 803        | JP    | 200  | 0-2 | 779 | 66  |     | 2000         |
|          |      |      |      |     |           |    |      |            |       |      |     |     |     |     | 2000<br>0913 |
| IIC      | 6482 | 560  |      |     | В1        | 20 | າດວາ | 1119       | 110   | 200  | 0-6 | 621 | 60  |     | 0913         |
| US       | 0402 | 500  |      |     | ы         | 20 | 7021 | LIIJ       | 03    | 200  | 0-0 | 021 | 00  |     | 2000         |
|          |      |      |      |     |           |    |      |            |       |      |     |     |     |     | 0914         |
| PRIORITY | APP  | LN.  | INFO | . : |           |    |      |            | JP    | 199  | 9-2 | 641 | 10  | 7   | A            |
|          |      |      |      |     |           |    |      |            |       |      |     |     |     |     | 1999         |
|          |      |      |      |     |           |    |      |            |       |      |     |     |     |     | 0917         |
|          |      |      |      |     |           |    |      |            |       |      |     |     |     |     |              |
|          |      |      |      |     |           |    |      |            | JP    | 199  | 9-2 | 912 | 91  | 1   | 4            |
|          |      |      |      |     |           |    |      |            |       |      |     |     |     |     | 1999<br>1013 |
|          |      |      |      |     |           |    |      |            |       |      |     |     |     |     | 1013         |
|          |      |      |      |     |           |    |      |            | ďΣ    | 199  | 9-3 | 252 | 22  | 7   | A            |
|          |      |      |      |     |           |    |      |            | 0.1   |      |     |     |     | -   | 1999         |
|          |      |      |      |     | •         | •  | •    |            |       |      |     |     |     |     | 1116         |

GI

A radiation-sensitive resin composition comprises (a) a resin containing an AB acid-dissociable group which is insol. or scarcely soluble in alkali and becomes alkali soluble when the acid-dissociable group dissocs., comprising the following recurring unit I, recurring unit II, and at least one of the recurring units III and IV (A, B = H, C1-4-alkyl; X, Y = H, monovalent O or N containing polar group, X joining together with Y may form dicarboxylic anhydride group; n = 0-2; R1 = H, CH3; R2 = CR33; R3 = monovalent alicyclic hydrocarbon group having 4-20 carbon atoms, its derivative, C1-4-alkyl; R4 = divalent hydrocarbon group having alicyclic skeleton containing 3-15 carbons), (b) a photoacid generator, (c) an acid diffusion controller, and (d) alicyclic additive. The radiation-sensitive resin composition is suitable for use as a chemical-amplified resist showing sensitivity to active radiation such as deep UV rays represented by a KrF excimer laser or ArF excimer laser, exhibiting superior dry etching resistance without being affected by types of etching gas, having high radiation transmittance, exhibiting excellent basic characteristics as a resist such as sensitivity, resolution, and pattern shape, possessing excellent storage stability as a composition, and exhibiting sufficient adhesion to substrates. IT 193810-83-2

(acid diffusion controller; copolymer compns. as chemical-amplified **photoresist** with superior dry etching **resistance**, sensitivity and resolution properties for deep UV lithog.)

RN 193810-83-2 HCAPLUS

CN 1H-Benzimidazole-1-carboxylic acid, 2-phenyl-, 1,1-dimethylethyl

<sup>\*</sup> STRUCTURE DIAGRAM TOO LARGE FOR DISPLAY - AVAILABLE VIA OFFLINE PRINT

## ester (9CI) (CA INDEX NAME)

IC ICM G03F007-039

CC 74-5 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes) Section cross-reference(s): 38

ST chem amplified **photoresist** polymer prepn compn deep UV lithog; dry etching **resistance** sensitivity resoln chem amplified **photoresist** polymer

IT Photoresists

(UV; copolymer compns. as chemical-amplified **photoresist** with superior dry etching **resistance**, sensitivity and resolution properties for deep UV lithog.)

IT 103-76-4, 1-(2-Hydroxyethyl)piperazine 611-36-9,
4-Hydroxyquinoline 1116-76-3, Tri-n-octylamine 3033-62-3,
Bis(2-dimethylaminoethyl)ether 7560-83-0,
Methyldicyclohexylamine 193810-83-2 330576-56-2
 (acid diffusion controller; copolymer compns. as
 chemical-amplified photoresist with superior dry etching
 resistance, sensitivity and resolution properties for deep
UV lithog.)

330576-37-9P 330576-38-0P 330576-39-1P 330576-41-5P IT 330576-42-6P 330576-43-7P 330576-44-8P 330576-46-0P 330576-47-1P 330576-48-2P 330576-49-3P 330576-51-7P 330576-52-8P 330576-54-0P 330576-55-1P

(copolymer compns. as chemical-amplified **photoresist** with superior dry etching **resistance**, sensitivity and resolution properties for deep UV lithog.)

IT 498-66-8D, Bicyclo[2.2.1]hept-2-ene, imide derivs. 66003-78-9 Triphenylsulfonium trifluoromethanesulfonate 144317-44-2, Triphenylsulfonium nonafluoro-n-butanesulfonate 194999-85-4 209482-18-8 330576-58-4

(photoacid generator; copolymer compns. as chemical-amplified photoresist with superior dry etching resistance, sensitivity and resolution properties for deep UV lithog.)

IT 157692-53-0, tert-Butyl deoxycholate 169228-97-1 231296-44-9, t-Butoxycarbonylmethyl deoxycholate

(resist additive; copolymer compns. as chemical-amplified photoresist with superior dry etching resistance, sensitivity and resolution properties for deep UV lithog.)

REFERENCE COUNT: 5 THERE ARE 5 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L24 ANSWER 22 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 2001:208013 HCAPLUS

DOCUMENT NUMBER: 134:229662

TITLE: Photographic material containing a novel

hydrazide type

INVENTOR(S): Loccufier, Johan; Lingier, Stefaan; Meeus,

Pascal

PATENT ASSIGNEE(S):

SOURCE:

Agfa-Gevaert N.V., Belg. Eur. Pat. Appl., 23 pp.

CODEN: EPXXDW

DOCUMENT TYPE: LANGUAGE: Patent English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

| EP 1085371 A1 20010321 EP 1999-203011   |              |
|---|--------------|
|   | 1999<br>0915 |
| EP 1085371 B1 20030806  |              |
| R: AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE<br>MC, PT, IE, SI, LT, LV, FI, RO | ,            |
| US 6361920 / B1 20020326 US 2000-661245   |              |
|   | 2000         |
|   | 0913         |
| JP 2001109094 A2 20010420 JP 2000-279567  |              |
|   | 2000         |
|   | 0914         |
| PRIORITY APPLN. INFO.: EP 1999-203011 A   |              |
|   | 1999         |
|   | 915          |
| US 1999-155333P P   |              |
|   | 1999         |
|   | 922          |

OTHER SOURCE(S):

MARPAT 134:229662

GI

The invention relates to a high contrast photog. materials with improved properties and to a novel class of nucleating agents contained in them. The material contains a hydrazide represented by (I), where L1 = divalent linking chain, Q1 = cationic heterocyclic ring containing N, L2 = divalent linking group, A1 and A2 = H or a group yielding H, and Y = anion. The material is preferably a graphic arts material for pre-press applications. High gradation and excellent dot quality, exposure latitude and stability on continuous processing are obtained.

IT 19809-30-4

(synthesis of oxalyl-amide hydrazide for photog. material

containing novel hydrazide using)

RN 19809-30-4 HCAPLUS

CN 1H-Benzimidazole-1-acetic acid, methyl ester (9CI) (CA INDEX NAME)

IC ICM G03C001-06

ICS C07D213-42; C07D215-12; C07D401-12; C07F009-58; C07F009-60; C07F009-62

CC 74-2 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

IT 552-89-6, 2-Nitrobenzaldehyde 3731-53-1, 4-Aminomethylpyridine 19809-30-4 25023-22-7

(synthesis of oxalyl-amide hydrazide for photog. material containing novel hydrazide using)

REFERENCE COUNT:

THERE ARE 4 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L24 ANSWER 23 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

1999:655531 HCAPLUS

DOCUMENT NUMBER:

132:4060

TITLE:

SOURCE:

Synthesis of a hydrophobic benzimidotricarbocyanine dye

AUTHOR (S):

Kharitonova, O. V.; Abramov, A. A.;

Zhidkoblinova, I. N.

CORPORATE SOURCE:

Mosk. Gos. Akad. Tonkoi Khimicheskoi

Tekhnologii im. Lomonosova, Moscow, Russia Zhurnal Nauchnoi i Prikladnoi Fotografii

(1999), 44(4), 38-43

CODEN: ZNPFEK; ISSN: 0869-6144

PUBLISHER:

Nauka Journal

DOCUMENT TYPE: LANGUAGE:

Russian

AB Condensation of 3-carboxyethyl-2-methyl-1-octyl-5,6-dichlorobenzimidazolium bromide with [5-(N-methyl-N-phenylamino)-3-octyl-2,4-pentadienylidene]-N-methyl-N-phenylammonium chloride yielded 3,3'-carboxyethyl-1,1',11-trioctyl-5,5',6,6'-tetrachlorobenzimidotricarbocyanine sodium salt. A pentamethine salt was synthesized reacting 1,1,5,5-tetraethoxy-3-octyl-3-pentanol with N-methylaniline hydrochloride in alc. under short-term boiling.

IT 251094-98-1P

(synthesis of a hydrophobic benzimidotricarbocyanine dye)

RN 251094-98-1 HCAPLUS

CN 1H-Benzimidazole-1-propanenitrile, 5,6-dichloro-2-methyl- (9CI) (CA INDEX NAME)

$$C1$$
 $N$ 
 $N$ 
 $CH_2-CH_2-CN$ 

CC 41-3 (Dyes, Organic Pigments, Fluorescent Brighteners, and **Photographic** Sensitizers)

IT 171193-68-3P **251094-98-1P** 251094-99-2P 251095-00-8P 251095-01-9P

(synthesis of a hydrophobic benzimidotricarbocyanine dye)

L24 ANSWER 24 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

1998:405517 HCAPLUS

DOCUMENT NUMBER:

129:128903

TITLE:

Heat-developable photographic recording

material for plate making

INVENTOR(S):

Yamada, Kozaburo; Kubo, Toshiaki; Suzuki,

Hiroyuki

PATENT ASSIGNEE(S):

SOURCE:

Fuji Photo Film Co., Ltd., Japan Jpn. Kokai Tokkyo Koho, 71 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

LANGUAGE:

Patent Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

| PATENT NO.             | KIND | DATE     | APPLICATION NO.  | DATE         |
|------------------------|------|----------|------------------|--------------|
| JP 10161270            | A2   | 19980619 | JP 1997-240511   |              |
| PRIORITY APPLN. INFO.: |      |          | JP 1996-279957 A | 1997<br>0821 |
| PRIORITI APPLN. INFO.: |      |          | 0: 1000 219931 R | 1996<br>1001 |

GI

AB In the title recording material having ≥1 image-forming layer, a specified hydrazine derivative and a compound I and/or II (R1-3 = H, monovalent substitute; EDW = electron attracting group; R4 =

monovalent substitute) are incorporated. The invention recording material can be developed in dry process and is useful for photog. plate making.

IT 210360-51-3

(combined with specified hydrazine derivative for heat-developable photog. material)

RN 210360-51-3 HCAPLUS

CN 2-Propenoic acid, 3-(1H-benzimidazol-1-yl)-2-cyano-, methyl ester (9CI) (CA INDEX NAME)

IC ICM G03C001-498

ICS G03C001-498

CC 74-2 (Radiation Chemistry, Photochemistry, and **Photographic** and Other Reprographic Processes)

IT 94-05-3 4432-64-8 5515-12-8 15166-81-1 61310-53-0 62701-44-4 68776-58-9, 4-Isoxazolecarbonitrile 76196-81-1

189154-57-2 189154-59-4 191489-55-1 210360-47-7

210360-48-8 210360-49-9 210360-50-2 **210360-51-3** 

210360-52-4 210363-29-4

(combined with specified hydrazine derivative for heat-developable photog. material)

L24 ANSWER 25 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

1998:112700 HCAPLUS

DOCUMENT NUMBER:

128:210864

TITLE:

Coumarin compound as photosensitizer and its

use in visible ray-curable ink or

resist

INVENTOR(S):

Suzuki, Rihoko; Otsuji, Akio; Urakami,

Tatsunobu; Takuma, Keisuke

PATENT ASSIGNEE(S):

Mitsui Toatsu Chemicals, Inc., Japan

SOURCE:

Jpn. Kokai Tokkyo Koho, 14 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

Japanese

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| PATENT NO.             | KIND       | DATE     | APPLICATION NO. | DATE         |
|------------------------|------------|----------|-----------------|--------------|
| JP 10045741            | <b>A</b> 2 | 19980217 | JP 1996-209756  | 1006         |
| PRIORITY APPLN. INFO.: |            |          | JP 1996-209756  | 1996<br>0808 |
|                        |            |          |                 | 1996<br>0808 |

OTHER SOURCE(S):

MARPAT 128:210864

GI

$$R^3$$
 $CH = Z$ 

$$= N$$

$$= CH$$

$$= CH$$

$$Y$$
III

AB The coumarins are represented as I [R1, R2 = H, alkyl, aryl, alkenyl, aralkyl, alkoxyalkyl, aryloxyalkyl, alkenyloxyalkyl, hydroxyalkyl, Q1[O(CH2)p]q; Q1 = H, alkyl, hydroxyalkyl, hydroxyalkoxyalkyl, alkoxyalkyl, cycloalkyl; p, q = 1-5; R1 and R2 may form ring optionally together with amino-substituted benzene ring; R3 = H, halogen, alkyl, alkoxyalkyl, hydroxyalkyl, halogenoalkyl, OH, alkoxy, aryloxy, alkoxyalkoxy, alklthio, arylthio, sulfonate salt group; Z = heterocycle group II, pyrone-type group III; X = O, S, NH, NR4; R4 = alkyl, aryl, aralkyl, alkoxyalkyl, aryloxyalkyl, alkenyloxyalkyl, Q1[O(CH2)p]q; II may be substituted; Y = O, :C(CN)2]. A photosensitizer containing I, a visible ray-sensitive resin composition containing I, visible ray-sensitive ink containing I and a solvent, and visible ray-sensitive material having the resin composition on a substrate, i.e., photoresist, are also claimed.

IT 203855-16-7 203855-23-6

(coumarin derivs. as photosensitizers for visible ray-sensitive inks or resists)

RN 203855-16-7 HCAPLUS

CN 2H-1-Benzopyran-2-one, 3-[[[1-(methoxymethyl)-1H-benzimidazol-2-yl]imino]methyl]-7-(methylphenylamino)- (9CI) (CA INDEX NAME)

RN 203855-23-6 HCAPLUS

CN 2H-1-Benzopyran-2-one, 3-[[[1-(2-methoxyethyl)-1H-benzimidazol-2-yl]imino]methyl]-7-(1-piperidinyl)- (9CI) (CA INDEX NAME)

IC ICM C07D311-16

ICS C07D405-12; C07D407-06; C07D413-12; C07D417-12; C07D491-06; C08F002-50; C08K005-18; C08L101-00; C09D011-00

CC 74-5 (Radiation Chemistry, Photochemistry, and **Photographic** and Other Reprographic Processes) Section cross-reference(s): 27

ST coumarin compd visible ray sensitizer; ink visible ray sensitive photosensitizer; **photoresist** visible ray sensitive photosensitizer

IT Photoresists

(coumarin derivs. as photosensitizers for visible ray-sensitive inks or resists)

IT Inks

(photocurable; coumarin derivs. as photosensitizers for visible ray-sensitive inks or **resists**)

IT 203855-12-3P 203855-13-4P

(coumarin derivs. as photosensitizers for visible ray-sensitive inks or resists)

IT 15625-89-5, Trimethylolpropane triacrylate 203855-14-5 203855-15-6 **203855-16-7** 203855-17-8 203855-18-9 203855-19-0 203855-20-3 203855-21-4 203855-22-5 203855-23-6 203855-24-7 203855-25-8 203855-26-9 203855-27-0 203855-28-1 203855-29-2 203855-30-5 203855-32-7 203855-33-8 203855-34-9 203855-31-6 203855-35-0 203855-37-2, Benzyl methacrylate-4-hydroxyphenyl methacrylate-methacrylic acid-methyl methacrylate copolymer

203856-95-5 (coumarin derivs. as photosensitizers for visible ray-sensitive inks or **resists**)

L24 ANSWER 26 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

1998:59384 HCAPLUS

DOCUMENT NUMBER:

128:161009

TITLE:

Visible ray-sensitive resin compositions, inks, photosensitive materials, coumarin compounds, and photosensitizers thereof Suzuki, Rioko; Otsuji, Atsuo; Uragami,

INVENTOR(S):

Tatsunobu; Takuma, Keisuke

PATENT ASSIGNEE(S):

Mitsui Toatsu Chemicals, Inc., Japan

SOURCE:

Jpn. Kokai Tokkyo Koho, 17 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

Japanese

FAMILY ACC. NUM. COUNT:

1

PATENT INFORMATION:

| PATENT NO.             | KIND | DATE     | APPLICATION NO.  | DATE |
|------------------------|------|----------|------------------|------|
|                        |      |          |                  |      |
| JP 10017604            | A2   | 19980120 | JP 1996-172610   |      |
|                        |      |          |                  | 1996 |
|                        |      |          |                  | 0702 |
| JP 3739136             | B2   | 20060125 |                  |      |
| JP 2005320338          | A2   | 20051117 | JP 2005-148984   |      |
|                        |      |          |                  | 2005 |
|                        |      |          |                  | 0523 |
| PRIORITY APPLN. INFO.: |      |          | JP 1996-172610 A | 3    |
|                        |      |          |                  | 1996 |
|                        |      |          |                  | 0702 |

OTHER SOURCE(S):

MARPAT 128:161009

GI

AB The visible ray-sensitive resin compns. contain (A) crosslinkable or polymerizable compds. with ethylenically unsatd. double bonds and (B) photopolymn. initiator compds. containing titanocenes and coumarines I [R1, R2 = H, (substituted) alkyl, aryl, alkenyl, aralkyl, Q1[O(CH2)p]q; Q1 = H, (substituted) alkyl; p, q = 1-5; R1, R2 may be bonded together or bonded with the amino-substituted benzene ring to form a ring; R3 = H, halo, (substituted) alkyl, OH, alkoxy, aryloxy, alkoxyalkoxy, alkylthio, arylthio, SO3H; X = O, S, NH, NR4; R4 = (substituted) alkyl, aryl, aralkyl, Q2[O(CH2)m]n; Q2 = H, (substituted) alkyl; m, n = 1-5; ring-A maybe substituted]. The inks contain the visible ray-sensitive resin compns. and solvents. The materials have the visible ray-sensitive resin compns. on substrates. The coumarin compds. and photosensitizers containing the coumarin compds. are also claimed. The compns. have excellent sensitivity to visible rays, especially Ar laser and YAG laser.

IT 202740-01-0 202740-04-3 202740-14-5 202740-18-9

(photosensitizer; **photoresists** containing coumarins and titanocenes and their inks and photosensitive materials)

RN 202740-01-0 HCAPLUS

CN 1H-Benzimidazole-2-acetonitrile, 1-[2-(2-hydroxyethoxy)ethyl]- $\alpha$ -[[7-[[2-(2-hydroxyethoxy)ethyl]-2-propenylamino]-2-oxo-2H-1-benzopyran-3-yl]methylene]-5,6-dimethoxy- (9CI) (CA INDEX NAME)

RN 202740-04-3 HCAPLUS

CN 1H-Benzimidazole-2-acetonitrile, α-[[8-bromo-7-(diethylamino)-2-oxo-2H-1-benzopyran-3-yl]methylene]-1-(2-propoxyethyl)- (9CI) (CA INDEX NAME)

RN 202740-14-5 HCAPLUS

CN 1H-Benzimidazole-2-acetonitrile,  $\alpha$ -[[7-(diethylamino)-8-(methylthio)-2-oxo-2H-1-benzopyran-3-yl]methylene]-5,6-dimethoxy-1-(2-methoxyethyl)- (9CI) (CA INDEX NAME)

RN 202740-18-9 HCAPLUS

CN 1H-Benzimidazole-2-acetonitrile, 1-[2-(2-methoxyethoxy)ethyl]- $\alpha$ -[[2-oxo-7-(1-piperidinyl)-2H-1-benzopyran-3-yl]methylene]-(9CI) (CA INDEX NAME)

$$\begin{array}{c|c} CN \\ C \\ \hline \\ CH_2 - CH_2 - O - CH_2 - CH_2 - OMe \end{array}$$

IT 202739-79-5P

(photosensitizer; **photoresists** containing coumarins and titanocenes and their inks and photosensitive materials)

RN 202739-79-5 HCAPLUS

CN 1H-Benzimidazole-2-acetonitrile,  $\alpha$ -[[7-(diethylamino)-2-oxo-2H-1-benzopyran-3-yl]methylene]-1-[2-(2-methoxyethoxy)ethyl]-(9CI) (CA INDEX NAME)

$$CH_2-CH_2-O-CH_2-CH_2-OMe$$

IC ICM C08F002-50

ICS G03F007-027; G03F007-029; G03F007-031; C07D405-06; C07D413-06; C07D417-06; C07D491-052; C07D498-16

CC 74-5 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

ST visible ray sensitive resist coumarin photosensitizer; titanocene coumarin photosensitizer photopolymn initiator resist; photoresist titanocene coumarin photosensitizer photopolymn initiator

IT Photosensitizers (pharmaceutical)

(coumarins; **photoresists** containing coumarins and titanocenes and their inks and photosensitive materials) Polymerization catalysts

(photopolymn.; **photoresists** containing coumarins and titanocenes and their inks and photosensitive materials)

IT Photoresists

IT

(photoresists containing coumarins and titanocenes and their inks and photosensitive materials)

IT 125051-32-3

(photopolymn. initiator; **photoresists** containing coumarins and titanocenes and their inks and photosensitive materials)

IT 168027-11-0P 200293-15-8P 202740-24-7P 202740-25-8P 202740-26-9P

(photoresists containing coumarins and titanocenes and their inks and photosensitive materials)

IT 178253-67-3

(photoresists containing commarins and titanocenes and their inks and photosensitive materials)

IT 105-53-3, Diethyl malonate 50586-80-6 56278-50-3, 2-Benzothiazoleacetonitrile 57597-64-5, 3-Formyl-7-diethylaminocoumarin 136803-42-4

```
(photoresists containing coumarins and titanocenes and
        their inks and photosensitive materials)
     15625-89-5, Trimethylolpropane triacrylate
IT
        (photoresists containing coumarins and titanocenes and
        their inks and photosensitive materials)
IT
     202739-81-9
                   202739-82-0
                               202739-83-1
                                               202739-84-2
     202739-85-3
                   202739-86-4
                                 202739-87-5
                                               202739-88-6
     202739-89-7
                   202739-90-0
                                 202739-91-1
                                               202739-92-2
     202739-93-3
                   202739-94-4
                                 202739-95-5
                                               202739-96-6
                   202739-98-8
                                 202739-99-9
                                               202740-00-9
     202739-97-7
                   202740-02-1
     202740-01-0
                                 202740-03-2
     202740-04-3
                   202740-05-4
                                 202740-06-5
                                               202740-07-6
     202740-08-7
                   202740-09-8
                                 202740-10-1
                                               202740-11-2
                   202740-13-4 202740-14-5
     202740-12-3
                                             202740-15-6
                   202740-17-8 202740-18-9
                                             202740-19-0
     202740-16-7
     202740-20-3
                   202740-21-4 202740-22-5
                                               202740-23-6
        (photosensitizer; photoresists containing coumarins and
        titanocenes and their inks and photosensitive materials)
IT
     202739-79-5P
                    202739-80-8P
        (photosensitizer; photoresists containing coumarins and
        titanocenes and their inks and photosensitive materials)
L24 ANSWER 27 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN
ACCESSION NUMBER:
                         1997:732348 HCAPLUS
DOCUMENT NUMBER:
                         128:68505
TITLE:
                         Coumarin compound, photosensitizers containing
                         and visible light-sensitive resin
                         compositions, containing them, and their uses
INVENTOR(S):
                         Suzuki, Rihoko; Otsuji, Atsuo; Uragami,
                         Tatsunobu; Takuma, Hirosuke
PATENT ASSIGNEE(S):
                         Mitsui Toatsu Chemicals, Inc., Japan
                         Jpn. Kokai Tokkyo Koho, 14 pp.
SOURCE:
                         CODEN: JKXXAF
DOCUMENT TYPE:
                         Patent
LANGUAGE:
                         Japanese
FAMILY ACC. NUM. COUNT:
PATENT INFORMATION:
     DATENT NO
                         MINIO
                                שתעע
                                            ADDITION NO
                                                                   רא ידיבי
```

| 996 |
|-----|
| 425 |
|     |
| 996 |
| 425 |
| 9:  |

GI

$$R^3$$
 $R^1$ 
 $R^2$ 
 $R^3$ 
 $R^2$ 
 $R^3$ 
 $R^3$ 

AB The coumarin compds. are represented by a structure I [R1-2 = (un) substituted alkyl; Q1[O(CH2)m]n; Q1 = H, (un) substituted alkyl, cycloalkyl; m, n = 1-5; NR1R2 may be a ring; R3 = H, halo, (un) substituted alkyl, halo, alkoxy, aryloxy, alkoxyalkoxy, alkylthio, arylthio, SO2H; X = O, S, NH, NR4; ring A may be substituted; R4 = (un) substituted alkyl, polyether, hydroxypolyether]. Also claimed are photosensitizers containing I, visible light-sensitive compns. containing the photosensitizers, inks for visible light-sensitive materials containing the compns. and solvents, and visible light-sensitive materials comprising a substrate and the compns. I have good solubility in solvents, thus providing a smooth uniform coating process film on a substrate, and are useful for resists sensitive to Ar laser radiation and YAG laser radiation and for electrodeposition coating process.

IT 200293-35-2DP, N-alkyl amino derivs. 200293-40-9P (prepared as photosensitizers for visible light-sensitive resists)

Ι

RN 200293-35-2 HCAPLUS

CN 2H-1-Benzopyran-4-carbonitrile, 3-[1-[2-(2-ethoxyethoxy)ethyl]-1H-benzimidazol-2-yl]-7-[[(ethoxymethoxy)methyl]amino]-2-oxo- (9CI) (CA INDEX NAME)

RN 200293-40-9 HCAPLUS

CN 2H-1-Benzopyran-4-carbonitrile, 3-[1-(2-methoxyethyl)-1H-benzimidazol-2-yl]-7-(4-morpholinyl)-2-oxo-(9CI) (CA INDEX NAME)

```
IC
     ICM C07D405-04
     ICS C07D413-04; C07D417-04; C09D007-12; C09D011-02; C09K003-00;
          G03F007-031; C07D405-04; C07D235-12; C07D311-16; C07D263-56;
          C07D277-66
CC
     74-5 (Radiation Chemistry, Photochemistry, and
     Photographic and Other Reprographic Processes)
ST
     coumarin deriv prepn resist photosensitizer; visible
     light resist coumarin deriv prepn; aminocoumarin deriv
     prepn visible light resist
     Photoresists
IT
        (containing aminocoumarin derivative as photosensitizer)
     Photosensitizers (pharmaceutical)
IT
        (containing aminocoumarin derivs. for visible light-sensitive
        resist)
ΙT
     Electrodeposition
        (using photoresist containing aminocoumarin derivative as
        photosensitizer)
ΙT
                    200293-20-5P
                                   200293-21-6P
                                                  200293-22-7P
     200293-18-1P
     200293-23-8P
                    200293-24-9P
                                   200293-25-0P
                                                  200293-26-1P
                    200293-28-3P
     200293-27-2P
                                   200293-29-4P
                                                  200293-30-7P
                    200293-32-9P
                                   200293-33-0P
     200293-31-8P
                                                  200293-34-1P
     200293-35-2DP, N-alkyl amino derivs. 200293-36-3P
     200293-37-4P 200293-38-5P 200293-39-6P 200293-40-9P
        (prepared as photosensitizers for visible light-sensitive
        resists)
     200293-15-8P
IT
                    200293-16-9P
                                   200293-17-0P
        (prepared for preparation of aminocoumarin derivs. as photosensitizers
        for visible light-sensitive resists)
IT
     56278-50-3, 2-Benzothiazolylacetonitrile
                                                136803-42-4
     200293-19-2
        (preparation of aminocoumarin derivs. as photosensitizers for
        visible light-sensitive resists)
L24 ANSWER 28 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN
ACCESSION NUMBER:
                         1997:380149 HCAPLUS
DOCUMENT NUMBER:
                         127:89735
                         Synthesis and photoinduced electron transfer
TITLE:
                         processes in Ru(II)(bpy)2/Os(III)(bpy)2-based
                         triad complexes containing functionalized
                         diimide ligands
                         Hossain, Md. Delower; Haga, Masa-aki;
AUTHOR (S):
                         Monjushiro, Hideaki; Gholamkhass, Bobak;
                         Nozaki, Koichi; Ohno, Takeshi
CORPORATE SOURCE:
                         Coordination Chemistry Laboratory, Inst.
                         Molecular Science, Okazaki, 444, Japan
SOURCE:
                         Chemistry Letters (1997), (6), 573-574
                         CODEN: CMLTAG; ISSN: 0366-7022
                        Chemical Society of Japan
PUBLISHER:
```

Journal English

DOCUMENT TYPE:

LANGUAGE:

GT

$$R-N$$
 $N-R$ 

Ι

[(Bpy)  $2Ru(\mu-L)M(bpy)$ 2]2+ (III) (L = I and II (R = AB 3-(2-(2-pyridyl)benzimidazol-1-yl)propyl); M = Os(II), Ru(II)) were prepared and characterized by cyclic voltammetry. The charge separated (CS) state was efficiently formed as a result of stepwise electron transfer reactions in III (M = Os) triad system (efficiency >0.7). The rate of electron transfer and the charge separation yield were determined from picosecond time-resolved absorption spectra.

ΙT 34707-83-0P

(for preparation of osmium-ruthenium and ruthenium-ruthenium pyridylbenzimidazolyldiimide dinuclear complexes)

RN 34707-83-0 HCAPLUS

CN 1H-Benzimidazole-1-propanenitrile, 2-(2-pyridinyl)- (9CI) INDEX NAME)

CC 78-7 (Inorganic Chemicals and Reactions)

Section cross-reference(s): 72, 74

IT 14668-82-7P, Vinyl isocyanide 34707-83-0P 191788-79-1P

(for preparation of osmium-ruthenium and ruthenium-ruthenium

pyridylbenzimidazolyldiimide dinuclear complexes) REFERENCE COUNT:

THERE ARE 17 CITED REFERENCES AVAILABLE

FOR THIS RECORD. ALL CITATIONS AVAILABLE

IN THE RE FORMAT

L24 ANSWER 29 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

17

ACCESSION NUMBER: 1996:50832 HCAPLUS

DOCUMENT NUMBER: 124:148723

TITLE: Phthlocyanine compounds for optical materials

and electric materials

INVENTOR (S): Yashiro, Tooru; Taniguchi, Masatoshi;

Narizuka, Toshiro

PATENT ASSIGNEE(S):

Ricoh Kk, Japan

SOURCE:

Jpn. Kokai Tokkyo Koho, 5 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

FAMILY ACC. NUM. COUNT:

Japanese

PATENT INFORMATION:

| PATENT NO.             | KIND | DATE     | APPLICATION NO. | DATE |
|------------------------|------|----------|-----------------|------|
|                        |      |          |                 |      |
| TD 05005105            |      | 10051001 |                 |      |
| JP 07286107            | A2   | 19951031 | JP 1994-104497  |      |
|                        |      |          |                 | 1994 |
|                        |      |          |                 | 0420 |
| PRIORITY APPLN. INFO.: |      |          | JP 1994-104497  |      |
|                        |      |          |                 | 1994 |
|                        |      |          |                 | 0420 |

OTHER SOURCE(S):

MARPAT 124:148723

GI

AB The compds. I (M = 2H, divalent metal, metal oxide, metal chloride; X = heterocyclyl containing ≥2 N or ≥1 N and  $\geq 1$  S on the ring; substitution positions of X = 2 or 3, 6 or 7, 10 or 11, and 14 or 15 or 1 or 4, 5 or 8, 9 or 12, and 13 or 16 positions on the phthalocyanine ring) are claimed. I show high solubility in various organic solvents at room temperature and are useful as dyes for optical recording and color filters, and for photoelec. conversion devices, electrophotog. photoreceptors, organic semiconductor devices, catalysts, gas sensors, etc. A mixture of benzimidazole, 4-nitrophthalonitrile, K2CO3, and DMSO was heated at 70° for 4 h to give 4-(1-benzimidazolyl)phthalonitrile. This was further treated with ZnCl2 and DBU in pentanol at 100° for 10 h to give tetra[β-(1-benzimidazolyl)] zinc phthalocyanine (II) with maximum absorption peak 682 nm.

IT . 173286-81-2P

> (inermol. cyclocondensation of; preparation of phthalocyanine dyes having heterocyclyl group with high solubility in organic solvents)

173286-81-2 HCAPLUS RN

CN 1,2-Benzenedicarbonitrile, 4-(1H-benzimidazol-1-yl)- (9CI) INDEX NAME)

IC ICM C09B047-04

CC 41-7 (Dyes, Organic Pigments, Fluorescent Brighteners, and Photographic Sensitizers)

Section cross-reference(s): 73, 74, 76

IT 173286-81-2P

(inermol. cyclocondensation of; preparation of phthalocyanine dyes having heterocyclyl group with high solubility in organic solvents)

L24 ANSWER 30 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

1995:680825 HCAPLUS

DOCUMENT NUMBER:

123:70225

TITLE:

Silver halide photographic material and image

formation

INVENTOR(S):

Sanpei, Takeshi

PATENT ASSIGNEE(S):

Konishiroku Photo Ind, Japan Jpn. Kokai Tokkyo Koho, 51 pp.

SOURCE:

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

| PATENT NO.             | KIND | DATE     | APPLICATION NO. | DATE |
|------------------------|------|----------|-----------------|------|
|                        |      |          |                 |      |
|                        |      |          |                 |      |
| JP 07104426            | A2   | 19950421 | JP 1993-250708  |      |
|                        |      |          |                 | 1993 |
|                        |      |          |                 | 1006 |
| JP 3362291             | B2   | 20030107 |                 |      |
| PRIORITY APPLN. INFO.: |      |          | JP 1993-250708  |      |
| ·                      |      |          |                 | 1993 |
|                        |      |          |                 | 1006 |

OTHER SOURCE(S): MARPAT 123:70225

AB In the title photog. material having ≥1 Ag halide emulsion layer and/or its adjacent layer containing a hydrazine derivative on 1 side of a support and ≥1 hydrophilic colloid layer on the other side of the support, the hydrophilic colloid layer contains a ≥1 nucleating accelerator. Image formation is also claimed. The photog. material is stable and free of fog and black spots.

IT 132773-86-5

(redox compound contained in photog. material free of fog and black spot)

RN 132773-86-5 HCAPLUS

CN Hydrazinecarboxylic acid, 2-[4-[[[3-(2,5-dihydro-5-thioxo-1H-tetrazol-1-yl)phenyl]sulfonyl]amino]phenyl]-, (nitro-1H-benzimidazol-1-yl)methyl ester (9CI) (CA INDEX NAME)

 $D1-NO_2$ 

ICM G03C001-76 IC

> ICS G03C001-06; G03C001-295; G03C001-33; G03C001-34; G03C001-43; G03C005-29; G03C005-31

CC 74-2 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

IT 132773-86-5 133682-17-4 134282-51-2 152208-74-7 164982-04-1

> (redox compound contained in photog. material free of fog and black spot)

L24 ANSWER 31 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

1995:498390 HCAPLUS

DOCUMENT NUMBER:

122:251982

TITLE:

Black and white silver halide photographic

material with ultra-high contrast

INVENTOR(S):

Fukawa, Junichi; Sanpei, Takeshi; Goto, Kenji Konishiroku Photo Ind, Japan

PATENT ASSIGNEE(S):

Jpn. Kokai Tokkyo Koho, 43 pp.

SOURCE:

CODEN: JKXXAF

DOCUMENT TYPE:

Patent LANGUAGE: Japanese

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| PATENT NO.             | KIND | DATE     | APPLICATION NO. | DATE |
|------------------------|------|----------|-----------------|------|
|                        |      |          |                 |      |
|                        |      |          |                 |      |
| JP 06347939            | A2   | 19941222 | JP 1993-138705  |      |
|                        |      |          |                 | 1993 |
|                        |      |          |                 | 0610 |
| PRIORITY APPLN. INFO.: |      |          | JP 1993-138705  |      |
|                        |      |          |                 | 1993 |
|                        |      |          |                 | 0610 |

OTHER SOURCE(S):

MARPAT 122:251982

GI

AB The title material contains I (R1 = H, acetyl; R2-4 = H, alkyl), polyhydroxy-benzene compds., or aminophenol compds. in a hydrophilic colloidal layer(s).

IT 132773-86-5

(black and white silver halide photog. material with ultra-high contrast)

RN 132773-86-5 HCAPLUS

CN Hydrazinecarboxylic acid, 2-[4-[[[3-(2,5-dihydro-5-thioxo-1H-tetrazol-1-yl)phenyl]sulfonyl]amino]phenyl]-, (nitro-1H-benzimidazol-1-yl)methyl ester (9CI) (CA INDEX NAME)

## $D1 - NO_2$

IC ICM G03C001-34

ICS G03C001-06; G03C001-33; G03C001-42

CC 74-2 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

IT 92-43-3, 1-Phenyl-3-pyrazolidone 95-86-3, 2,4-DiAminophenol 103-14-0, p-Benzylaminophenol 120-80-9, 2-Hydroxyphenol, uses 121-79-9, n-Propyl 3,4,5-Trihydroxybenzoate 122-87-2, n-(4-Hydroxyphenyl)glycine 123-30-8, 4-Aminophenol Hydroquinone, uses 149-91-7, Benzoic acid, 3,4,5-trihydroxy-, 150-75-4, N-Methyl-4-Aminophenol 611-24-5, N-Methyl-2-Aminophenol 824-46-4, 2-MethoxyHydroquinone 2525-05-5, 1,2-Benzenediol, 4-butyl- 2654-57-1, 1-Phenyl-4-methyl-3-pyrazolidone 2654-58-2, 1-Phenyl-4,4dimethyl-3-pyrazolidone 2835-96-3, 2-Methyl-4-aminophenol 2835-99-6, 3-Methyl-4-Aminophenol 13047-13-7, 1-Phenyl-4-methyl-4-hydroxymethyl-3-pyrazolidone 49865-92-1 86475-37-8, 1-Phenyl-2-acetyl-4,4-dimethyl-3-pyrazolidone 92698-99-2, 1-Phenyl-4,4-di-n-propyl-3-pyrazolidone 132773-86-5 133805-77-3, 1,2,3-Benzenetriol, 5-methoxy-134282-47-6 134282-51-2 146657-28-5 146657-30-9

146657-31-0 152208-74-7 160744-90-1

(black and white silver halide photog. material with ultra-high contrast)

L24 ANSWER 32 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

1995:275298 HCAPLUS

DOCUMENT NUMBER:

122:277984

TITLE:

Silver halide photographic materials

INVENTOR(S):

Yoshida, Kazuhiro

PATENT ASSIGNEE(S):

Konishiroku Photo Ind, Japan

SOURCE:

Jpn. Kokai Tokkyo Koho, 38 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

Japanese

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| PATENT NO.             | KIND | DATE     | APPLICATION NO. | DATE |
|------------------------|------|----------|-----------------|------|
|                        |      |          |                 |      |
|                        |      |          |                 |      |
| JP 06242545            | A2   | 19940902 | JP 1993-49936   |      |
|                        |      |          |                 | 1993 |
|                        |      |          |                 | 0217 |
| PRIORITY APPLN. INFO.: |      |          | JP 1993-49936   |      |
|                        |      |          |                 | 1993 |
|                        |      |          |                 | 0217 |

OTHER SOURCE(S):

MARPAT 122:277984

GI

In the title photog. materials comprising a support coated with AB ≥1 Ag halide emulsion layer, the gelatin content on  $\geq 1$  side with the layer is  $\leq 3.0$  g/m2 and  $\geq 1$ layer contains a hydrazine derivative, a redox compound releasing a development restrainer by oxidation, and a compound I [R1 = H, alkyl, aryl, amino, OR5 (R5 = alkyl, aryl, saturated carbon ring residue); R2-4 = H, halo, alkyl, aryl, alkoxy, aryloxy, cyano, sulfo, carboxy, R2 and R3, R2 and R4, or R3 and R4 may form a ring; m = 0-3; n = 1-3]. The materials show high contrast, good dot controlling property, and storage stability, and are useful for printing platemaking. Thus, a PET film with a conductive layer and a protective layer on the back side was coated successively with a Ag(I, Br) gelatin emulsion layer containing II and o-HOC6H4CH:NOH, a 1st gelatin-based layer, a 2nd gelatin-based layer containing III, and a protective layer to give a photog. film.

IT 161069-18-7

> (photog. film containing hydrazine derivative and redox compound and oxime compound)

RN 161069-18-7 HCAPLUS

CN Hydrazinecarboxylic acid, 2-(2-quinolinyl)-, [nitro-2-(1,2,2,2tetrafluoroethyl)-1H-benzimidazol-1-yl]methyl ester (9CI) (CA INDEX NAME)

$$\begin{array}{c|c}
F \\
CH-CF_3 \\
N \\
N-CH_2-O-C-NH-N
\end{array}$$

D1-NO2

IC ICM G03C001-34

ICS G03C001-047; G03C001-06; G03C001-43

CC 74-2 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

TΤ 94-67-7 1595-14-8 7470-09-9 134282-54-5 137215-47-5

141303-86-8 146615-50-1 152971-97-6 138981-32-5 154075-35-1 157761-46-1 160641-21-4 160816-94-4

160816-95-5 161069-18-7

(photog. film containing hydrazine derivative and redox compound and oxime compound)

L24 ANSWER 33 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 1994:422627 HCAPLUS

DOCUMENT NUMBER: 121:22627

TITLE: Thermal transfer sheet using sublimation dye

INVENTOR(S): Eguchi, Hiroshi; Kafuku, Masaaki; Takiguchi,

Ryohei

PATENT ASSIGNEE(S): Dai Nippon Printing Co., Ltd., Japan

SOURCE: Jpn. Kokai Tokkyo Koho, 34 pp.

CODEN: JKXXAF

DOCUMENT TYPE: Patent LANGUAGE: Japanese

FAMILY ACC. NUM. COUNT:

## PATENT INFORMATION:

| PATENT NO.      | KIND   | DATE     | APPLICATION NO. | DATE |
|-----------------|--------|----------|-----------------|------|
|                 |        |          |                 | _    |
|                 |        |          |                 |      |
| JP 05124364     | A2     | 19930521 | JP 1991-310199  |      |
|                 |        |          |                 | 1991 |
|                 |        |          |                 | 1030 |
| PRIORITY APPLN. | INFO.: |          | JP 1991-310199  |      |
|                 |        |          |                 | 1991 |
|                 |        |          |                 | 1030 |

OTHER SOURCE(S):

MARPAT 121:22627

GI

$$R^{5}$$
 $R^{6}$ 
 $N-N$ 
 $N=NK$ 
 $R^{5}$ 
 $N=NK$ 
 $N=NK$ 

AB The title thermal transfer sheet comprises a sheet substrate and a dye layer on 1 side of the substrate, and the magenta dye contained is a mixture of ≥1 anthraquinone dye I [(1) X = S, O, SO2; R3 = (cyclo)alkyl, aryl, allyl; or (2) X = chemical bond; R3 = halo, CN when R1 = NH2, R2 = OH and YR4 = H; (3) X = NH; R3 as defined above; YR4 = H when R1 = R2 = OH; and (4) X, R3 as defined above; Y = X; R4 = R3 when R1 = R2 = NH2, and  $\geq 1$  aromatic or aromatic heterocyclic azo dye from eg. II, III [R5-7 = H, halo, NO2, CN, (substituted) amino, (cyclo) alkyl, aryl, allyl, aralkyl, alkoxy, aryloxy, arylthio, alkoxycarbonyl, alkoxyalkyl, alkoxycarbonylalkyl, acylamino, sulfonylamino, ureido, carbamoyl, sulfamoyl, acyl, aromatic heterocyclyl; K = p-dialkylaminophenol, p-dialkylaminopyridino]. Full color images with superior high-d., sharpness, fastness and photoresistance can be obtained. ΙT 155525-14-7

(dye, thermal transfer sheet using)

RN 155525-14-7 HCAPLUS

CN Acetamide, N-[2-[[1-(4-ethoxybutyl)-5-methyl-1H-benzimidazol-2yl]azo]-5-[ethyl(2-hydroxyethyl)amino]phenyl]- (9CI) (CA INDEX

```
Et
                  (CH<sub>2</sub>)<sub>4</sub> - OEt
                                                         N-
                                                             СH2-СH2-ОН
                                               NHAC
Me
```

IC ICM B41M005-38 74-7 (Radiation Chemistry, Photochemistry, and CC Photographic and Other Reprographic Processes) 6408-72-6 TΤ 2478-67-3 16517-79-6 116-82-5 17418-58-5 33976-57-7 20210-72-4 38919-98-1 68385-96-6 69465-00-5 91576-02-2 71009-25-1 79609-68-0 83356-28-9 107689-09-8 112940-71-3 119308-07-5 120412-48-8 120412-59-1 135198-96-8 148331-78-6 154341-02-3 154341-03-4 154341-04-5 154341-05-6 154341-07-8 154341-08-9 154341-10-3 154341-11-4 154341-12-5 154341-13-6 154341-18-1 154341-16-9 154341-17-0 154341-19-2 155524-21-3 155524-22-4 155524-23-5 155524-20-2 155524-24-6 155524-25-7 155524-27-9 155524-26-8 155524-30-4 155524-28-0 155524-29-1 155524-31-5 155524-34-8 155524-32-6 155524-33-7 155524-35-9 155524-36-0 155524-37-1 155524-38-2 155524-39-3 155524-40-6 155524-41-7 155524-42-8 155524-43-9 155524-44-0 155524-45-1 155524-46-2 155524-47-3 155524-49-5 155524-48-4 155524-50-8 155524-51-9 155524-53-1 155524-52-0 155524-54-2 155524-55-3 155524-56-4 155524-57-5 155524-58-6 155524-59-7 155524-60-0 155524-61-1 155524-63-3 155524-62-2 155524-64-4 155524-65-5 155524-66-6 155524-67-7 155524-68-8 155524-69-9 155524-70-2 155524-71-3 155524-72-4 155524-73-5 155524-74-6 155524-75-7 155524-76-8 155524-77-9 155524-78-0 155524-79-1 155524-80-4 155524-81-5 155524-82-6 155524-83-7 155524-84-8 155524-85-9 155524-86-0 155524-87-1 155524-88-2 155524-89-3 155524-90-6 155524-91-7 155524-92-8 155524-93-9 155524-94-0 155524-95-1 155524-96-2 155524-97-3 155524-98-4 155524-99-5 155525-00-1 155525-01-2 155525-02-3 155525-03-4 155525-04-5 155525-05-6 155525-06-7 155525-07-8 155525-08-9 155525-09-0 155525-10-3 155525-11-4 155525-12-5 155525-13-6 155525-14-7 155525-15-8 155525-18-1 155525-16-9 155525-17-0 155525-19-2 155525-20-5 155525-21-6 155525-22-7 155525-23-8 155525-24-9 155525-27-2 155525-25-0 155525-26-1 155525-28-3 155525-29-4 155525-30-7 155525-31-8 155525-32-9 155525-33-0 155525-34-1 155525-35-2 155525-36-3 155525-37-4 155525-38-5 155525-39-6 155525-40-9 155525-41-0 (dye, thermal transfer sheet using)

L24 ANSWER 34 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 1994:148829

DOCUMENT NUMBER: 120:148829

TITLE: Silver halide photographic material containing development-inhibitor-releasing coupler

HCAPLUS

Page 67

INVENTOR(S):

Sanpei, Takeshi

PATENT ASSIGNEE(S):

Konishiroku Photo Ind, Japan

SOURCE:

Jpn. Kokai Tokkyo Koho, 44 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

Japanese

FAMILY ACC. NUM. COUNT:

. 1

PATENT INFORMATION:

| PATENT NO.             | KIND | DATE     | APPLICATION NO. | DATE |
|------------------------|------|----------|-----------------|------|
|                        |      |          |                 |      |
|                        |      |          |                 |      |
| JP 05241264            | A2   | 19930921 | JP 1992-39673   |      |
|                        |      |          |                 | 1992 |
|                        |      |          |                 | 0226 |
|                        |      |          |                 | 0226 |
| JP 2995360             | B2   | 19991227 |                 |      |
| PRIORITY APPLN. INFO.: |      |          | JP 1992-39673   |      |
|                        |      |          |                 | 1992 |
|                        |      |          |                 | 0226 |

OTHER SOURCE(S):

MARPAT 120:148829

AB The material has a hydrophilic colloid layer containing a redox DIR compound and a photog. emulsion layer containing a hydrazine derivative and the total gelatin content at the emulsion side is ≤3.5 g/m2. The material gives sharp gradation image with low black pepper generation.

IT 132773-86-5

(photog. DIR coupler)

RN 132773-86-5 HCAPLUS

CN Hydrazinecarboxylic acid, 2-[4-[[[3-(2,5-dihydro-5-thioxo-1H-tetrazol-1-yl)phenyl]sulfonyl]amino]phenyl]-, (nitro-1H-benzimidazol-1-yl)methyl ester (9CI) (CA INDEX NAME)

 $D1-NO_2$ 

IC ICM G03C001-06

ICS G03C001-295; G03C001-34; G03C001-43

CC 74-2 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

IT 132773-86-5 134282-47-6 134282-51-2 152208-74-7 (photog. DIR coupler)

L24 ANSWER 35 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

1992:265487 HCAPLUS

DOCUMENT NUMBER:

116:265487

TITLE:

Silver halide photographic material containing

development inhibitor-releasing coupler

INVENTOR(S):

Sugita, Shuichi; Kida, Shuji

PATENT ASSIGNEE(S):

Konica Co., Japan SOURCE:

Jpn. Kokai Tokkyo Koho, 14 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

Japanese

FAMILY ACC. NUM. COUNT:

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PATENT INFORMATION:

PATENT NO. KIND DATE

JP 04044036

A2 19920213 JP 1990-153150

> 1990 0612

DATE

PRIORITY APPLN. INFO.:

JP 1990-153150

APPLICATION NO.

-----

II

1990

0612

GI

$$Cp(TIME)_1s \xrightarrow{N}_{R1}^{R2}$$

AB The title material contains a coupler represented by general structures I and II (Cp = coupler residue which can undergo a coupling reaction with an oxidized color developing agent; TIME = timing group linked to Cp at the coupling site; 1 = 0 or 1; R1 = group represented by XY, or substituent other than group represented by XY; R2 = H, R1; ≥1 of R1 and R2 is a group represented by XY; X = linking group; Y = hydrolyzable group). The above-mentioned coupler can release a development inhibitor upon reaction with an oxidized developing agent. The title material provides good sharpness and excellent color reproduction IT 141720-28-7P

(preparation of, as photog. development inhibitor-releasing coupler)

ŔŊ 141720-28-7 HCAPLUS CN

1H-Benzimidazole-1-acetic acid, 2-[[[4-[1-[[[2-chloro-5-[(hexadecylsulfonyl)amino]phenyl]amino]carbonyl]-3,3-dimethyl-2oxobutoxy]-3-nitrophenyl]methyl]thio]-, methyl ester (9CI) (CA INDEX NAME)

IC ICM G03C007-305 ICS G03C007-32

CC 74-2 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

Section cross-reference(s): 41

IT 141720-28-7P 141720-29-8P (preparation of, as photog. development inhibitor-releasing coupler)

L24 ANSWER 36 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

1992:72139 HCAPLUS

DOCUMENT NUMBER:

INVENTOR(S):

116:72139

TITLE:

Silver halide photographic material Inoue, Nobuaki; Okamura, Hisashi

PATENT ASSIGNEE(S): SOURCE:

Fuji Photo Film Co., Ltd., Japan Jpn. Kokai Tokkyo Koho, 35 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent Japanese

LANGUAGE:

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| PATENT NO.             | KIND | DATE     | APPLICATION NO. | DATE |
|------------------------|------|----------|-----------------|------|
|                        |      |          |                 |      |
|                        |      |          |                 |      |
| JP 03100646            | A2   | 19910425 | JP 1989-239277  |      |
|                        |      |          |                 | 1989 |
|                        |      |          |                 | 0914 |
| PRIORITY APPLN. INFO.: |      |          | JP 1989-239277  |      |
|                        |      |          |                 | 1989 |
|                        |      |          |                 | 0914 |

GI

AB In the title material comprising ≥2 kinds of monodispersed Ag halide emulsions on a support, the Ag halide emulsions or other hydrophilic colloid layers contain hydrazine derivs. and RYNHLNHNHCO(Time)tPUG (I) [R = an aliphatic group, aryl, heterocyclyl; L = a divalent organic group; Time = a timing group; t = 0 or 1; PUG = a photog. useful group; Y = SO2, Y1P(:O)Y1R; Y1 = O, NH, etc.]. The average size of Ag halide grains in the emulsions is 0.5 μm or less. The title material provides high-quality images. II is an example of I.

IT 132773-86-5

(photog. emulsion containing)

RN 132773-86-5 HCAPLUS

CN Hydrazinecarboxylic acid, 2-[4-[[[3-(2,5-dihydro-5-thioxo-1H-tetrazol-1-yl)phenyl]sulfonyl]amino]phenyl]-, (nitro-1H-benzimidazol-1-yl)methyl ester (9CI) (CA INDEX NAME)

 $D1 - NO_2$ 

IC ICM G03C001-06

CC 74-2 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

IT 86551-61-3 114750-35-5 **132773-86-5** 134282-55-6 138502-88-2 138502-89-3 138502-90-6 138502-91-7 138502-92-8 138551-67-4 (photog. emulsion containing)

L24 ANSWER 37 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 1992:48775 HCAPLUS

DOCUMENT NUMBER: 116:48775

TITLE:

Silver halide photographic material

INVENTOR (S):

Inoue, Nobuaki; Inoe, Nobuaki; Okada, Hisashi

PATENT ASSIGNEE(S): SOURCE:

Fuji Photo Film Co., Ltd., Japan Jpn. Kokai Tokkyo Koho, 59 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent Japanese

---**-**

LANGUAGE:
FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

PATENT NO. KIND DATE APPLICATION NO. DATE

\_\_\_\_\_

A2 19910412 JP 1990-45234

1990 0226

PRIORITY APPLN. INFO.:

JP 03087733

JP 1989-144721

1989

0607

GI

AB In the title material comprising one or more photosensitive Ag halide emulsion layers on a support, the emulsion layers or other hydrophilic colloid layers contain one or more hydrazine derivs. and one or more redox compds. which release development inhibitors upon oxidation The photosensitive emulsion layers in the title material consists of monodispersed emulsions. I is an example of the above-mentioned hydrazines. The title material provides high-quality images.

Ι

IT 132773-86-5

(silver halide photog. emulsion containing)

RN 132773-86-5 HCAPLUS

CN Hydrazinecarboxylic acid, 2-[4-[[[3-(2,5-dihydro-5-thioxo-1H-tetrazol-1-yl)phenyl]sulfonyl]amino]phenyl]-, (nitro-1H-benzimidazol-1-yl)methyl ester (9CI) (CA INDEX NAME)

D1-NO2

IC ICM G03C001-06

CC 74-2 (Radiation Chemistry, Photochemistry, and **Photographic** and Other Reprographic Processes)

IT 86551-61-3 114750-35-5 **132773-86-5** 138499-95-3 138499-96-4

(silver halide photog. emulsion containing)

L24 ANSWER 38 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

1992:22874 HCAPLUS

DOCUMENT NUMBER:

116:22874

TITLE:

Dye-donor elements comprising methine or

azomethine dyes for use in thermal dye

transfer

INVENTOR (S):

Vanmaele, Luc Jerome

PATENT ASSIGNEE(S):

Agfa-Gevaert N. V., Belg.

SOURCE:

Eur. Pat. Appl., 23 pp.
CODEN: EPXXDW

DOCUMENT TYPE:

Patent

LANGUAGE:

English

FAMILY ACC. NUM. COUNT:

AMILY ACC. NOM. COUNT:

PATENT INFORMATION:

| PATENT NO.             | KINE | DATE        | APPLICATION NO.     | DATE      |
|------------------------|------|-------------|---------------------|-----------|
|                        |      |             |                     | · <b></b> |
| EP 444327              | A1   | 19910904    | EP 1990-200483      |           |
|                        |      |             |                     | 1990      |
|                        |      |             |                     | 0301      |
| EP 444327              | B1   | 19940921    |                     |           |
| R: AT, BE, CH,         | DE,  | DK, ES, FR, | GB, GR, IT, LI, LU, | NL, SE    |
| US 5116806             | Α    | 19920526    | US 1991-654684      |           |
| w:                     |      |             |                     | 1991      |
|                        |      |             |                     | 0213      |
| JP 04216994            | A2   | 19920807    | JP 1991-56049       |           |
|                        |      |             |                     | 1991      |
|                        |      |             |                     | . 0226    |
| PRIORITY APPLN. INFO.: |      |             | EP 1990-200483      | A         |
| •                      |      |             |                     | 1990      |
|                        |      |             |                     | 0301      |

OTHER SOURCE(S): MARPAT 116:22874
GI For diagram(s), see printed CA Issue.

AB Thermal-transfer printing elements consist of supports, binders, and dyes I [ring A is aromatic or heterocyclic, and may be substituted; X = NZ1, NZ2, NN:Z2, CR1R2; Y = O, S, NR3; R1, R2 =

H, (un) substituted alkyl, cycloalkyl, aryl, alkenyl, alkynyl, or heterocyclyl, CN, halogen, SO2R4, COR4, CSR4, POR4R5, or CR1R2 is a ring; R3 = H, (un) substituted alkyl, cycloalkyl, or aryl, SO2R4, COR4, CSR4, POR4R5; R4, R5 = (un)substituted alkyl, cycloalkyl, aryl, alkenyl, aralkyl, alkoxy, aryloxy, alkylthio, arylthio, amino, or heterocyclyl, or PR4R5 is a 5- or 6-membered ring; Z1 = p-substituted aryl; Z2 = (un) substituted heterocyclyl], the synthesis of which is described. Mixing 2-(cyanomethyl)benzimidazole in MeOH with 1.1 equiv p-Et2NC6H4NH2.HCl, adding aqueous NaCO3, treating with iodine in MeOH, and filtering gave I (A is benzo, X = NC6H4NEt2-4, Y = NH) (II), Amax (MeOH) 495 nm. A donor element containing a layer of 50 parts II in 50 parts cellulose acetate butyrate was placed in contact with a receiving element and put through a color video printer to give images with maximum color d. (RD 919 densitometer, status A) 140.

IT 20923-18-6

(condensation of, with dimethylpyranone)

RN 20923-18-6 HCAPLUS

CN 1H-Benzimidazole-1-carboxylic acid, 2-(cyanomethyl)-, ethyl ester (9CI) (CA INDEX NAME)

IT 138073-99-1P 138101-61-8P

(preparation of, as dye for thermal-transfer printing)

RN 138073-99-1 HCAPLUS

CN 1H-Benzimidazole-1-carboxylic acid, 2-[cyano(2,6-dimethyl-4H-pyran-4-ylidene)methyl]-, ethyl ester (9CI) (CA INDEX NAME)

RN 138101-61-8 HCAPLUS

CN 1H-Benzimidazole-1-carboxylic acid, 2-[cyano[[4-(diethylamino)phenyl]imino]methyl]-, ethyl ester (9CI) (CA INDEX NAME)

IT 138073-86-6P 138073-95-7P 138073-96-8P 138101-60-7P

(preparation of, for donor element for three-color transfer printing)

RN 138073-86-6 HCAPLUS

CN 1H-Benzimidazole-1-carboxylic acid, 2-[cyano[[4-(diethylamino)-2-methylphenyl]imino]methyl]-, ethyl ester (9CI) (CA INDEX NAME)

RN 138073-95-7 HCAPLUS

CN 1H-Benzimidazole-1-carboxylic acid, 2-[cyano[[4-(diethylamino)-2-[(2-methyl-1-oxopropyl)amino]phenyl]imino]methyl]-, ethyl ester (9CI) (CA INDEX NAME)

RN 138073-96-8 HCAPLUS

CN 1H-Benzimidazole-1-carboxylic acid, 2-[cyano[[4-(diethylamino)-2-[(1-oxohexyl)amino]phenyl]imino]methyl]-, ethyl ester (9CI) (CA INDEX NAME)

RN 138101-60-7 HCAPLUS

CN 1H-Benzimidazole-1-carboxylic acid, 2-[cyano[[4-(diethylamino)-2-[(2,2-dimethyl-1-oxopropyl)amino]phenyl]imino]methyl]-, ethyl ester (9CI) (CA INDEX NAME)

IC ICM B41M005-38

CC 41-3 (Dyes, Organic Pigments, Fluorescent Brighteners, and
Photographic Sensitizers)
Section cross-reference(s): 74

IT 20923-18-6

(condensation of, with dimethylpyranone)

IT 51553-32-3P 57319-74-1P 138073-98-0P 138073-99-1P 138074-00-7P 138074-05-2P 138074-06-3P 138074-07-4P 138074-09-6P 138074-12-1P 138074-13-2P 138101-61-8P 138101-62-9P

(preparation of, as dye for thermal-transfer printing)
IT 138073-81-1P 138073-82-2P 138073-83-3P 138073-84-4P
138073-85-5P 138073-86-6P 138073-87-7P 138073-88-8P
138073-89-9P 138073-90-2P 138073-91-3P 138073-92-4P

138073-93-5P 138073-94-6P **138073-95-7P** 138073-96-8P 138073-97-9P 138101-59-4P

138101-60-7P

(preparation of, for donor element for three-color transfer printing)

L24 ANSWER 39 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 1992:13197 HCAPLUS

DOCUMENT NUMBER: 116:13197

TITLE: Ultrahigh-contrast silver halide photographic

materials

INVENTOR(S): Kato, Kazunobu; Okada, Hisashi PATENT ASSIGNEE(S): Fuji Photo Film Co., Ltd., Japan

SOURCE:

Jpn. Kokai Tokkyo Koho, 43 pp.

CODEN: JKXXAF

DOCUMENT TYPE: LANGUAGE:

Patent Japanese

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| PATENT NO.             | KIND | DATE     | APPLICATION NO. | DATE |
|------------------------|------|----------|-----------------|------|
|                        |      |          |                 |      |
|                        |      |          |                 |      |
| JP 02304433            | A2   | 19901218 | JP 1989-125385  |      |
|                        |      |          |                 | 1989 |
|                        |      |          |                 | 0518 |
| PRIORITY APPLN. INFO.: |      |          | JP 1989-125385  |      |
|                        |      |          |                 | 1989 |
|                        |      |          |                 | 0518 |

AB In the title material having on a support gelatin-containing hydrophilic colloidal layers, the hydrophilic colloidal layers have fine polymer particles containing a hydrazine derivative and the hydrophilic colloidal layers and/or the other hydrophilic colloidal layers contain a redox compound which releases a development inhibitor upon oxidation

IT 132773-86-5

(ultrahigh-contrast silver halide photog. materials containing)

RN 132773-86-5 HCAPLUS

Hydrazinecarboxylic acid, 2-[4-[[[3-(2,5-dihydro-5-thioxo-1H-CN tetrazol-1-yl)phenyl]sulfonyl]amino]phenyl]-, (nitro-1Hbenzimidazol-1-yl)methyl ester (9CI) (CA INDEX NAME)

D1-NO2

IC ICM G03C001-06

ICS G03C001-04

74-2 (Radiation Chemistry, Photochemistry, and CC Photographic and Other Reprographic Processes)

ΙT 105754-54-9 128811-06-3 **132773-86-5** 136271-71-1

137757-22-3 137757-23-4 136322-65-1

(ultrahigh-contrast silver halide photog. materials containing)

L24 ANSWER 40 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

1991:691047 HCAPLUS

DOCUMENT NUMBER:

115:291047

TITLE:

Silver halide photographic material Goto, Takahiro; Kato, Kazunobu

INVENTOR(S): PATENT ASSIGNEE(S):

Fuji Photo Film Co., Ltd., Japan

SOURCE:

Jpn. Kokai Tokkyo Koho, 43 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

Japanese

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| PATENT NO.             | KIND | DATE     | APPLICATION NO.  | DATE |
|------------------------|------|----------|------------------|------|
|                        |      |          |                  |      |
| JP 03103843            | A2   | 19910430 | JP 1989-242442   |      |
|                        |      |          |                  | 1989 |
|                        |      |          |                  | 0919 |
| JP 2881221             | B2   | 19990412 |                  |      |
| US 5155006             | A    | 19921013 | US 1990-584668   |      |
|                        |      |          |                  | 1990 |
|                        |      |          |                  | 0919 |
| PRIORITY APPLN. INFO.: |      |          | JP 1989-242442 A |      |
|                        |      |          |                  | 1989 |
|                        |      |          |                  | 0919 |

The title material comprises: (a) at least one photosensitive Ag AB halide emulsion layer containing a hydrazine derivative; (b) a hydrophilic colloid layer (other than the above-mentioned photosensitive layer) containing a redox compound which releases a development inhibitor upon oxidation; and (c) a developing agent in the above-mentioned Ag halide emulsion layer or at least one of the hydrophilic colloid layers. The title material shows high contrast.

IT 132773-86-5

(photog. material containing)

RN132773-86-5 HCAPLUS

Hydrazinecarboxylic acid, 2-[4-[[[3-(2,5-dihydro-5-thioxo-1H-CN tetrazol-1-yl)phenyl]sulfonyl]amino]phenyl]-, (nitro-1Hbenzimidazol-1-yl) methyl ester (9CI) (CA INDEX NAME)

 $D1-NO_2$ 

IC ICM G03C001-06

74-2 (Radiation Chemistry, Photochemistry, and CC

Photographic and Other Reprographic Processes)

IT 92-43-3, 1-Phenyl-3-pyrazolidone 123-31-9, Hydroquinone, uses and miscellaneous 86551-61-3 105754-54-9 132773-86-5 133682-17-4 133682-19-6 134282-47-6 134282-53-4 134293-25-7 137811-39-3 137814-39-2 (photog. material containing)

L24 ANSWER 41 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

1991:570803 HCAPLUS

DOCUMENT NUMBER:

115:170803

TITLE:

High contrast silver halide photographic films

INVENTOR(S):
PATENT ASSIGNEE(S):

Kato, Kazunobu; Okamura, Hisashi Fuji Photo Film Co., Ltd., Japan Jpn. Kokai Tokkyo Koho, 39 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

SOURCE:

Japanese

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| PATENT NO.             | KIND       | DATE     | APPLICATION NO. |   | DATE                 |
|------------------------|------------|----------|-----------------|---|----------------------|
| <br>JP 02285340        | <b>A</b> 2 | 19901122 | JP 1989-108216  |   | 1989                 |
| US 5187042             | A          | 19930216 | US 1990-515882  |   | 1990                 |
| PRIORITY APPLN. INFO.: |            |          | JP 1989-108216  | A | 0427<br>1989<br>0427 |
|                        |            |          | JP 1989-109981  | A | 1989<br>0428         |
|                        |            |          | JP 1989-113093  | A | 1989<br>0502         |
|                        |            |          | JP 1989-129226  | A | 1989<br>0523         |
|                        |            |          | JP 1989-144721  | A | 1989<br>0607         |

AB The title material, suited for use in lith film, comprises ≥1 Ag halide emulsion layer(s) containing hydrazine deriv(s).0 a redox compound releasing a development inhibitor upon oxidation, and a A-B copolymer [A = ethylenic unsatd. monomer having acid group(s); B = unsat. cross linking monomer having ≥2 ethylenic unsatd. groups.

IT 132773-86-5

(development inhibitor-releasing redox compound, high contrast lith film containing)

RN 132773-86-5 HCAPLUS

CN Hydrazinecarboxylic acid, 2-[4-[[[3-(2,5-dihydro-5-thioxo-1H-tetrazol-1-yl)phenyl]sulfonyl]amino]phenyl]-, (nitro-1H-benzimidazol-1-yl)methyl ester (9CI) (CA INDEX NAME)

 $D1-NO_2$ 

IC ICM G03C001-04 ICS G03C001-06

CC 74-2 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)

IT 132773-86-5 133682-17-4 133682-18-5 134282-53-4

136271-69-7 136271-70-0 136271-71-1

(development inhibitor-releasing redox compound, high contrast lith film containing)

L24 ANSWER 42 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

1991:482126 HCAPLUS

DOCUMENT NUMBER:

115:82126

TITLE:

Silver halide photographic materials

INVENTOR(S):

Kato, Kazunobu; Okada, Hisashi Fuji Photo Film Co., Ltd., Japan

PATENT ASSIGNEE(S): SOURCE:

Jpn. Kokai Tokkyo Koho, 40 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

TYPE: Patent

LANGUAGE:

Japanese 5

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| 1989         |
|--------------|
| 0428         |
|              |
| 1990         |
| 0427         |
| 1989         |
| 0427         |
|              |
|              |
| 1989<br>0428 |
| 0420         |
|              |
| 1989         |
| 0502         |
|              |
|              |

1989 0523

JP 1989-144721

1989 0607

GI

AB The title materials comprise: a) one or more photosensitive silver halide emulsion layers containing a hydrazine derivative; b) a redox compound which releases a development inhibitor upon oxidation; and c) a benzoxazole derivative I (Z11, Z12 = non-metallic atoms forming benzoxazole, benzothiazole ring, etc.; R11, R12 = alkyl, aralkyl, at least one of them has an acidic group; X = counter ion; m = 0 or 1). Benzoxazole II is an example of I.

IT 132773-86-5

(photog. material containing)

RN 132773-86-5 HCAPLUS

CN Hydrazinecarboxylic acid, 2-[4-[[[3-(2,5-dihydro-5-thioxo-1H-tetrazol-1-yl)phenyl]sulfonyl]amino]phenyl]-, (nitro-1H-benzimidazol-1-yl)methyl ester (9CI) (CA INDEX NAME)

 $D1-NO_2$ 

IC ICM G03C001-06

CC 74-2 (Radiation Chemistry, Photochemistry, and **Photographic** and Other Reprographic Processes)

IT 51588-61-5 86551-61-3 90895-26-4 105754-54-9 121216-75-9

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121216-77-1 122558-45-6 127890-98-6 132773-86-5
133682-17-4 134282-47-6 134282-48-7 134282-52-3
134282-53-4 134282-54-5 135350-58-2
                                      135350-59-3
135350-60-6 135350-61-7 135377-54-7
   (photog. material containing)
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L24 ANSWER 43 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

1991:482098 HCAPLUS

DOCUMENT NUMBER:

115:82098

TITLE: INVENTOR (S): Silver halide photographic materials Katoh, Kazunobu; Yagigara, Morio; Goto,

Takahiro

PATENT ASSIGNEE(S):

Fuji Photo Film Co., Ltd., Japan

SOURCE:

Eur. Pat. Appl., 79 pp.

CODEN: EPXXDW

DOCUMENT TYPE:

Patent

LANGUAGE:

English

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| PATENT NO.                          | KIND     | DATE                 | APPLICATION NO. | DATE               |
|-------------------------------------|----------|----------------------|-----------------|--------------------|
| EP 395069                           | A2       | 19901031             | EP 1990-107991  | 1990               |
| ED 305060                           | 3.2      | 10010116             |                 | 0426               |
| EP 395069<br>EP 395069<br>R: DE, GB | A3<br>B1 | 19910116<br>19960710 |                 |                    |
| JP 03174143                         | A2       | 19910729             | JP 1990-91570   | 1990<br>0406       |
| JP 03039952                         | A2       | 19910220             | JP 1990-93484   | 1990<br>0409       |
| US 5395732                          | A        | 19950307             | US 1992-893945  | 1992<br>0604       |
| PRIORITY APPLN. INFO.:              |          |                      | JP 1989-108215  | .A<br>1989<br>0427 |
|                                     |          |                      | JP 1989-240967  | A<br>1989<br>0918  |
|                                     |          |                      | US 1990-515994  | B1<br>1990<br>0427 |

OTHER SOURCE(S): MARPAT 115:82098

A Ag halide photog. material is disclosed, which comprises: (a) ≥1 light-sensitive Ag halide emulsion layer containing a hydrazine derivative; and (b) a hydrophilic colloid layer which is different from the light-sensitive silver halide emulsion layer and contains a redox compound capable of releasing a development inhibitor as a result of oxidation The material has superhigh contrast, and is useful in photomech. processes.

IT 132773-86-5

(photog. emulsion containing)

RN 132773-86-5 HCAPLUS

CN Hydrazinecarboxylic acid, 2-[4-[[[3-(2,5-dihydro-5-thioxo-1H-tetrazol-1-yl)phenyl]sulfonyl]amino]phenyl]-, (nitro-1H-benzimidazol-1-yl)methyl ester (9CI) (CA INDEX NAME)

D1-NO2 ·

IC ICM G03C001-10

ICS G03C007-305; G03C001-46; G03C001-76

CC 74-2 (Radiation Chemistry, Photochemistry, and **Photographic** and Other Reprographic Processes)

IT 86551-61-3 105754-54-9 114750-35-5 132773-86-5 133682-17-4 133682-18-5 134282-46-5 134282-47-6 134282-49-8 134282-48-7 134282-50-1 134282-51-2 134282-52-3 134282-53-4 134282-54-5 134282-55-6 134293-25-7

(photog. emulsion containing)

L24 ANSWER 44 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

1991:217975 HCAPLUS

DOCUMENT NUMBER:

114:217975

TITLE:

Silver halide photographic material containing

compound releasing photographically useful

group

INVENTOR (S):

Okamura, Hisashi; Okada, Hisashi; Yagihara,

Morio; Katoh, Kazunobu; Mihayashi, Keiji

PATENT ASSIGNEE(S):

Fuji Photo Film Co., Ltd., Japan

SOURCE:

Eur. Pat. Appl., 94 pp. CODEN: EPXXDW

DOCUMENT TYPE:

Patent

LANGUAGE:

English

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| PATENT NO.               | KIND     | DATE                 | APPLICATION NO. | DATE |
|--------------------------|----------|----------------------|-----------------|------|
| EP 393720                | A2       | 19901024             | EP 1990-107625  | 1990 |
| EP 393720<br>EP 393720   | A3<br>B1 | 19920930<br>19950823 |                 | 0423 |
| R: DE, GB<br>JP 03039949 | A2       | 19910220             | JP 1989-290563  | 1989 |
| JP 2632056               | В2       | 19970716             |                 | 1108 |

US 5134055 A 19920728 US 1990-512221

1990
0420

PRIORITY APPLN. INFO.:

JP 1989-102395 A

1989
0421

JP 1989-290563 A

1989
1108

OTHER SOURCE(S): MARPAT 114:217975

AB Ag halide photog. material contains ≥1 compound represented by the general formula RYNHLNHNHCO(Time)t PUG (R = an aliphatic, aromatic, or heterocyclic group; L, Time = a divalent group; t = 0 or 1; PUG = a photog. useful group; Y = S = Oz, ZSO2, ZPOZR; Z = O, NH, or NR) and optionally ≥1 hydrazine derivative represented by the general formula R1R2NNR3Z1R4 (R1 = an aliphatic or aromatic group; R2, R3 = H, acyl, alkylsulfonyl, or arylsulfonyl with R2 R3 = H; R4 = H, alkyl, aryl, alkoxy, aryloxy, amino, carbamoyl, or oxycarbonyl; Z1 = CO, SO2, SO, COCO, POR4, thiocarbonyl, or iminomethylene). The photog. material thus described has high-resolution and broad exposure latitude in line image-taking work and may excellently reproduce a line original to form an ultrahard image having a gamma value ≥10.

IT 132773-86-5

(silver halide photog. emulsions containing, for lithog.)

RN 132773-86-5 HCAPLUS

CN Hydrazinecarboxylic acid, 2-[4-[[[3-(2,5-dihydro-5-thioxo-1H-tetrazol-1-yl)phenyl]sulfonyl]amino]phenyl]-, (nitro-1H-benzimidazol-1-yl)methyl ester (9CI) (CA INDEX NAME)

 $D1-NO_2$ 

IC ICM G03C001-06

ICA G03C008-08; G03C008-40

CC 74-2 (Radiation Chemistry, Photochemistry, and

Photographic and Other Reprographic Processes)
132773-86-5 132773-87-6 132773-88-7 1328

IT **132773-86-5** 132773-87-6 132773-88-7 132801-46-8 132877-36-2 132877-37-3 132877-38-4 132877-39-5

132877-40-8 132877-41-9 132877-42-0 132877-43-1

132877-44-2 132877-45-3 132877-46-4 132877-47-5

132877-48-6 132877-49-7 133832-21-0

(silver halide photog. emulsions containing, for lithog.)

L24 ANSWER 45 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN ACCESSION NUMBER: 1989:415474 HCAPLUS

DOCUMENT NUMBER:

111:15474

TITLE:

Formation of nonlinear optical patterns

INVENTOR (S):

Okazaki, Masaki; Kubodera, Seiichi Fuji Photo Film Co., Ltd., Japan

PATENT ASSIGNEE(S): SOURCE:

Jpn. Kokai Tokkyo Koho, 10 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

Japanese

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

| PATENT NO.             |        | KIND | DATE     | APPLICATION NO. | DATE |
|------------------------|--------|------|----------|-----------------|------|
|                        |        |      |          |                 |      |
|                        |        |      |          |                 |      |
| JP 63237038            | 3      | A2   | 19881003 | JP 1987-72183   |      |
|                        |        |      |          |                 | 1987 |
|                        |        |      |          | •               | 0326 |
| PRIORITY APPLN. INFO.: | INFO.: |      |          | JP 1987-72183   |      |
| •                      |        |      |          | •               | 1987 |
|                        |        |      |          |                 | 0326 |

GI

The title patterns are formed on substrates, e.g., in the preparation AB of optical elements for communication devices, etc., by coating with amphipathic materials, MLA [M = hydrophobic groups containing polymerizable monomer units; L = hydrophilic groups; A = residue of (nitro- and other group-substituted) benzimidazole, imidazole, or indole derivs.], exposing to high energy radiation through a patterned mask, and developing. Compound I, deposited as built-up Langmuir-Blodgett films (400 layer) on a quartz waveguide support, was irradiated with far-UV through a mask, and developed with a 1:4 CHCl3-hexane mixture to prepare a 1-µm nonlinear optical pattern layer.

Ι

IT 121092-75-9

(Langmuir-Blodgett films, radiation-curable, nonlinear optical patterns from)

121092-75-9 HCAPLUS RN

CN 3,5,8-Trioxa-4-phosphanonacosa-18,20-diyn-1-aminium, 4-hydroxy-N,N,N-trimethyl-7-[[[9-(2-methyl-5-nitro-1H-benzimidazol-1-yl)-1-oxononyl]oxy]methyl]-9-oxo-, inner salt, 4-oxide, homopolymer (9CI) (CA INDEX NAME)

CM 1 CRN 121092-74-8 CMF C46 H73 N4 O10 P

PAGE 1-A

PAGE 1-B

-- (CH<sub>2</sub>)<sub>7</sub>-Me

— м+мез

IC ICM G02F001-35

ICS C08F018-12; C08F020-20; C08F020-36; C08F020-38; C08F026-02; C08F030-02; C08F246-00; C08L101-00; G02B006-12

CC 74-13 (Radiation Chemistry, Photochemistry, and **Photographic** and Other Reprographic Processes)

Section cross-reference(s): 38, 73

IT 121092-61-3 121092-63-5 121092-65-7 121092-67-9

121092-69-1 121092-71-5 121092-73-7 **121092-75-9** 

121092-77-1 121092-79-3

(Langmuir-Blodgett films, radiation-curable, nonlinear optical patterns from)

L24 ANSWER 46 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 1989:85382 HCAPLUS

DOCUMENT NUMBER: 110:85382

TITLE: Electrophotographic photoreceptor containing

charge-transporting benzimidazole derivative

INVENTOR(S): Shiino, Yasuko; Matsumoto, Masakazu

PATENT ASSIGNEE(S): Canon K. K., Japan

SOURCE: Jpn. Kokai Tokkyo Koho, 13 pp.

CODEN: JKXXAF

DOCUMENT TYPE: Patent

LANGUAGE: Japanese FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

| PATENT NO.  | KIND | DATE     | APPLICATION NO. | DATE         |
|-------------|------|----------|-----------------|--------------|
| JP 63157157 | A2   | 19880630 | JP 1986-303856  | 1986<br>1222 |

PRIORITY APPLN. INFO.:

JP 1986-303856

1986 1222

GI

AB The title photoreceptor has a photosensitive layer containing a benzimidazole derivative I (R1 = alkyl, aryl, heterocyclyl; R2, R3 = H, R1, aralkyl; R2, R3, and the central C may form a ring residue; A = aralkyl, R1).

IT 119028-30-7

(electrophotog. charge-transporting agent)

RN 119028-30-7 HCAPLUS

CN Benzenamine, 4-[2-[2-(2-furanyl)-1-(3-propoxy-1-naphthalenyl)-1H-benzimidazol-5-yl]-1-phenylethenyl]-N,N-dimethyl- (9CI) (CA INDEX NAME)

IC ICM G03G005-06

IT

CC 74-3 (Radiation Chemistry, Photochemistry, and

Photographic and Other Reprographic Processes) 119028-13-6 119028-14-7 119028-26-1 11902

119028-13-6 119028-14-7 119028-26-1 119028-27-2 119028-28-3 119028-29-4 **119028-30-7** 119028-31-8

119028-32-9 119028-33-0 119028-34-1 119028-35-2

119028-36-3 119028-37-4 119028-38-5 119028-39-6

119045-81-7

(electrophotog. charge-transporting agent)

L24 ANSWER 47 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 1984:69842 HCAPLUS

DOCUMENT NUMBER: 100:69842

TITLE: Arylamination of aminohalogenoanthraquinones

AUTHOR(S): Philip, George; Nabar, U. T.; Kanetkar, V. R.;

Sunthankar, S. V.

CORPORATE SOURCE: Dep. Chem. Technol., Univ. Bombay, Bombay, 400

019, India

SOURCE: Indian Journal of Chemistry, Section B:

Organic Chemistry Including Medicinal

Chemistry (1983), 22B(8), 808-11 CODEN: IJSBDB; ISSN: 0376-4699

DOCUMENT TYPE: LANGUAGE: Journal English

OTHER SOURCE(S):

CASREACT 100:69842

AB 1-Amino-4-(arylamino) anthraquinones were prepared in high yields by reacting 1-amino-4-chloroanthraquinone [2872-47-1] 1, arylamine 6, and anhydrous AlCl3 5 mol in PhNO2 at room temperature 1-Amino-2-bromoanthraquinone, 2-amino-1-chloroanthraquinone, 1-benzamido-4-chloroanthraquinone, and 1-amino-5-chloroanthraquinone failed to give arylaminated products. 1-Amino-2,4-dibromoanthraquinone [81-49-2] gave only 4-arylaminated compds. whereas 1-amino-8-chloroanthraquinone [117-09-9] gave 2-arylaminated derivs. A mechanism for the reaction was suggested. The arylaminated compds were applied on polyester as disperse dyes and their dyeing properties evaluated.

IT 88653-29-6P

(preparation of)

RN 88653-29-6 HCAPLUS

CN 3H-Anthra[1,2-d]imidazole-6,11-dione, 3-(4-methoxyphenyl)- (9CI) (CA INDEX NAME)

CC 41-4 (Dyes, Organic Pigments, Fluorescent Brighteners, and **Photographic** Sensitizers)

Section cross-reference(s): 25

IT 1564-71-2P 60683-36-5P 88653-16-1P 88653-19-4P 88653-20-7P 88653-23-0P 88653-26-3P 88653-28-5P **88653-29-6P** (preparation of)

L24 ANSWER 48 OF 48 HCAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER:

1972:571214 HCAPLUS

DOCUMENT NUMBER:

77:171214

TITLE:

Stabilized silver halide photographic

emulsions

INVENTOR(S):

Gauss, Walter; Mueller-Bardoff, Wolfgang; Von Koening, Anita; Moll, Franz; Saleck, Wilhelm

PATENT ASSIGNEE(S):

Agfa-Gevaert A.-G.

SOURCE:

Ger. Offen., 33 pp. CODEN: GWXXBX

DOCUMENT TYPE:

Patent

LANGUAGE:

German

FAMILY ACC. NUM. COUNT:

## PATENT INFORMATION:

| PATENT NO.             | KIND       | DATE     | APPLICATION NO.   | DATE         |
|------------------------|------------|----------|-------------------|--------------|
|                        |            |          |                   |              |
| DE 2042522             | Α          | 10720202 | DE 1070 2042522   |              |
| DE 2042533             | A          | 19720302 | DE 1970-2042533   | 1970         |
|                        |            |          |                   | 0827         |
| DE 2042533             | B2         | 19810122 |                   | ••           |
| DE 2042533             | C3         | 19811001 |                   |              |
| GB 1340544             | Α          | 19731212 | GB 1971-38481     |              |
|                        |            |          |                   | 1971         |
|                        |            |          |                   | 0817         |
| CA 979709              | A1         | 19751216 | CA 1971-120711    | 1051         |
|                        |            |          |                   | 1971<br>0817 |
| BE 771731              | <b>A</b> 1 | 19720225 | BE 1971-3341      | 0017         |
| 22                     |            | 17/20225 | 25 17,1 3311      | 1971         |
|                        |            |          |                   | 0825         |
| US 3761278             | Α          | 19730925 | US 1971-174930    |              |
|                        |            |          |                   | 1971         |
|                        |            |          |                   | 0825         |
| CH 571233              | Α          | 19751231 | CH 1971-12536     |              |
|                        |            |          |                   | 1971<br>0826 |
| FR 2106153             | A5         | 19720428 | FR 1971-31203     | 0826         |
| IK 2100133             | n.J        | 13720420 | TR 1971 31203     | 1971         |
|                        |            |          |                   | 0827         |
| FR 2107076             | A5         | 19720505 | FR 1971-31204     |              |
|                        |            |          |                   | 1971         |
|                        | _          |          |                   | 0827         |
| JP 55009695            | B4         | 19800311 | JP 1971-65241     |              |
|                        |            |          |                   | 1971<br>0827 |
| PRIORITY APPLN. INFO.: |            |          | DE 1970-2042533 A |              |
|                        |            |          | DD 1770 2012333 R | 1970         |
|                        |            |          |                   | 0827         |
|                        |            |          |                   |              |
|                        |            |          | DE 1971-2130031 A |              |
|                        |            |          |                   | 1971         |
|                        |            |          |                   | 0618         |
|                        |            |          |                   |              |

AB Stabilizers whose -SH group is liberated by hydrolysis during development only, and which therefore exert a min. depression on sensitivity and cause formation of smaller Ag grains due to gradual decreasing of the development are composed of heterocyclic compds. (benzimidazoles, imidazoles, purines, pyrimidines, triazoles, tetrazoles, etc.) containing N-C1-6 alkylcarbonyl or N-arylcarbonyl and 2-thio or 2-alkylcarbonylthio substituents. The stabilizer is added at 1-50 mg per mole Ag halide in an organic solvent solution prior to the ripening of the emulsion and, to improve the effect, a tetra-or pentaazaindene is added after the ripening. Thus, after 7 min development of a high-speed AgBr emulsion (with 6% AgI) the fog was reduced from 0.35 to 0.19 by 5 mg 2-ethoxycarbonylthio-1,4,5-triphenylimidazole and to 0.1 if 200 mg of 4-hydroxy-6-methyl-1,3,3a,7-tetrazaindene was also added per kg of emulsion ready to coat.

IT 38586-33-3 38815-64-4 38815-65-5 38815-66-6

(photog. stabilizer)

RN 38586-33-3 HCAPLUS

CN 1H-Benzimidazole-1-carboxylic acid, 5,6-dichloro-2-[[(1-methylethoxy)carbonyl]thio]-, 1-methylethyl ester (9CI) (CA INDEX NAME)

RN 38815-64-4 HCAPLUS

CN 1H-Benzimidazole-1-carboxylic acid, dichloro-2-[(propoxycarbonyl)thio]-, propyl ester (9CI) (CA INDEX NAME)

2 (D1-C1)

RN 38815-65-5 HCAPLUS

CN 1H-Benzimidazole-1-carboxylic acid, dichloro-2-[[(1-methylethoxy)carbonyl]thio]-, 1-methylethyl ester (9CI) (CA INDEX NAME)

2 (D1-C1)

RN 38815-66-6 HCAPLUS

CN 1H-Benzimidazole-1-carboxylic acid, dichloro-2-

[(ethoxycarbonyl)thio]-, ethyl ester (9CI) (CA INDEX NAME)

2 (D1-C1)

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IC
     G03C
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CC 74-2 (Radiation Chemistry, Photochemistry, and

Photographic Processes)

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ΙT
     2178-82-7
                              2178-86-1
                                          2178-90-7
                                                       2178-91-8
                 2178-83-8
     2178-92-9
                 2178-93-0
                              2178-96-3
                                          2178-97-4
                                                       2179-02-4
                 2233-08-1
     2179-04-6
                              21521-70-0
                                           21521-73-3
                                                         38586-25-3
                  38586-29-7
     38586-27-5
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     38586-37-7
                  38586-38-8
                                38586-39-9
                                             38593-83-8
                                                           38593-84-9
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                  38593-87-2
                                38593-88-3
                                             38593-89-4
                                                           38593-92-9
     38593-93-0
                                             38593-96-3
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                                38593-95-2
                                                           38593-97-4
     38593-99-6
                  38594-02-4
                                38594-03-5
                                             38594-06-8
                                                           38594-07-9
     38594-08-0
                  38594-10-4
                                38594-11-5
                                             38594-12-6
                                                           38594-13-7
     38594-14-8
                  38594-16-0
                                38594-17-1
                                             38666-65-8
     38815-64-4 38815-65-5 38815-66-6
        (photog. stabilizer)
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